

Advanced Scanning Probe Microscopy

Petr Klapetek, Český metrologický institut, Okružní 31, 638 00 Brno

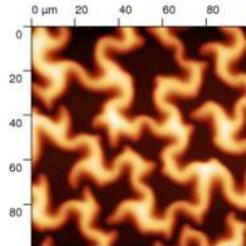
Scanning probe microscopy

Versatile surface measurement technique:

- no sample preparation
- many quantities achievable
- simple principle and construction
- cost effective

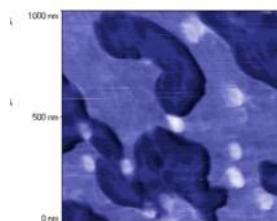
Novel regimes emerging quickly.

What about quantitative aspects?

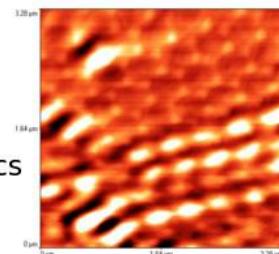


Morphology from microscale to nanoscale

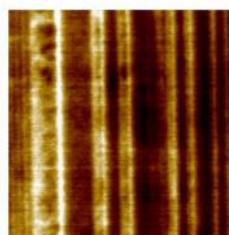
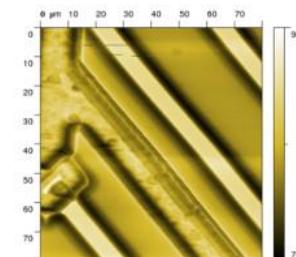
Local mechanical properties



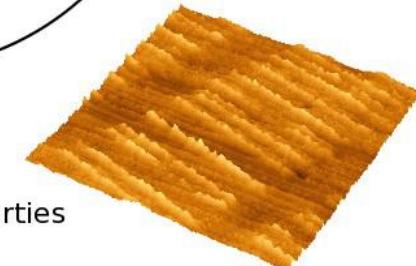
Optics and plasmonics



Temperature and thermal conductivity



Magnetic properties



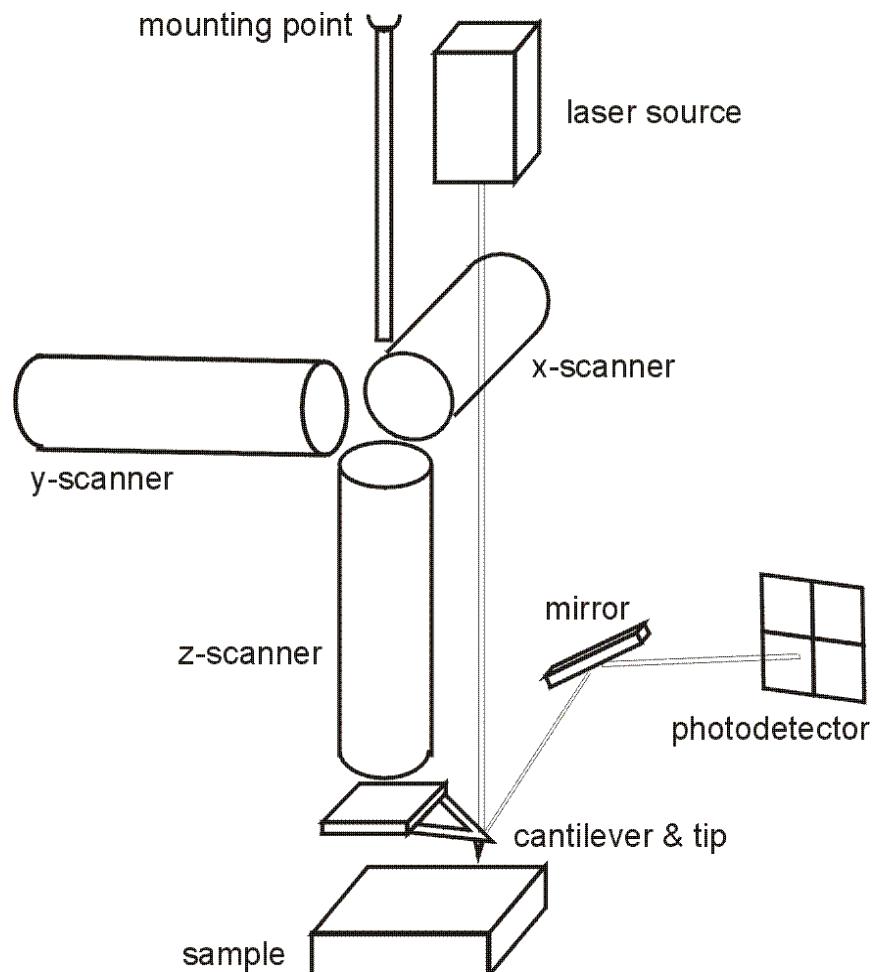
Key concept

Small probe scanning close to surface

Small probe ...
sharp tip

... scanning ...
scanners, piezoelectric materials,
positioning sensors

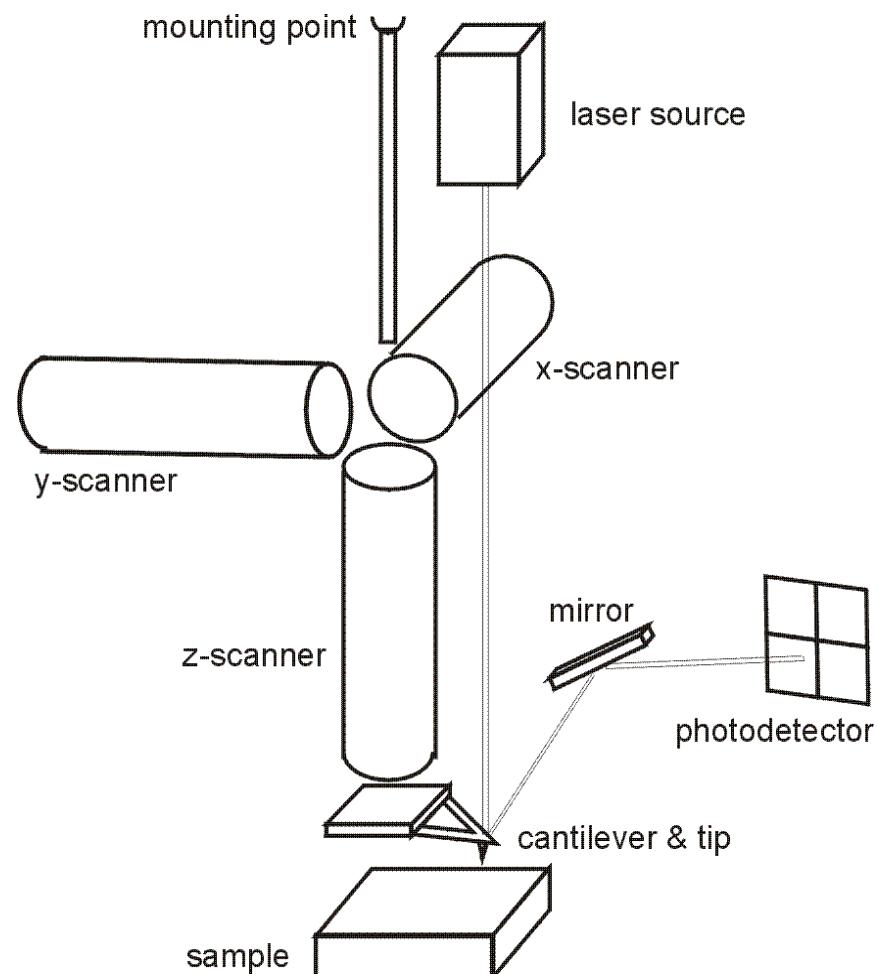
... close to surface
feedback loop, optical pickup, self-sensing
probes.



Key concept

Small probe scanning close to surface

Small probe ...
sharp tip

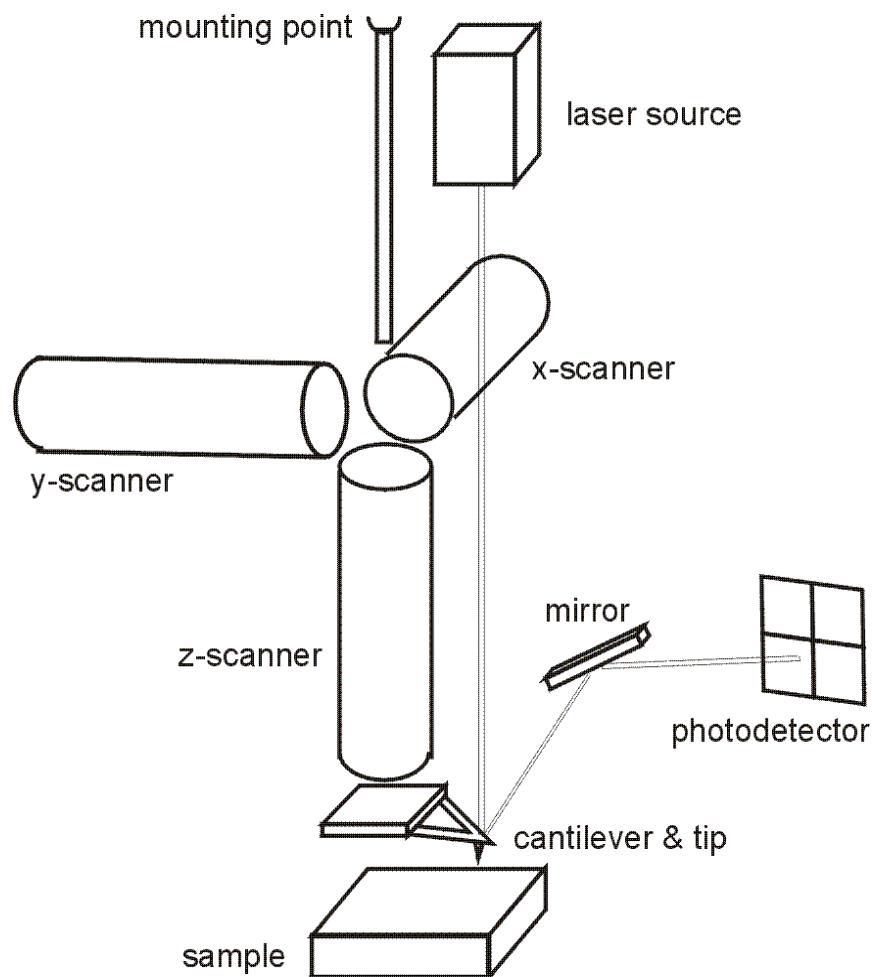


Key concept

Small probe scanning close to surface

Small probe ...
sharp tip

... scanning ...
scanners, piezoelectric materials,
positioning sensors



Key concept

Small probe scanning close to surface

Small probe ...

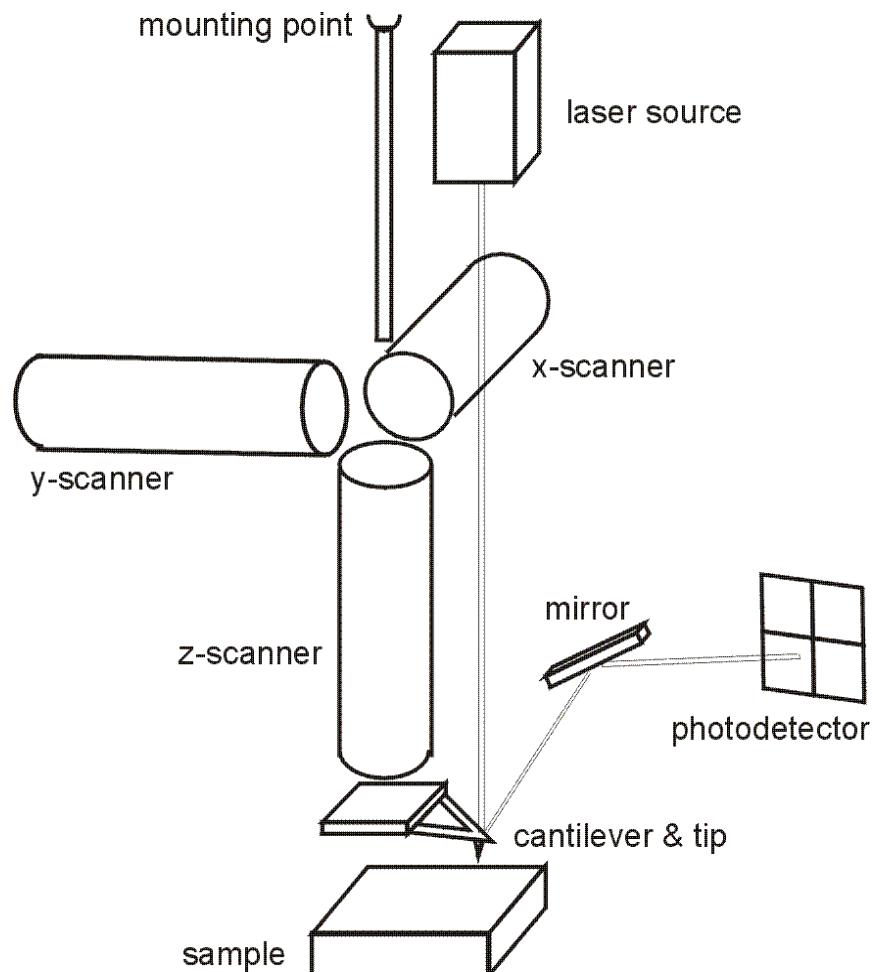
sharp tip

... scanning ...

scanners, piezoelectric materials,
positioning sensors

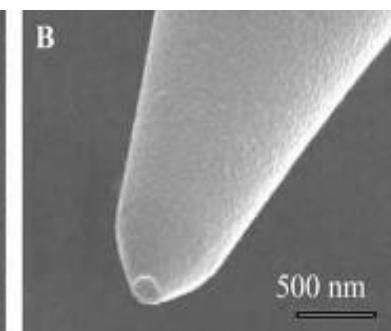
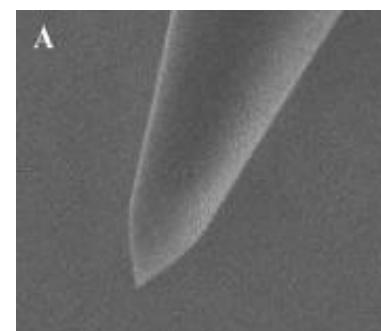
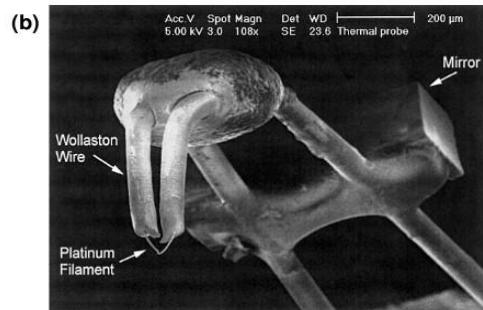
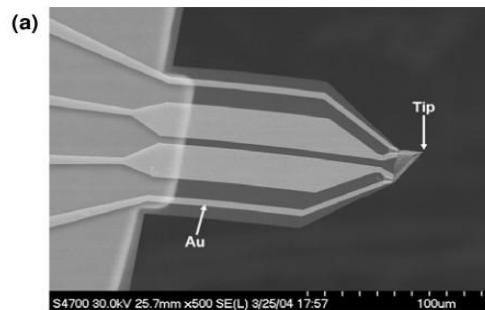
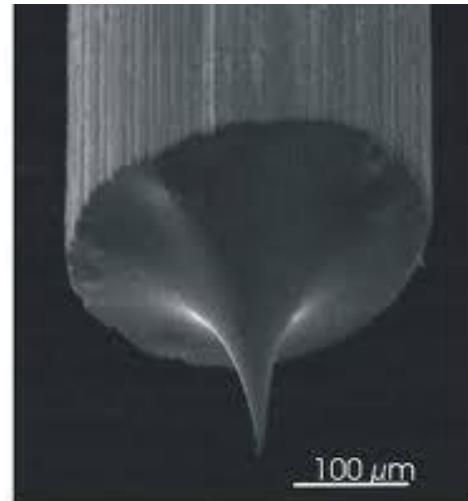
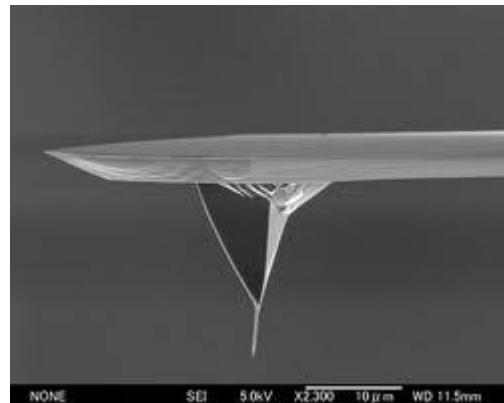
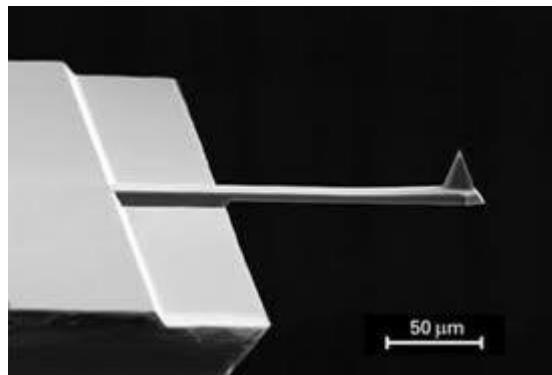
... close to surface

feedback loop, optical pickup, self-sensing
probes.



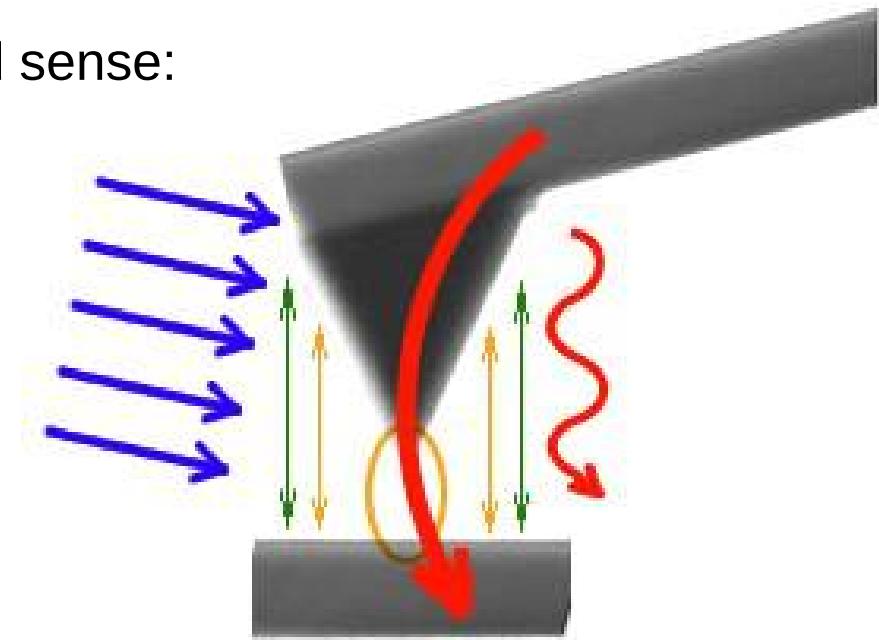
Many probe types:

- tip geometries (super-sharp, spherical, ...)
- functionalisation (electrical, magnetic, ...)
- stiffness (contact, tapping, ...)



There are many interactions that a probe could sense:

- inter-atomic forces (AFM)
- electrostatic field (AFM, EFM, KPFM, SCM)
- magnetic field (MFM)
- temperature and heat transfer (SThM)
- electromagnetic field distribution (SNOM, SMM)



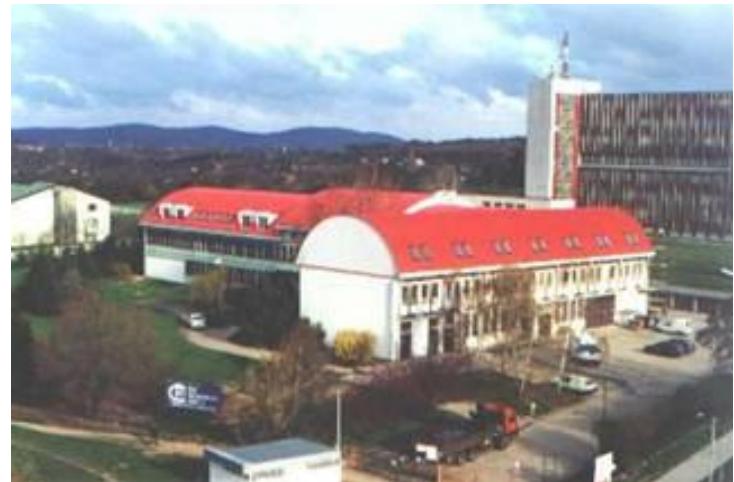
We want to make everything quantitative!

National metrology institute of the Czech Republic

fundamental metrology: maintenance and development of national standards, R&D in metrology

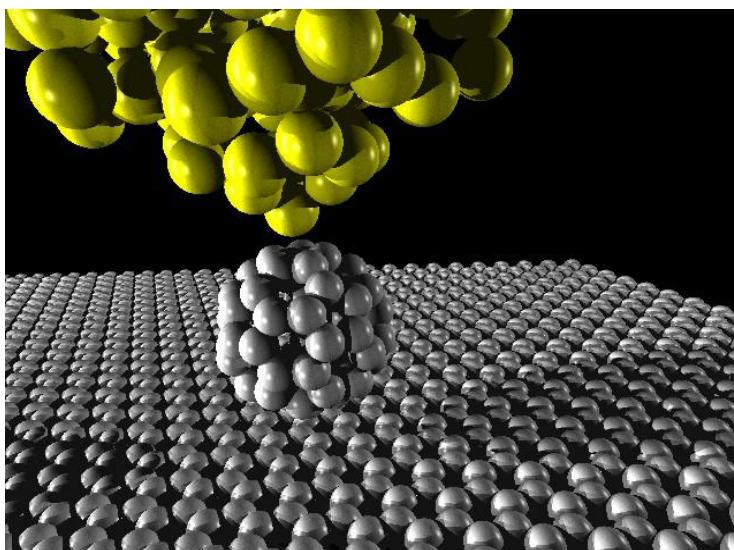
dissemination of units: top level calibration of standards and measuring instruments

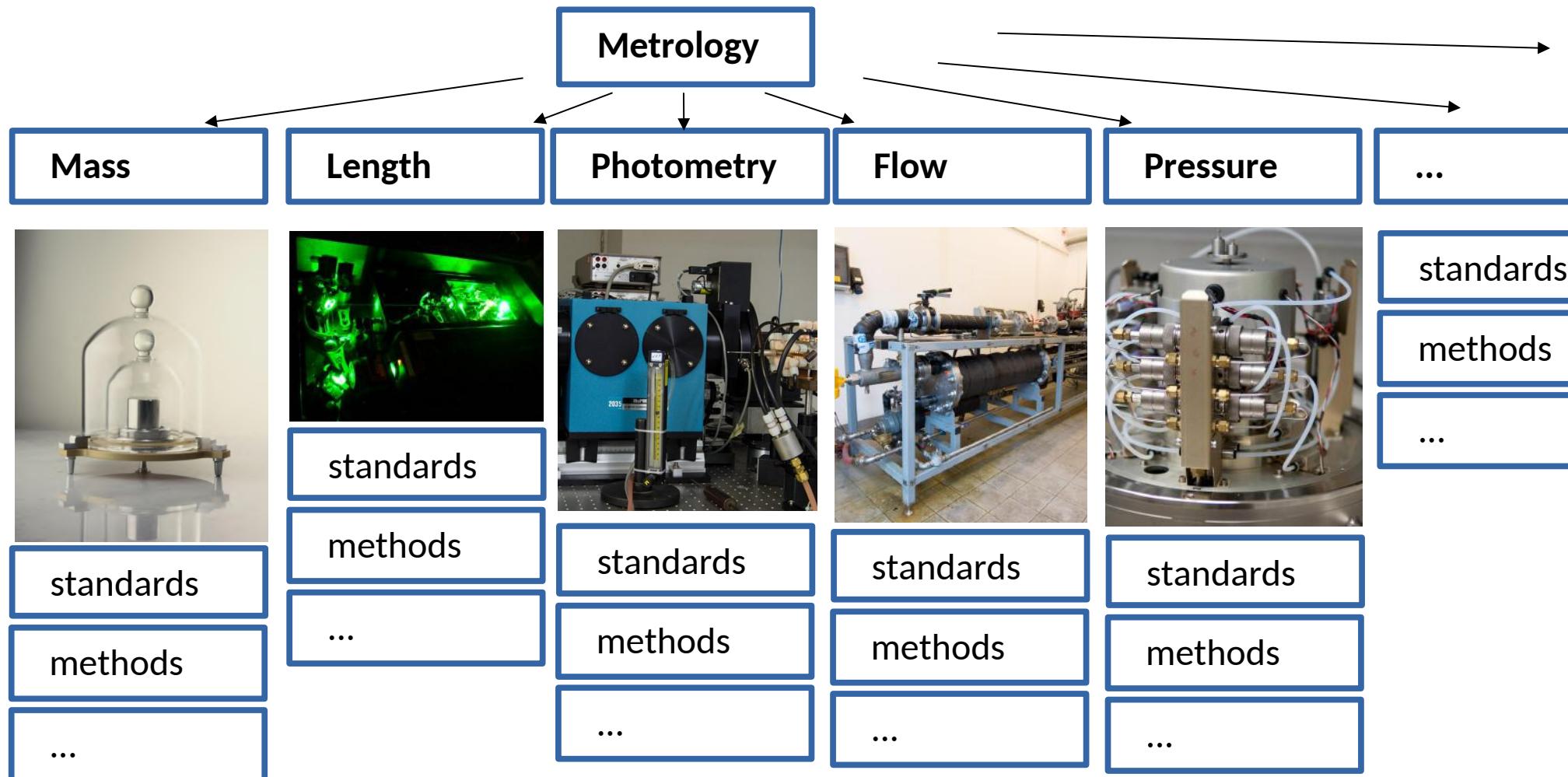
legal metrology: regulated sphere, type approvals of legal metrology instruments...

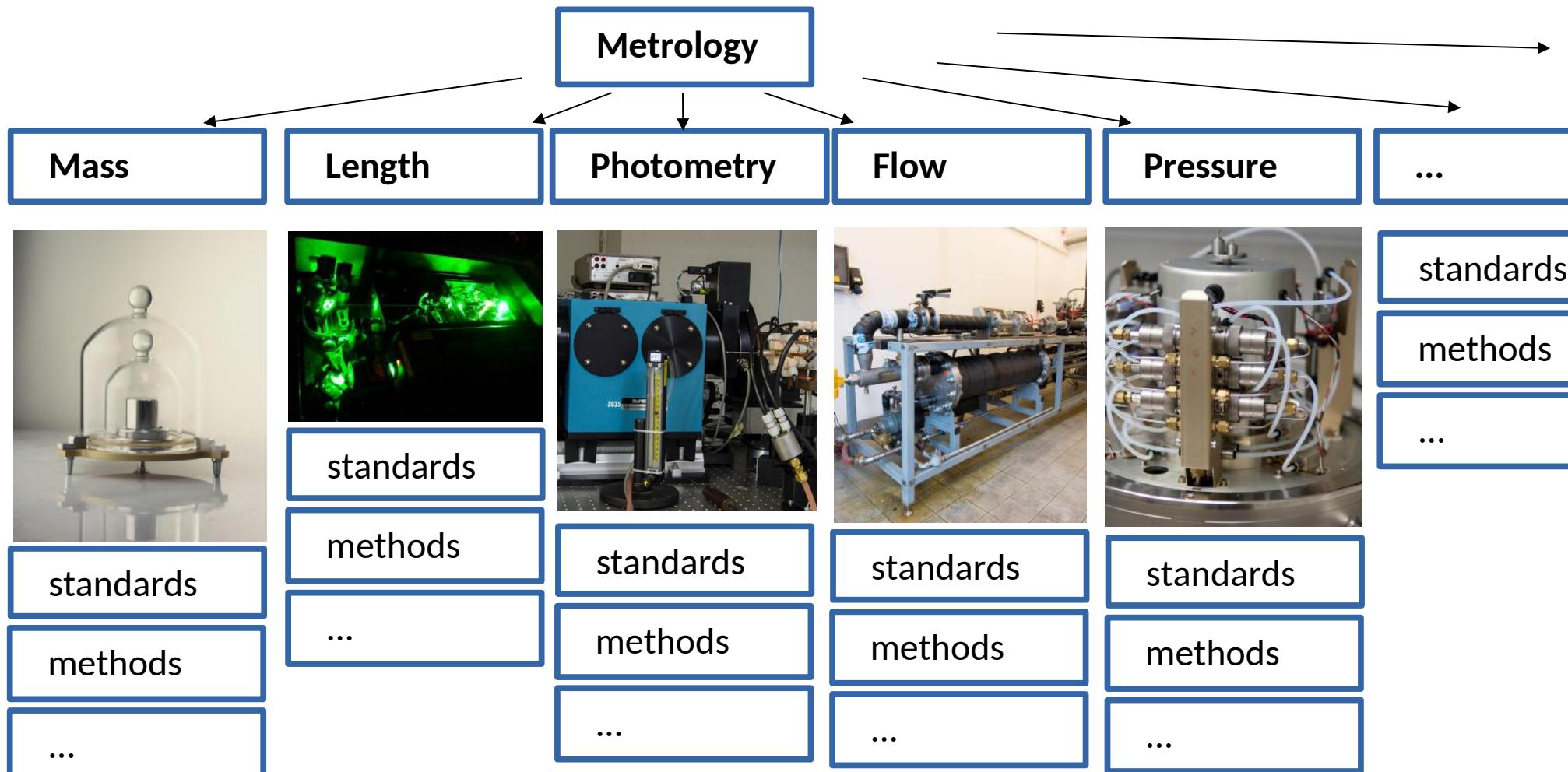


Department of nanometrology: CMI Regional Branch Brno.

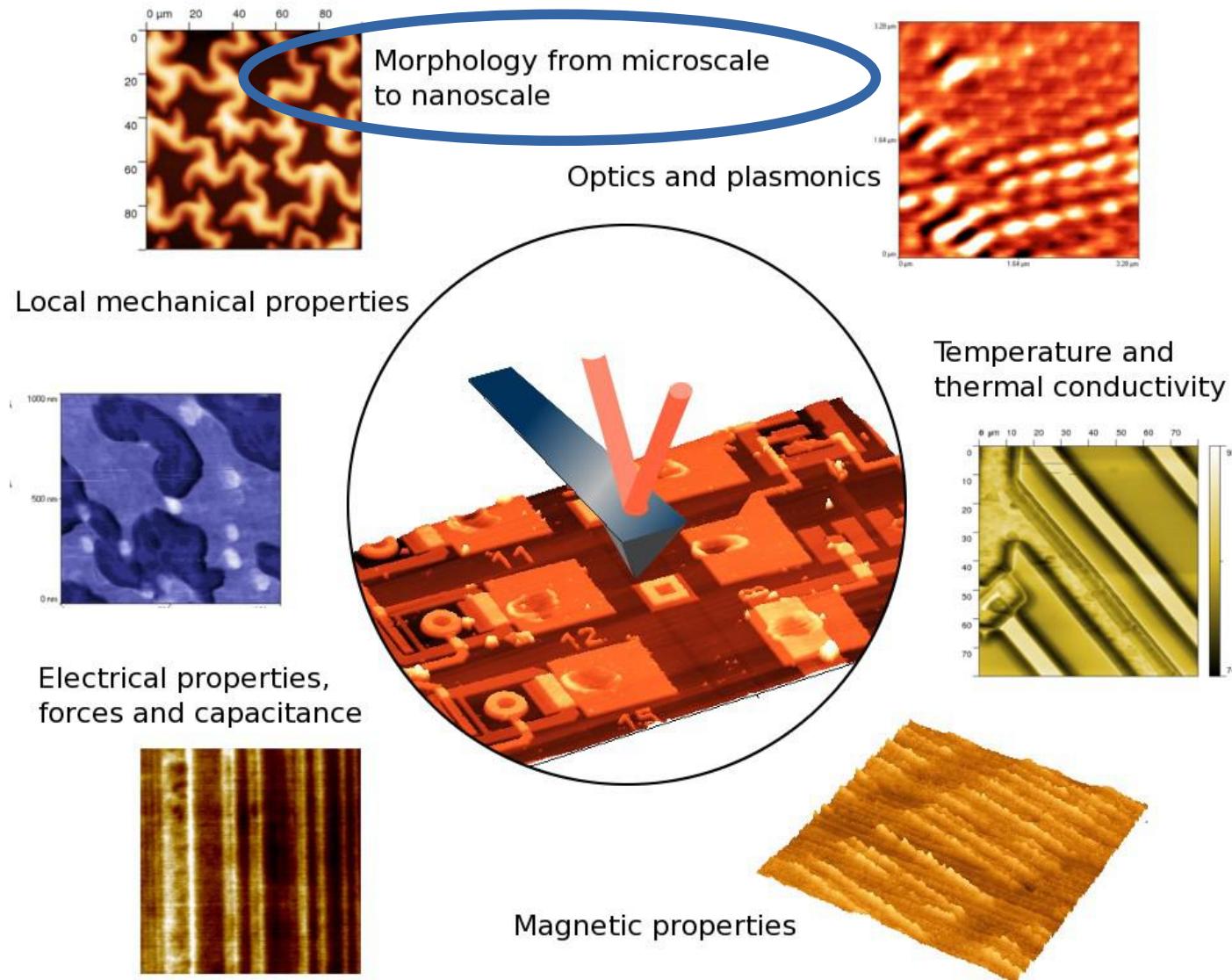
- scanning probe microscopy methods
- numerical modeling at nanoscale and microscale
- advanced data processing algorithms development
- providing metrological traceability
- methodology, uncertainty analysis







SPM – scanning probe microscopy

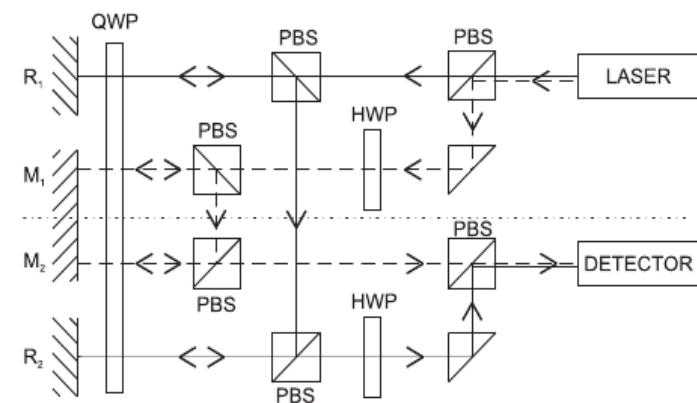
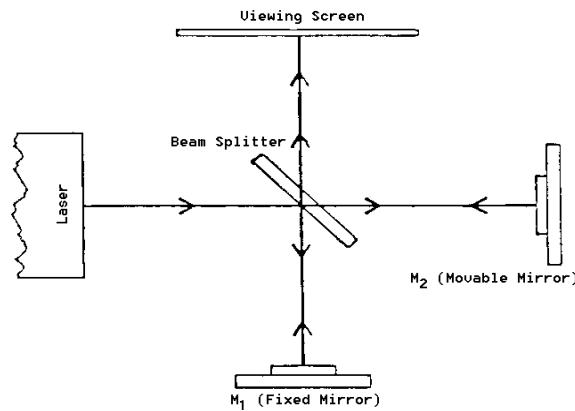
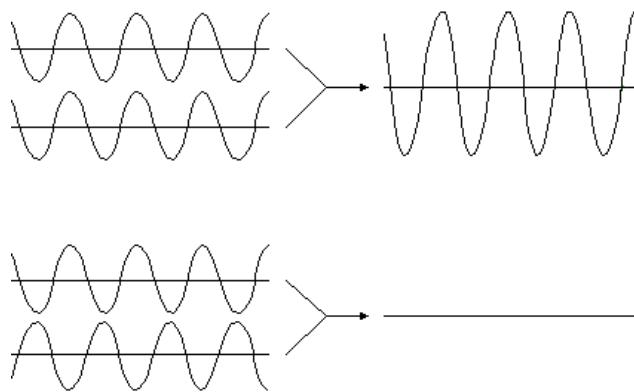


Metre definition:

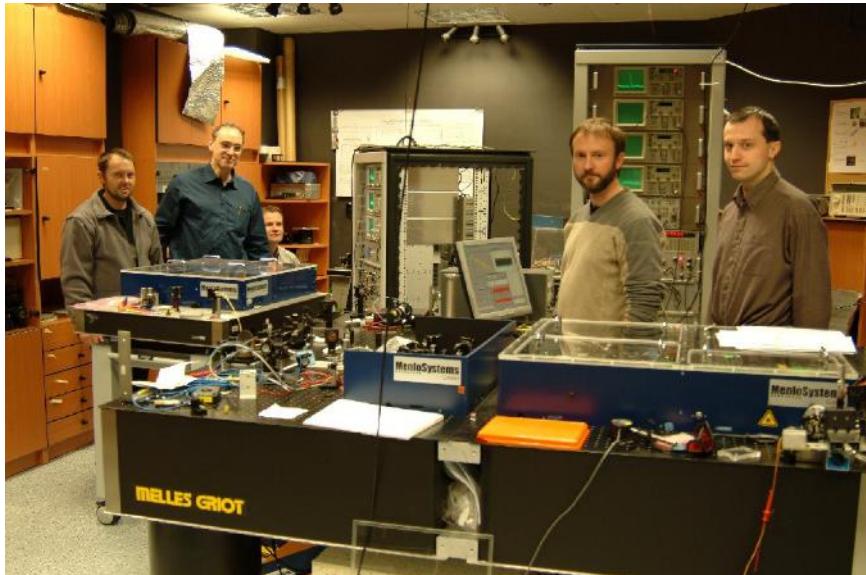
The metre, symbol m, is the SI unit of length. It is defined by taking the fixed numerical value of the speed of light in vacuum c to be 299792458 when expressed in the unit $\text{m}\cdot\text{s}^{-1}$, where the second is defined in terms of the caesium frequency $\Delta\nu_{\text{Cs}}$.

Length measurements via lasers: laser interferometers

- based on monitoring the interference of monochromatic light of known wavelength
- range up to tens of meters
- resolution down to tens of picometers



State etalons of length: stabilised lasers



Calibration of wavelength of lasers used in **laser interferometers**.

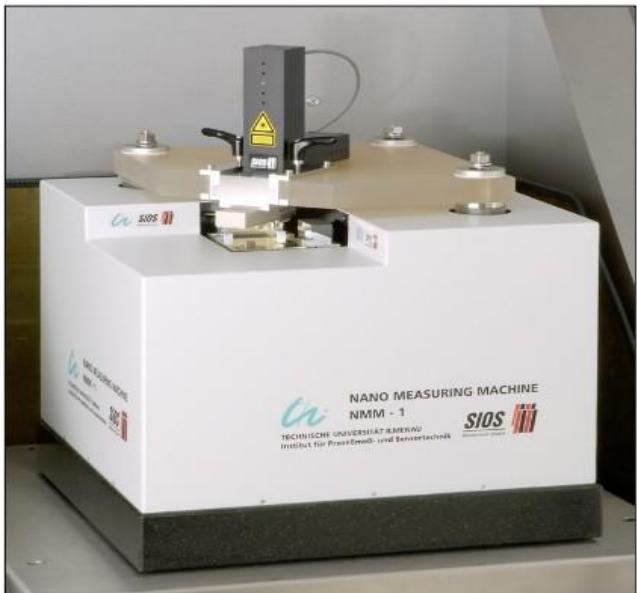
Interferometers are then used to calibrate **other sensors**.



Going up: Large area SPMs

Interferometric calibration of positioning systems

- use of independent interferometer at calibration
- cheaper sensors used for routine operation
- time stability needs to be analyzed
- larger uncertainties



Positioning systems using interferometers

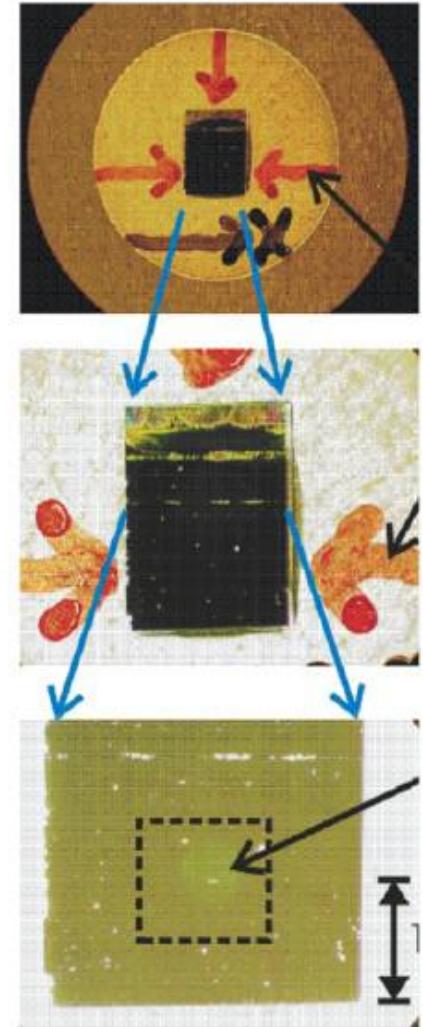
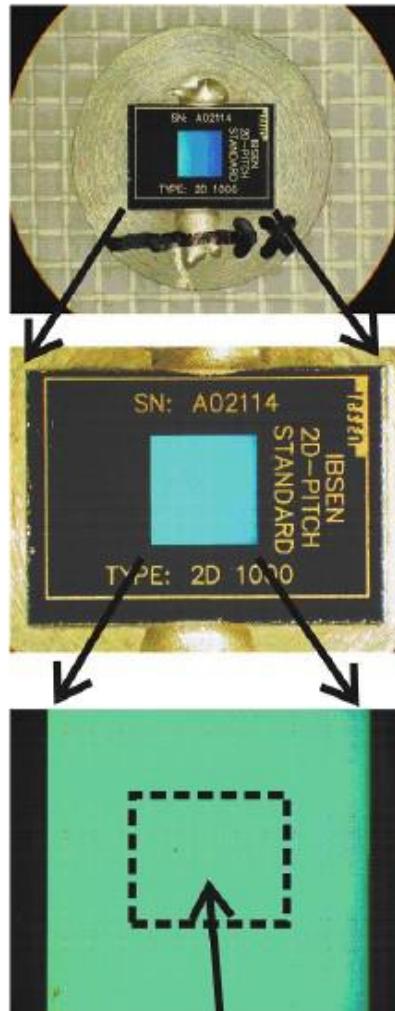
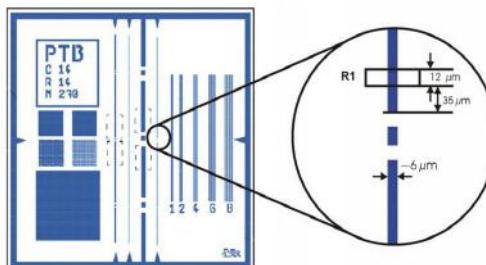
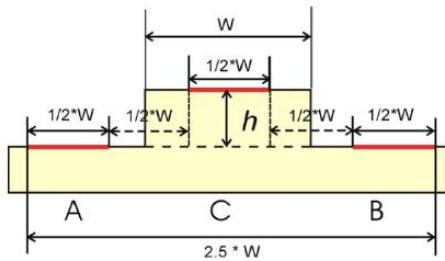
- direct traceability
- many effects can be compensated
- more expensive, more sensitive to disturbances

Grating: lateral scale calibration

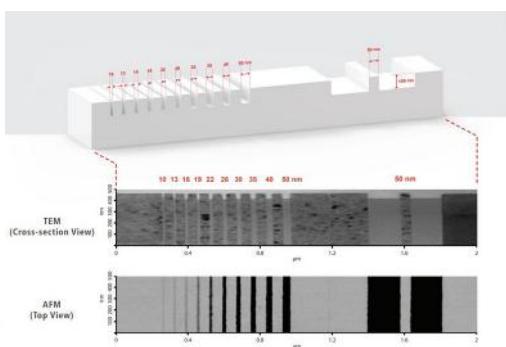
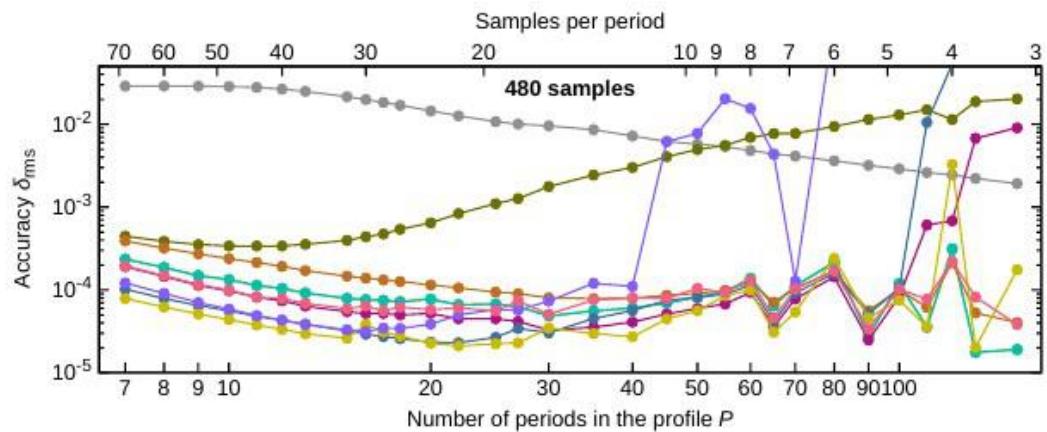
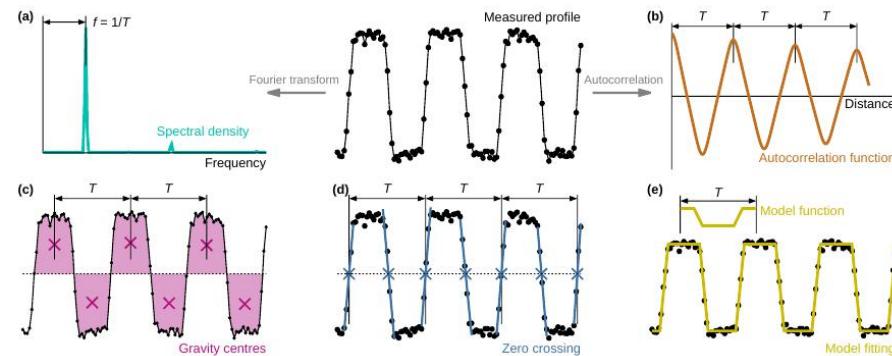
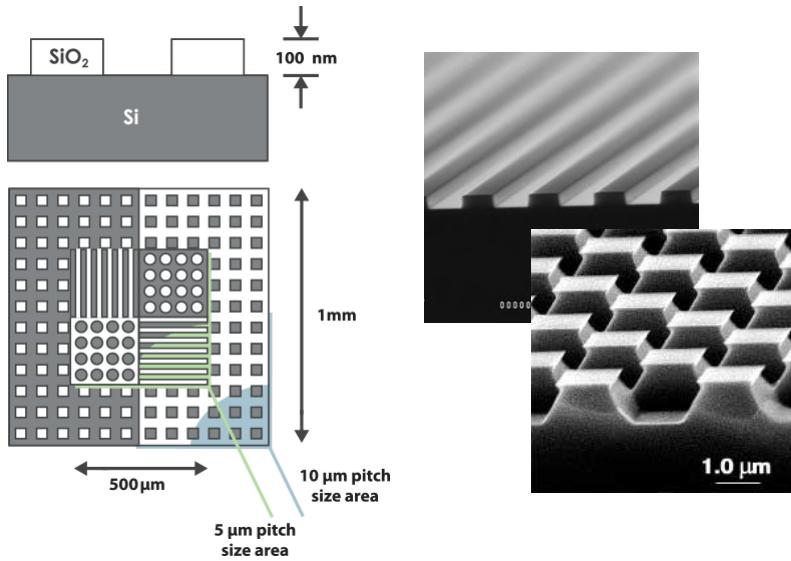
Step height: z-scale calibration

You can buy 1D and 2D gratings on many places.

The grating itself can be used as a step height standard (of a limited accuracy).



Grating: lateral scale calibration
(Bruker, Tipsnano, Nanoandmore, ...)



Step height: z-scale calibration
(Park Systems, Tipsnano)
Can be combined with grating.

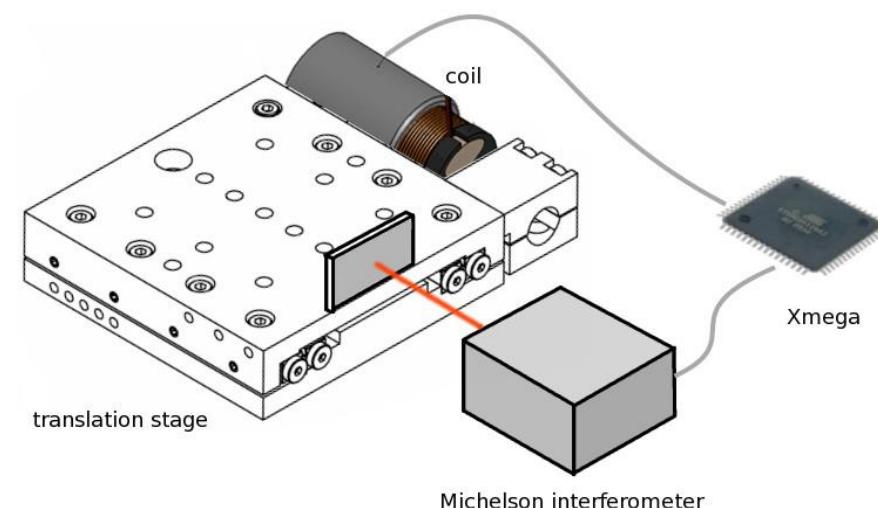
How to perform and measure a nanometer motion over large scale?

The simplest choice: piezoelectric material. However, this many disadvantages:

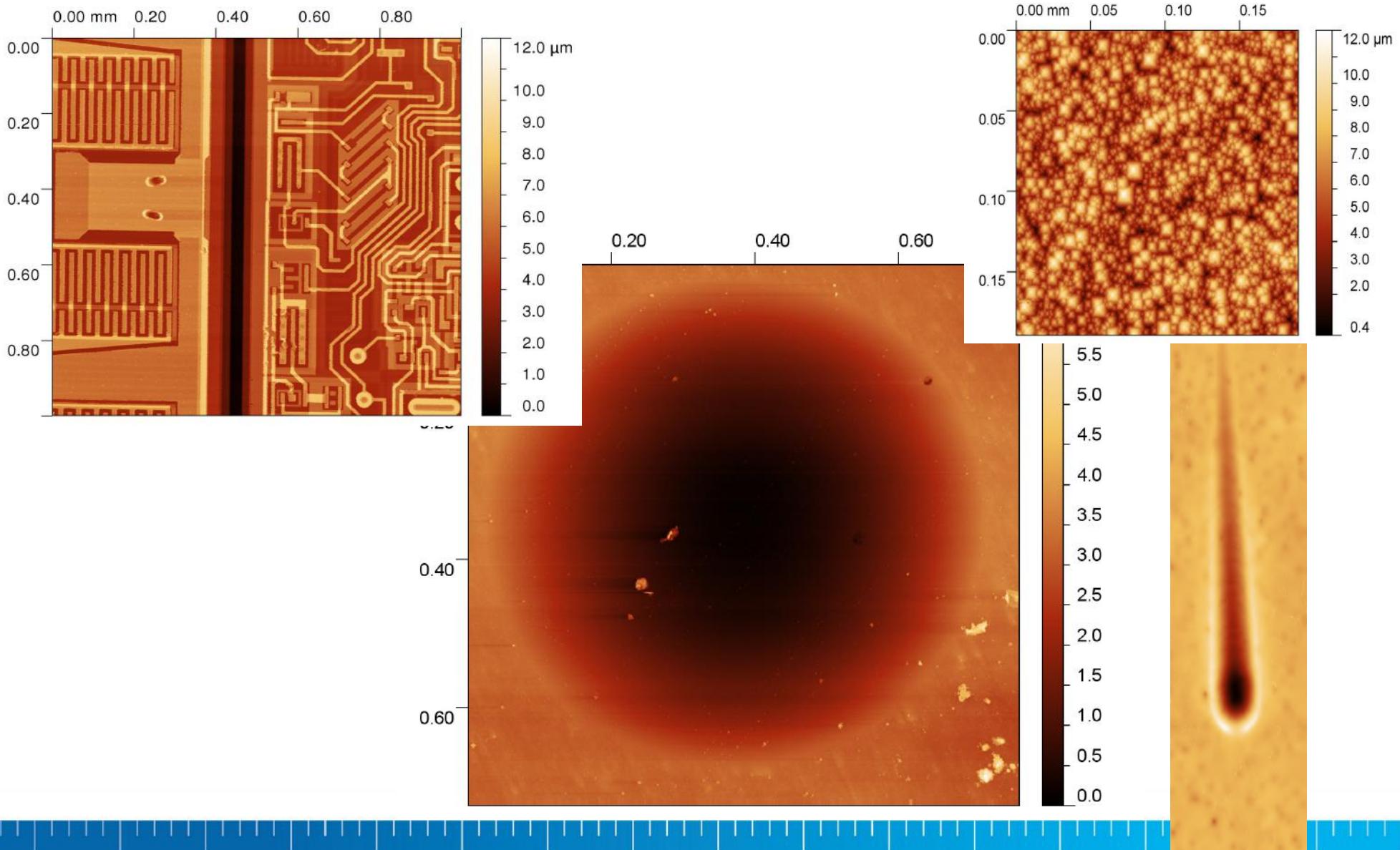
- small range (typically 10 microns per centimeter of actuator size)
- power demands (high voltage, large currents for fast changes)
- limited long term stability.

Good DA converter is necessary to be able to get both large scanning range and high resolution. This is a **voltage to position transducer**.

As an alternative, we can use **voltage-force transducer** coupled to a high resolution sensor, interferometer.

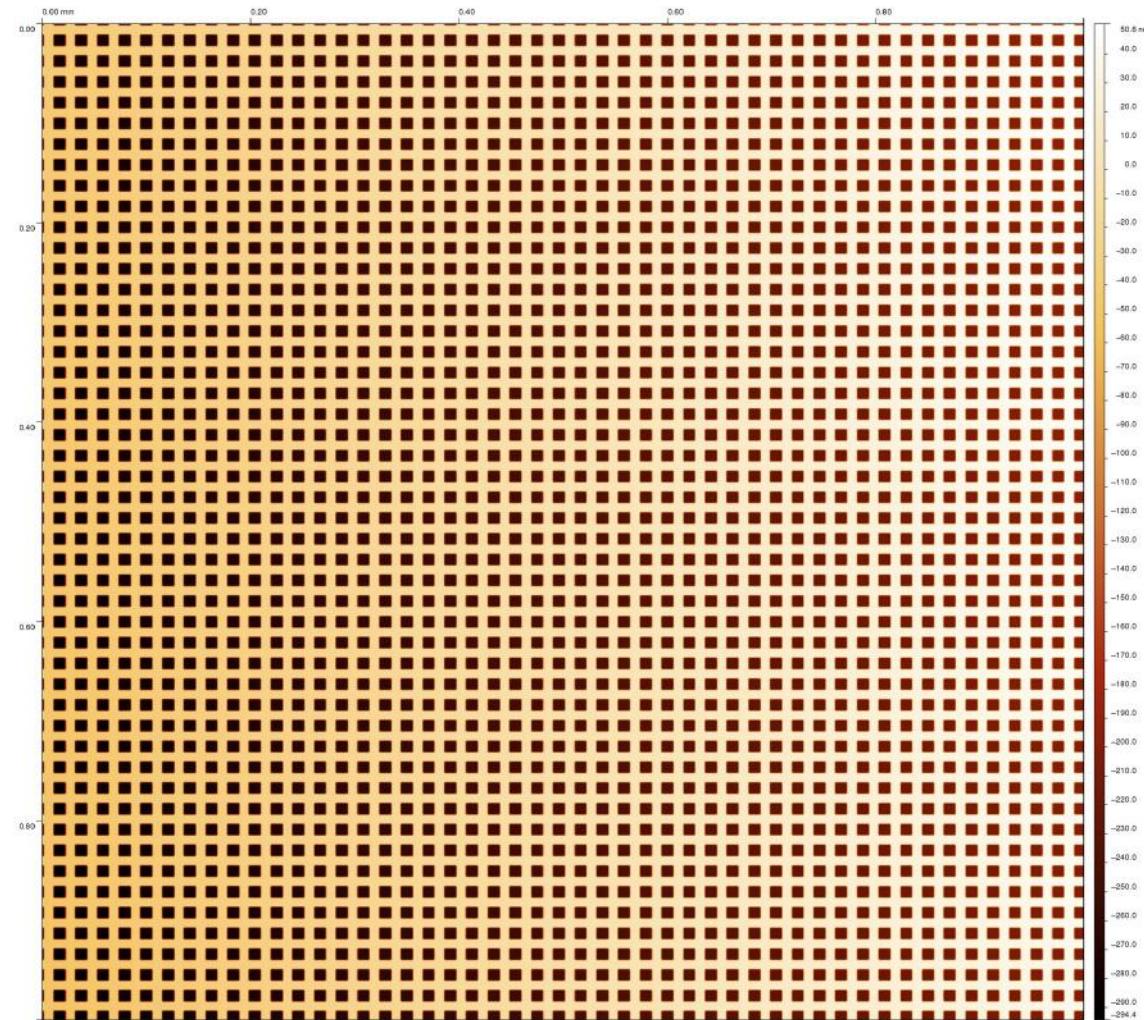
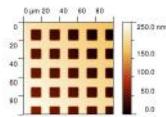


Going up: Large area SPMs



Going up: Large area SPMs

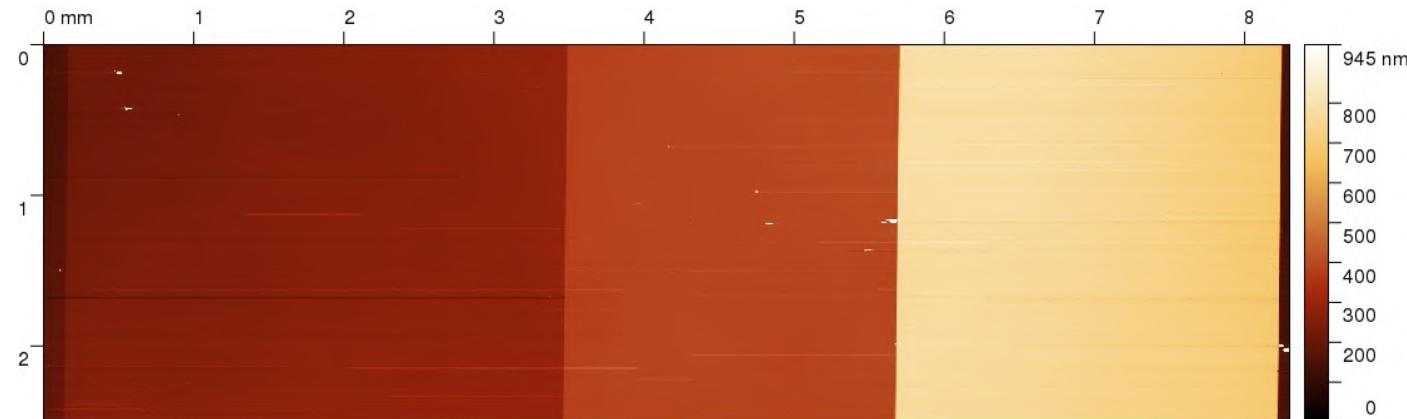
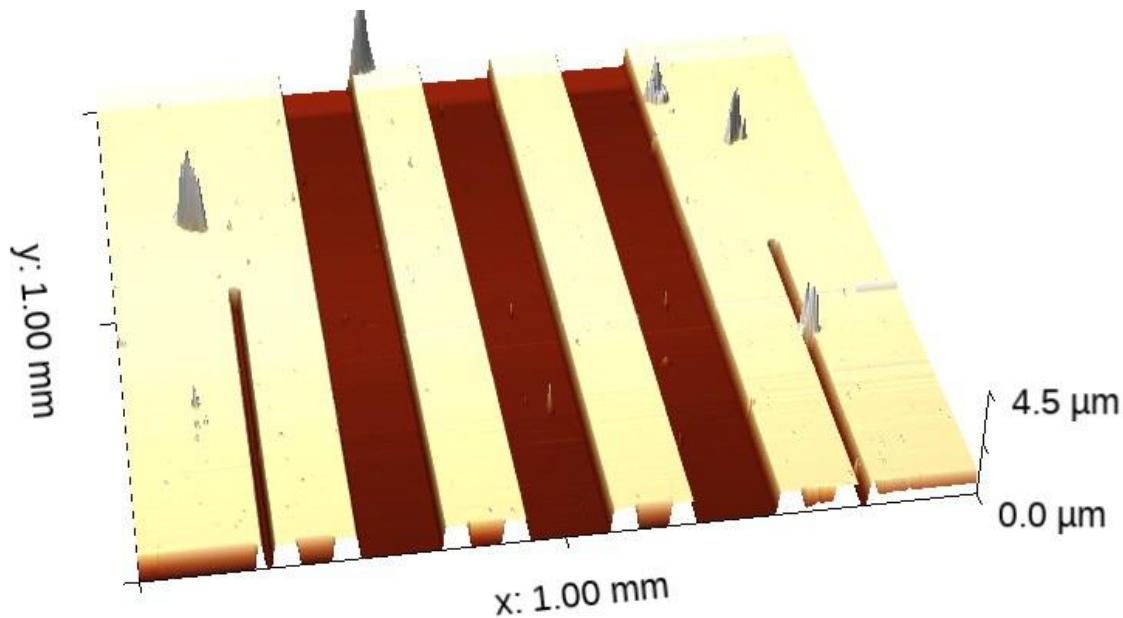
Typical SPM data



1x1 mm SPM data

Going up: Large area SPMs

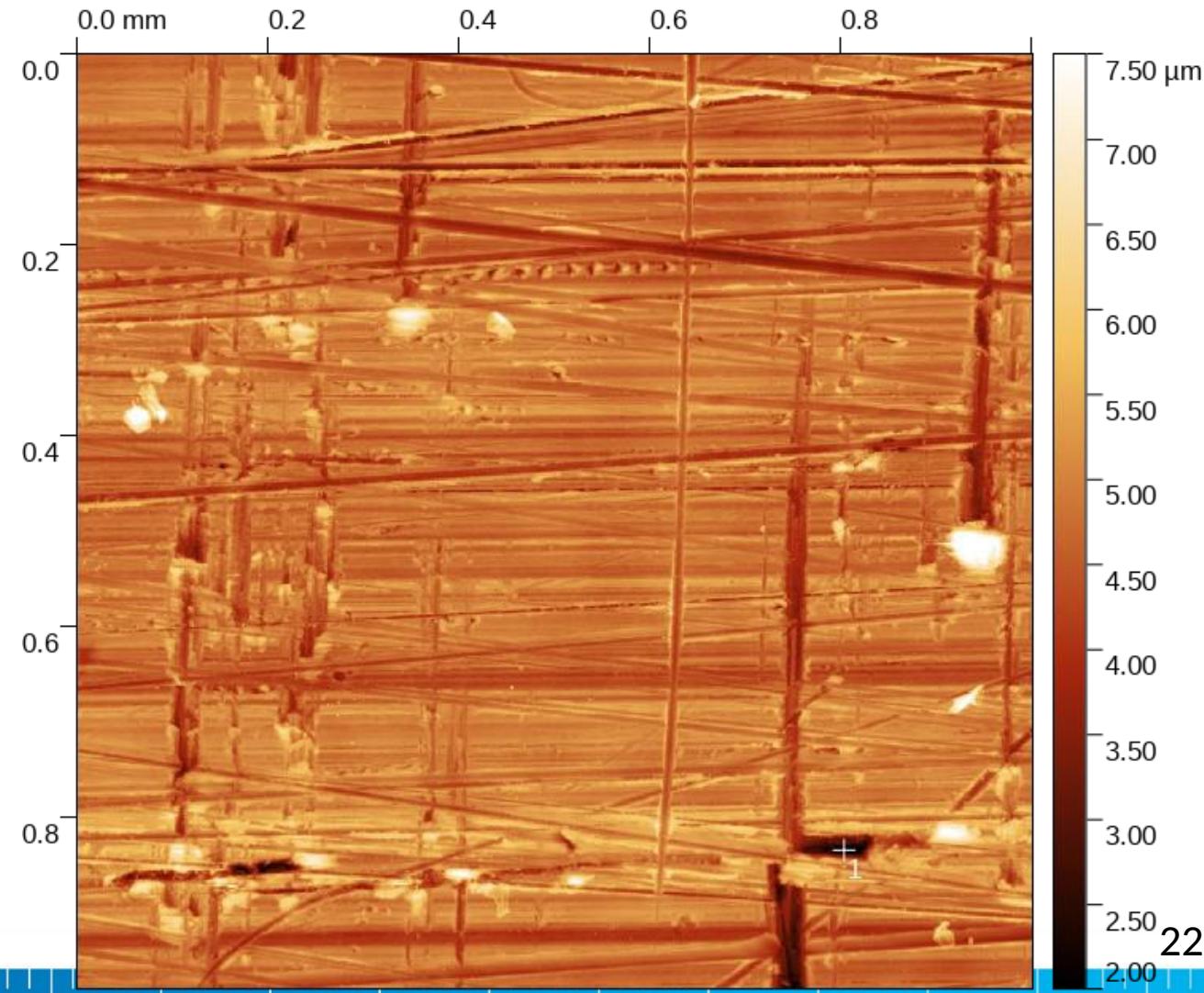
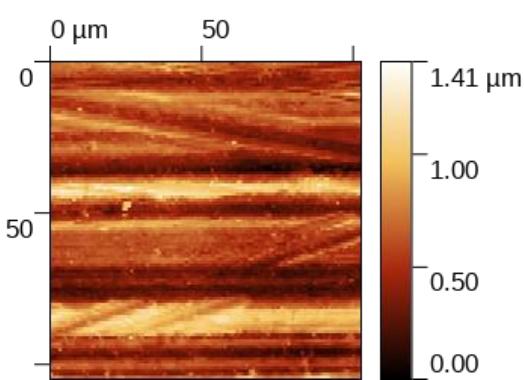
Calibration of step height standards suitable for larger range measurement techniques (e.g. confocal microscopes).



Monitoring thin film thickness variations over millimeter or centimeter areas.

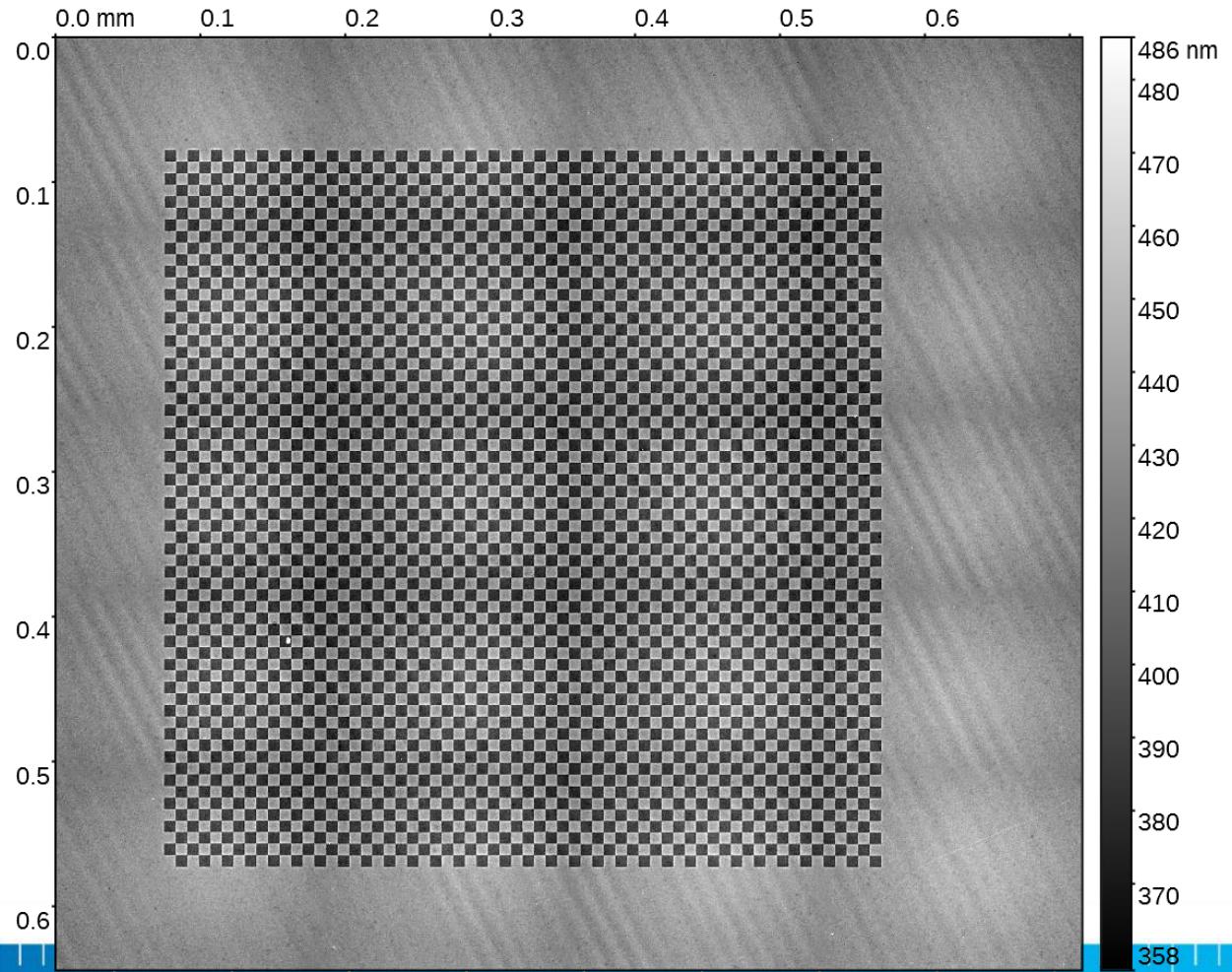
Going up: Large area SPMs

Roughness measurements on large areas: beyond the stylus measurements capabilities.



Going up: Large area SPMs

SPM has less systematic errors than optical techniques (e.g. confocal microscopy), is not sensitive to refractive index variations and less sensitive surface roughness.

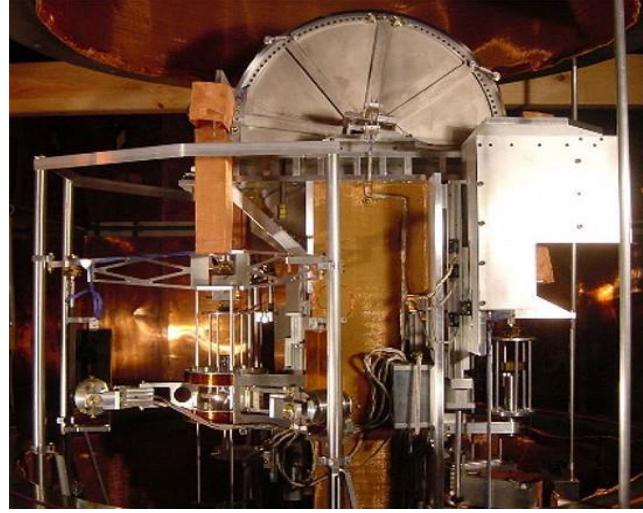
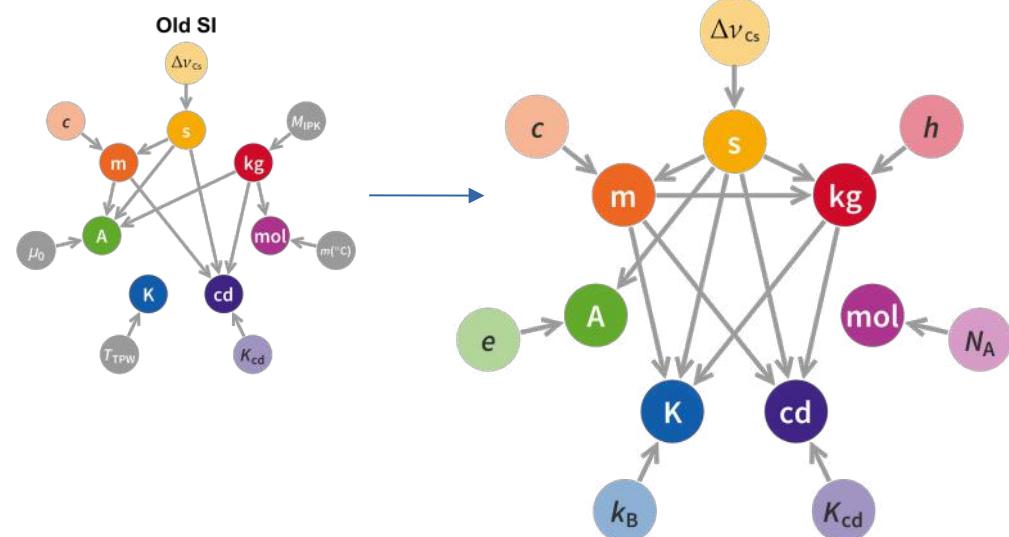


Going down: Silicon step standards

Redefinition of SI:

The biggest metrology challenge in the last years.

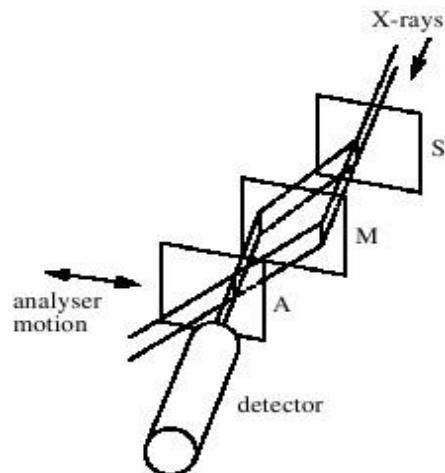
Goal was to used physical constants instead of unit prototypes.



Going down: Silicon step standards

How the length measurements benefit from SI redefinition?

(a)



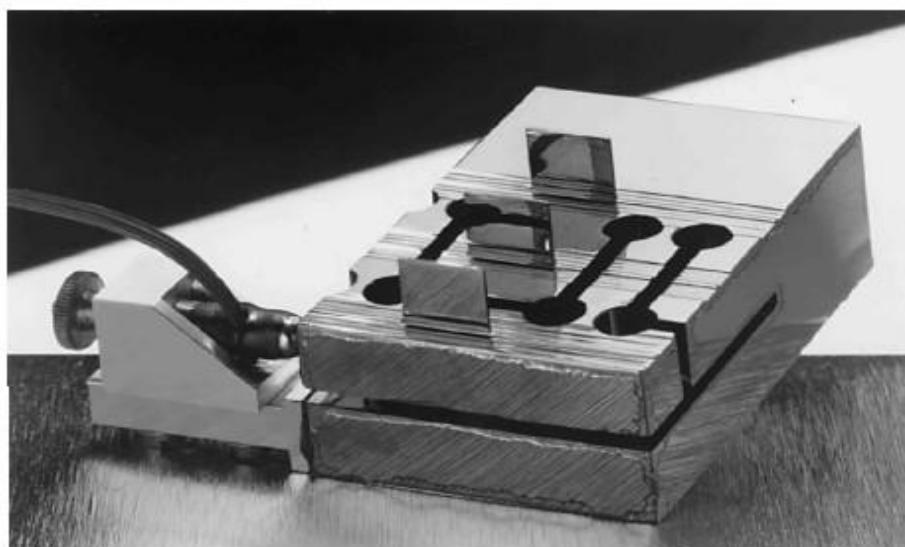
Interferometers are limited by the wavelength; everything that is below its fraction (e.g. half of the wavelength) is a kind of interpolation.

Going to extremely small wavelengths:

X-ray interferometry

Based on a gratings created by silicon lattice.

(b)



COXI X-ray interferometer based in National Physical Laboratory is being used e.g. for characterisation of non-linearities of other interferometers.

Traceability to **silicon lattice** is also a next potential realization of meter, covered to the present Mise en pratique documents by BIPM.

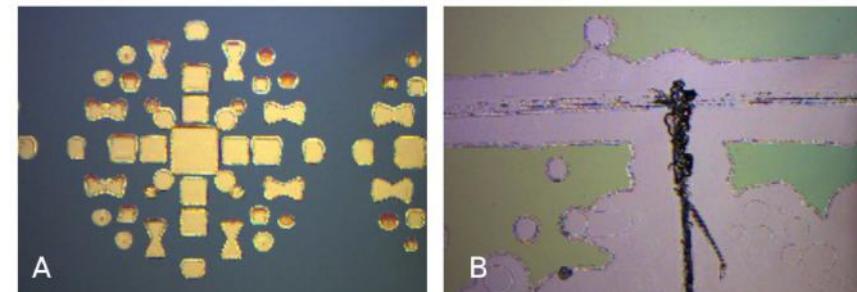
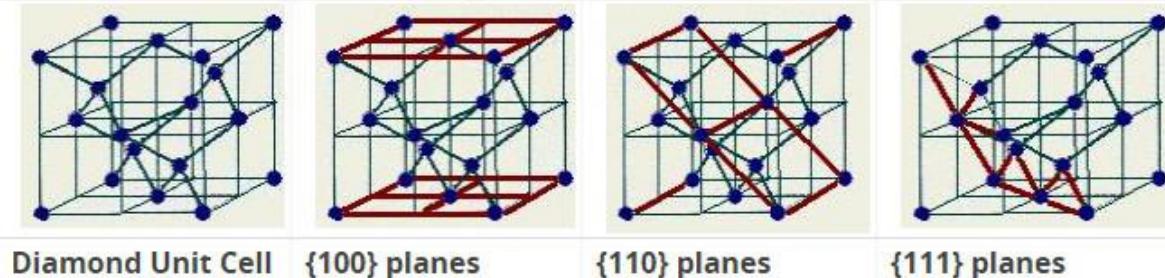
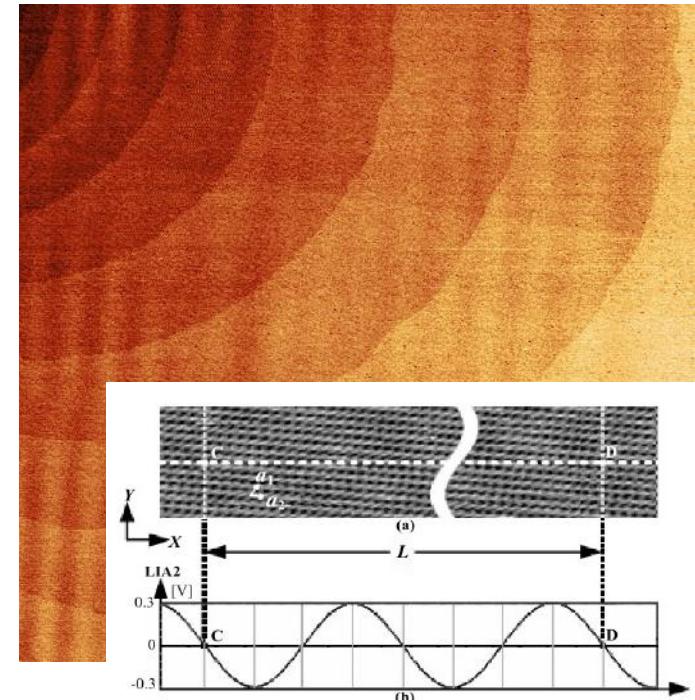
Going down: Silicon step standards

Si d_{220} , CODATA value $(192,0155714 \pm 0.0000032)$ pm

Step height for $d_{111} = (313,5601151 \pm 0.0000053)$ pm

Uncertainty in the range of 10^{-8} , comparable to the best custom built interferometric systems.

No need to care for interferometers uncertainty sources (refractie index, Abbe error, etc.).

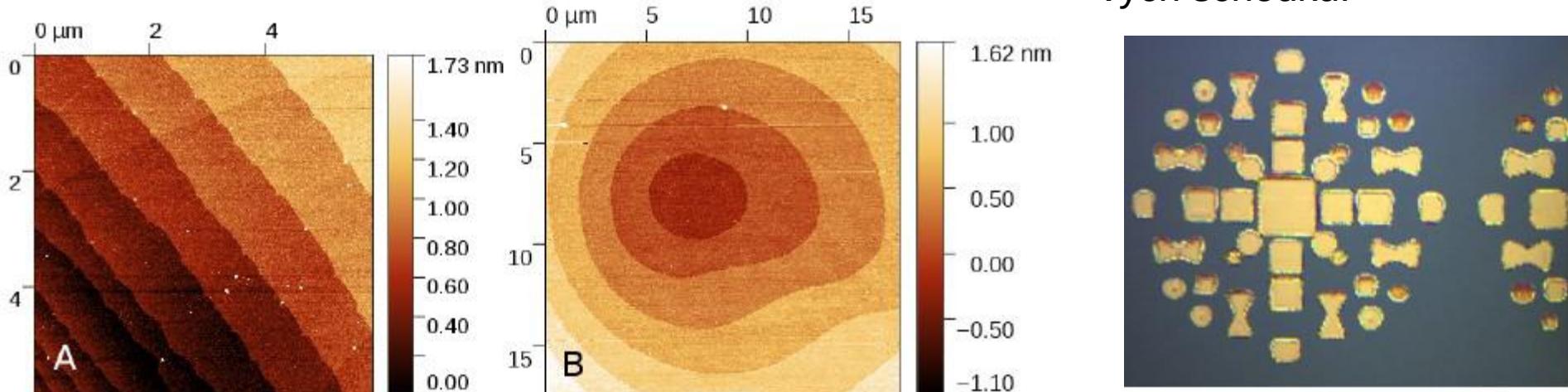


Atomární schodky v nanometrologii

Možnost využití atomárních schodků je jedním z důsledků redefinice kilogramu a dalších aktivit souvisejících s novou SI soustavou. Velmi přesná hodnota meziatomární vzdálenosti v křemíku vedla k rozpracování metodik pro sekundární realizaci metru pomocí křemíku – pro kalibraci TEM mikroskopů a pro měření výšky v různých mikroskopických metodách.

V minulosti vznikla řada slibných vzorků o různých geometriích, metodické pokyny pro jejich využití a aspekty nejistoty měření však zůstaly nepokryty.

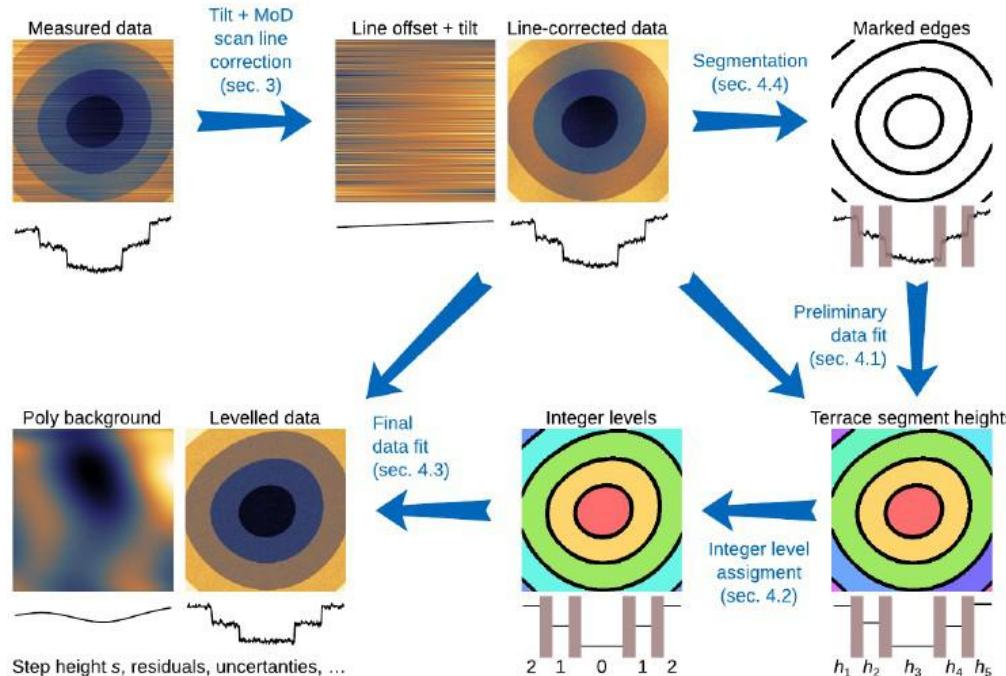
Proto jsme se podíleli na vývoji algoritmi pro analýzu křemíkových schodků.



Going down: Silicon step standards

Separation of background and silicon steps data

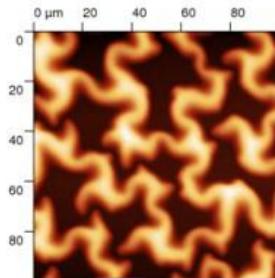
A procedure suggested by DFM was extended to 2D by David Nečas and is now part of Gwyddion open source software.



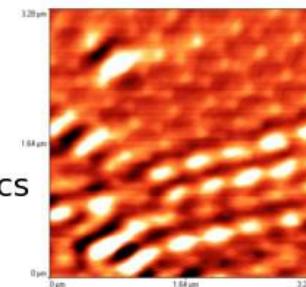
Dimensional measurements guidelines:

- calibrate your microscope (at least once a year)
- know your probe
- if you have doubts about your measurement, rotate the sample by 90 degrees
- follow all the data processing guidelines provided in yesterday's talk

SPM – scanning probe microscopy

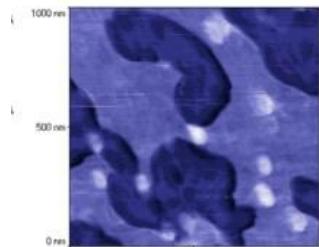


Morphology from microscale
to nanoscale

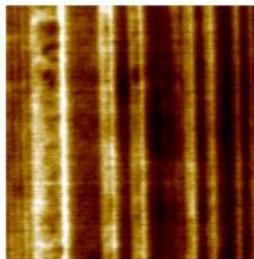


Optics and plasmonics

Local mechanical properties

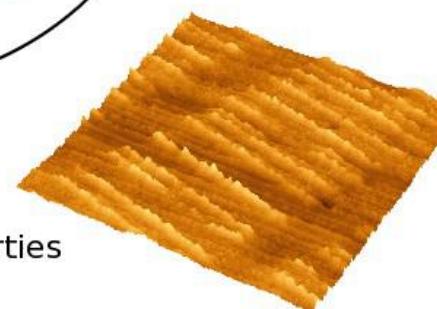
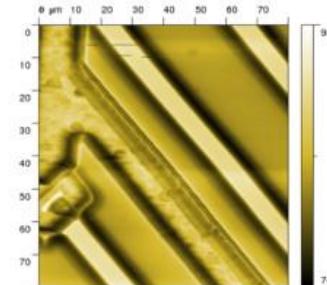


Electrical properties,
forces and capacitance



Magnetic properties

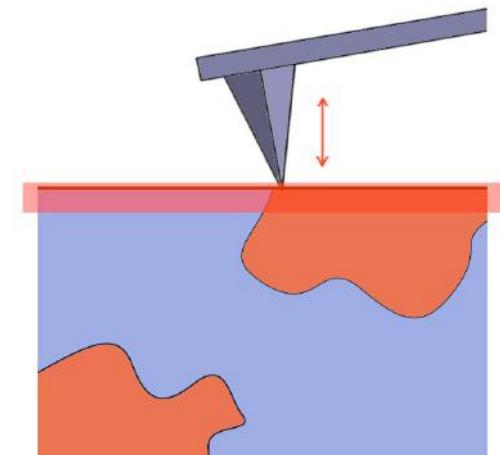
Temperature and
thermal conductivity



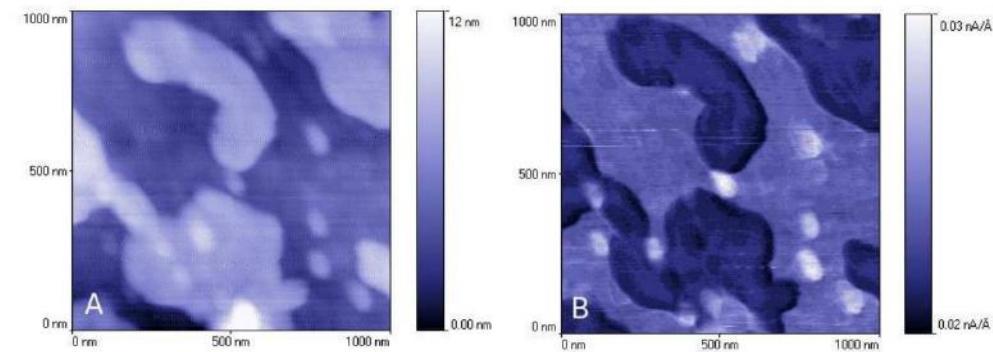
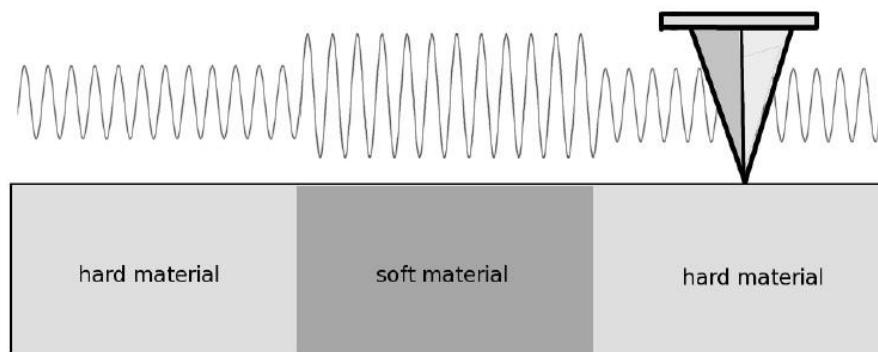
Motivation

Since very beginning there were some attempts to use the force-distance data in AFM for some viscoelastic properties mapping.

Z-modulation technique was one of the first trials.



With advent of fast FPGA based controllers we can see massive improvements by nearly all the manufacturers.



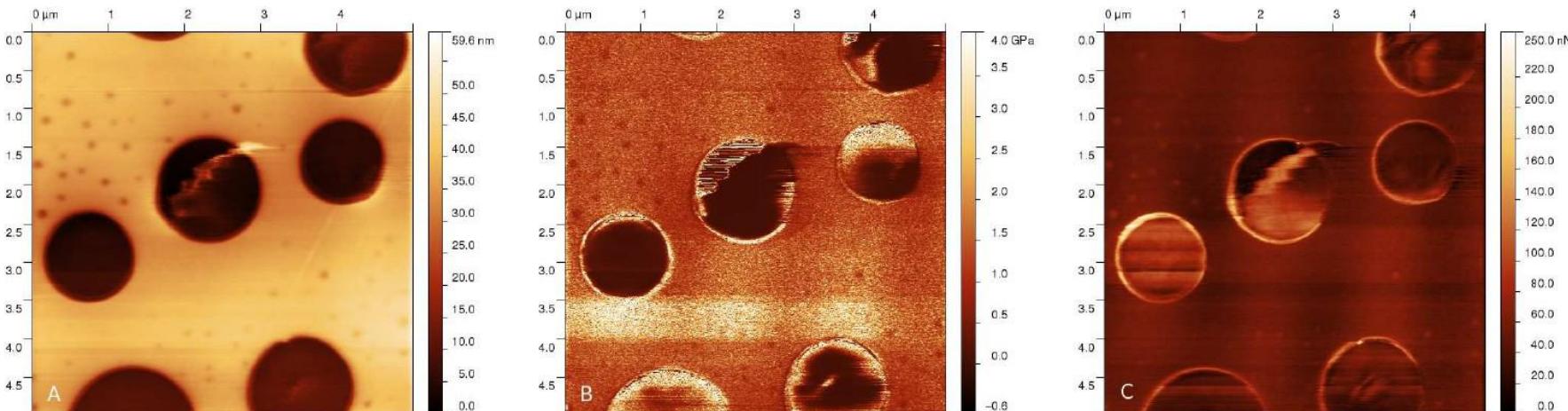
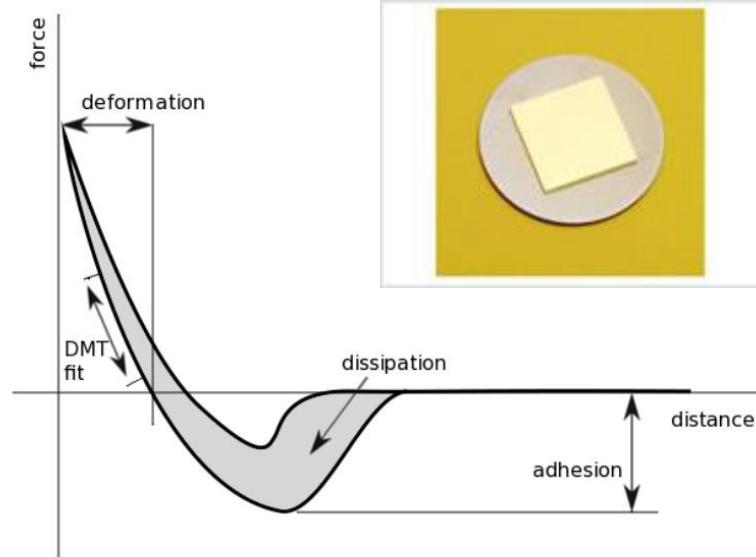
Various brand names:

PeakForce QNM (Bruker), Quantitative Imaging (JPK),
PinPoint (Park), RSI (NT-MDT). They differ only in details

Principle: Indentation at every pixel

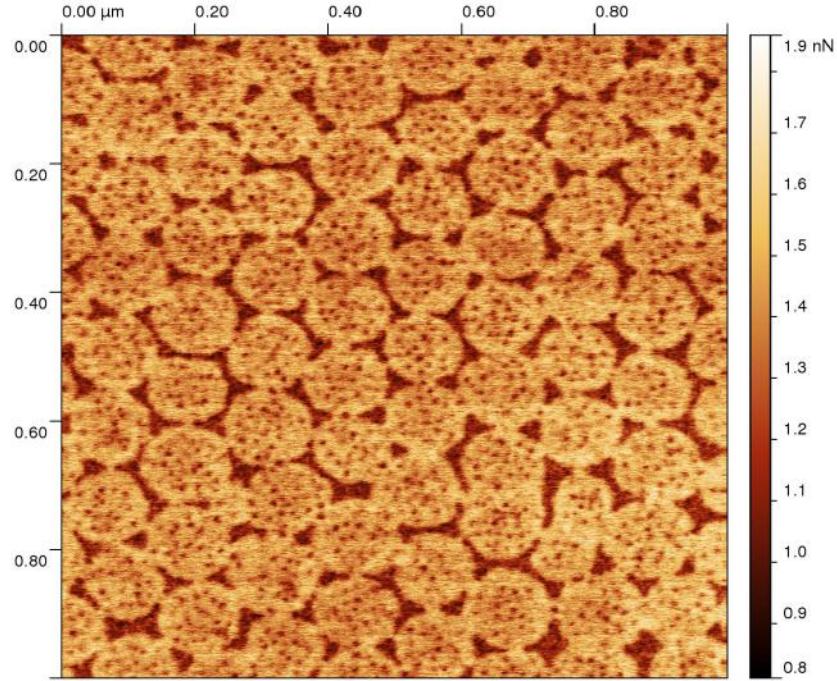
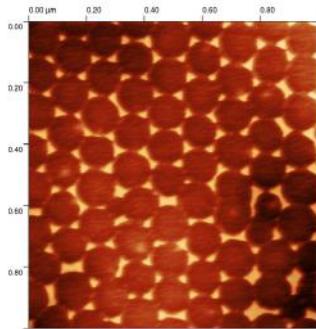
Benefits: small indentation depths, very high resolution

Reference samples: still a problem, two component polymer mixtures are good test sample.



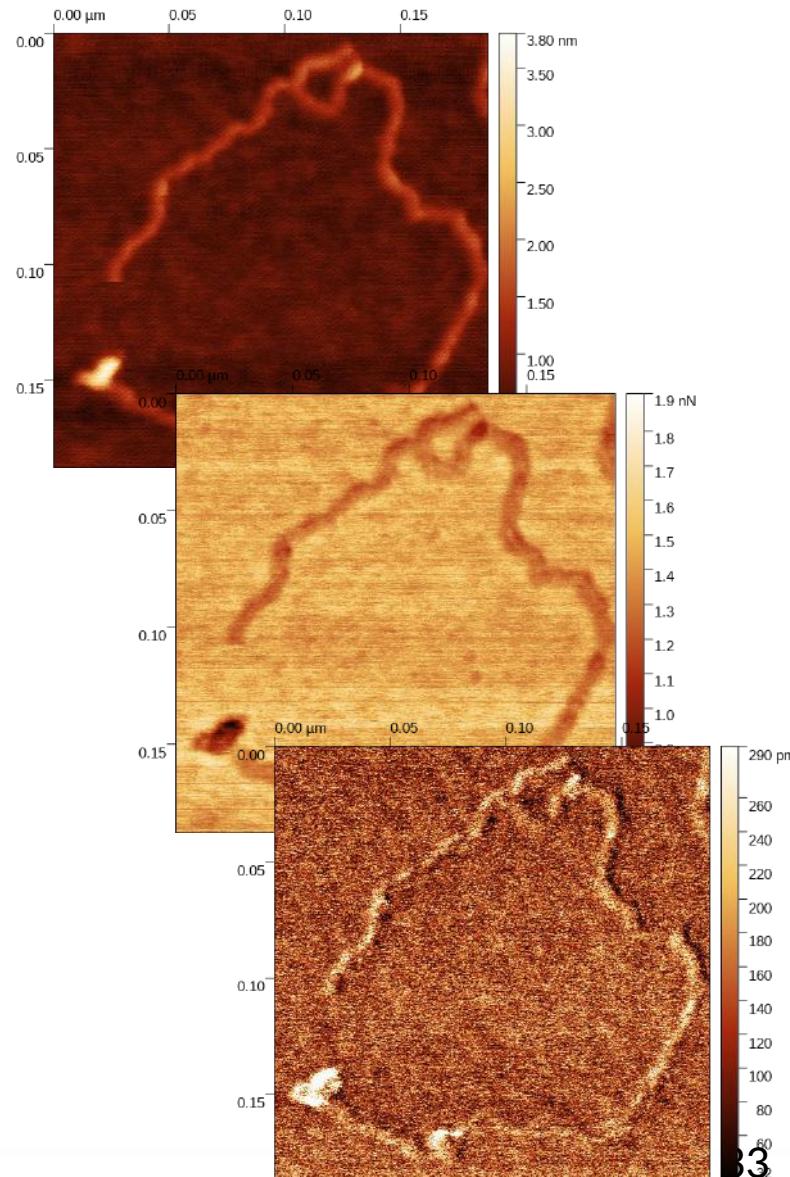
Applications:

Many impressive results on biological samples, like cells or tissues, on polymers, single molecules and molecular films, graphene and other 2D materials, thin films, nanocomposites.



Sample courtesy:

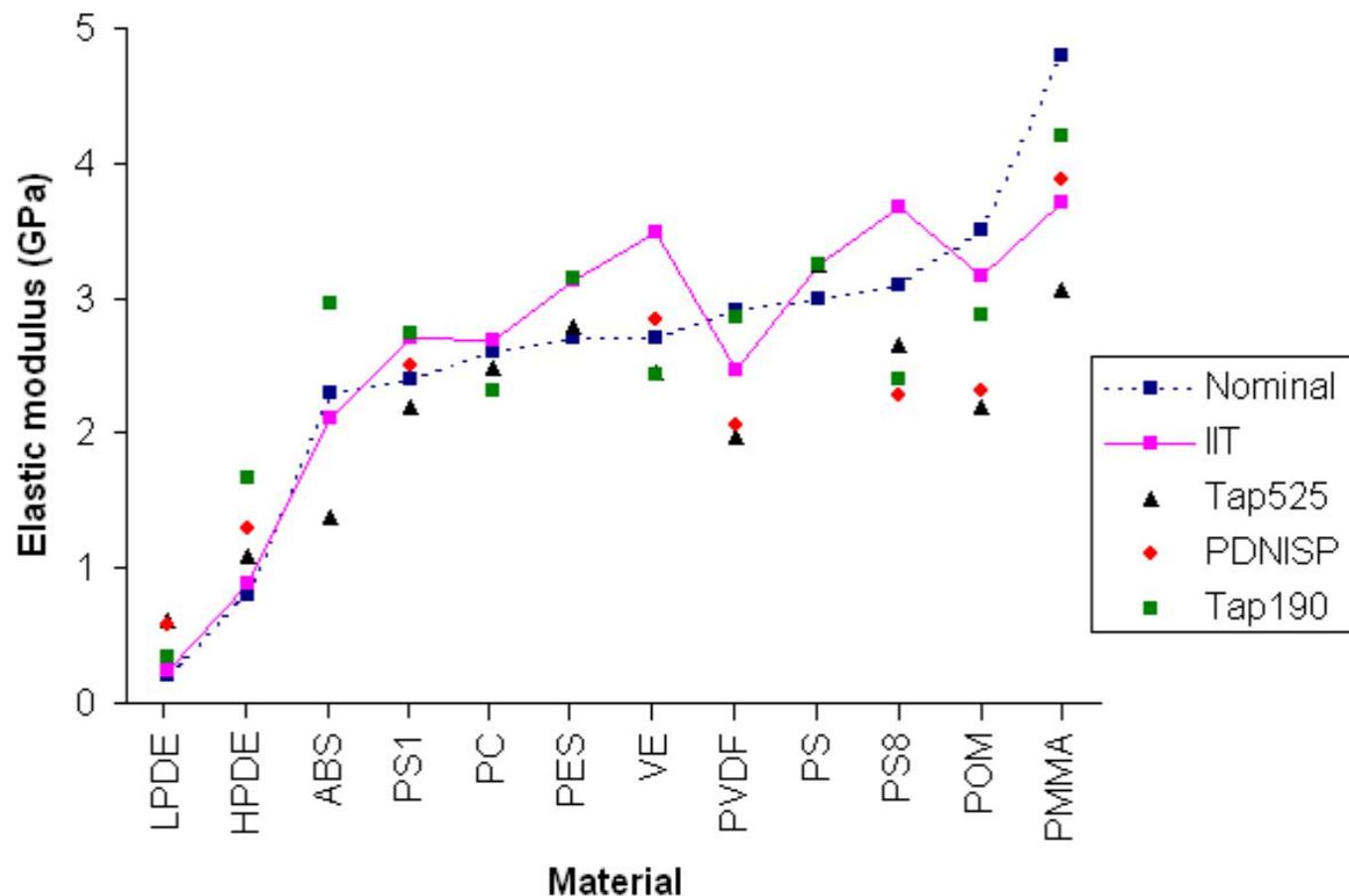
Petr Marek



Accuracy and traceability?

There are only few studies on method accuracy in the literature.

http://epubs.surrey.ac.uk/722268/3/Young_et_al%2C_Peak_Force_QNM.pdf



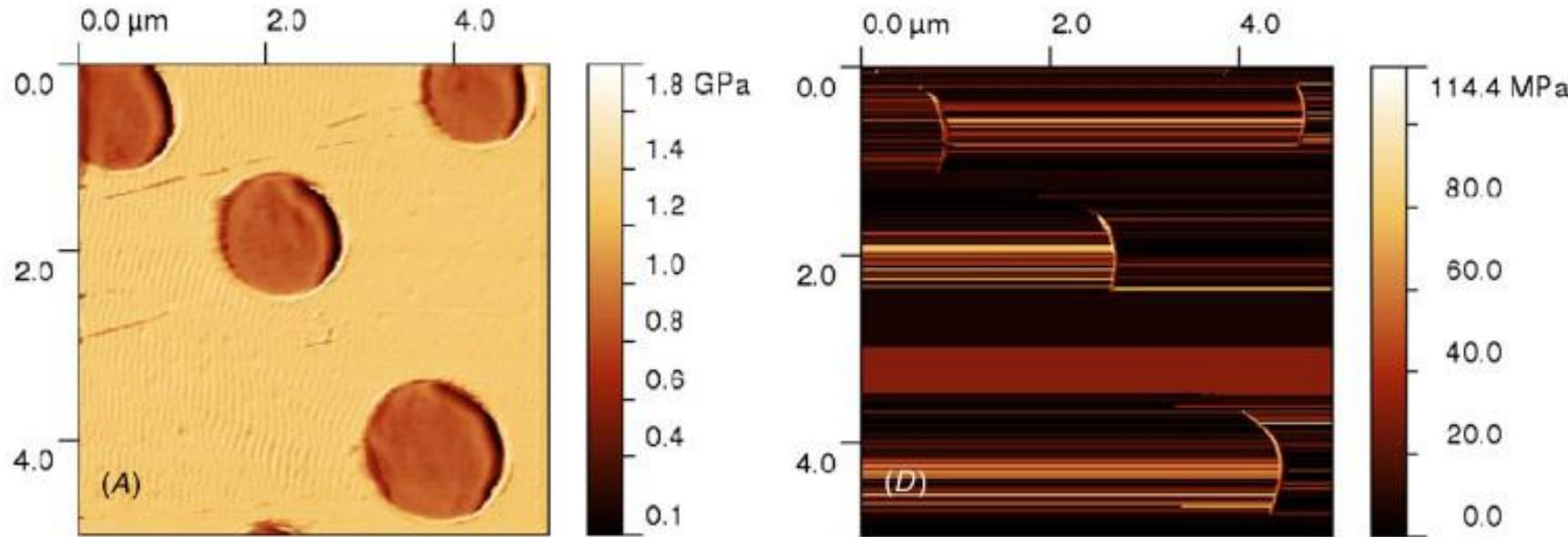
Accuracy and traceability?

Measurement protocol needs to be very carefully followed to get anything quantitative. Even after that, manufacturer's calibration routines have limited accuracy.

Wide range of potential results depending on settings, e.g. tip radius.

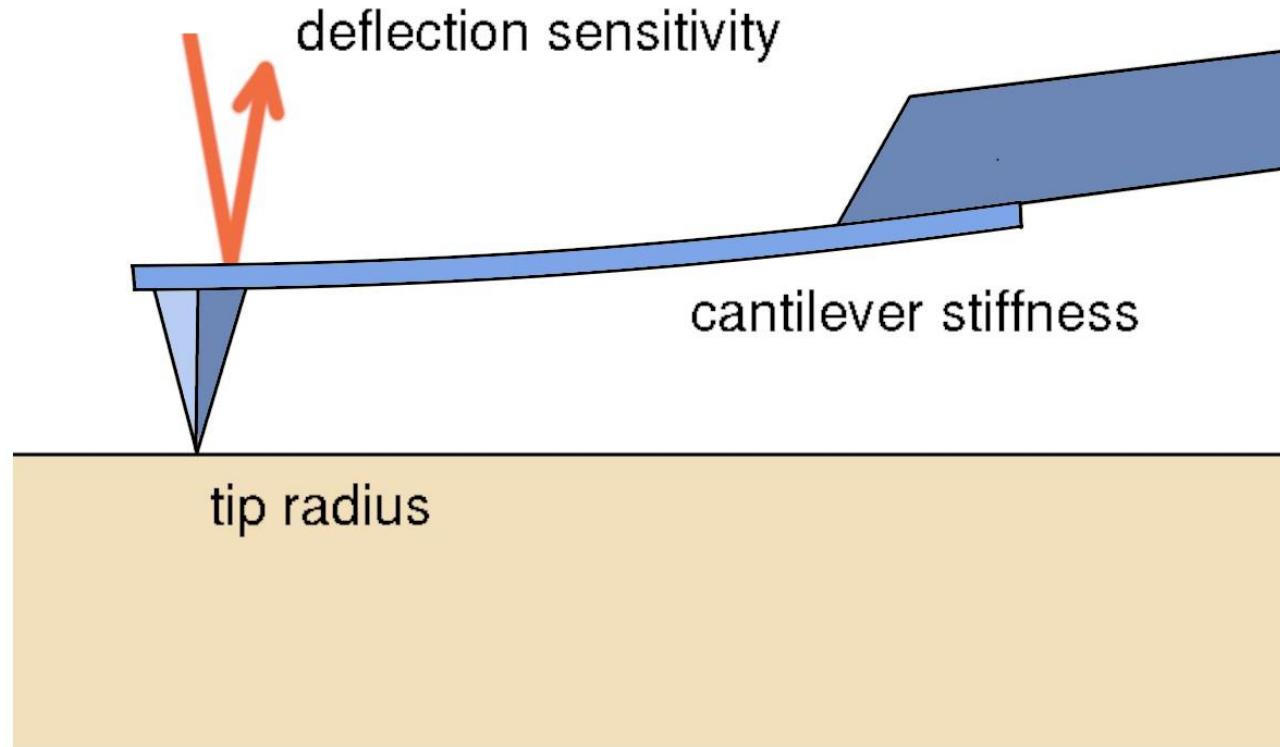
Real time data analysis does not work always, which can be easily unnoticed.

It is assumed that results can be about 10 percent accurate. How often this happens?



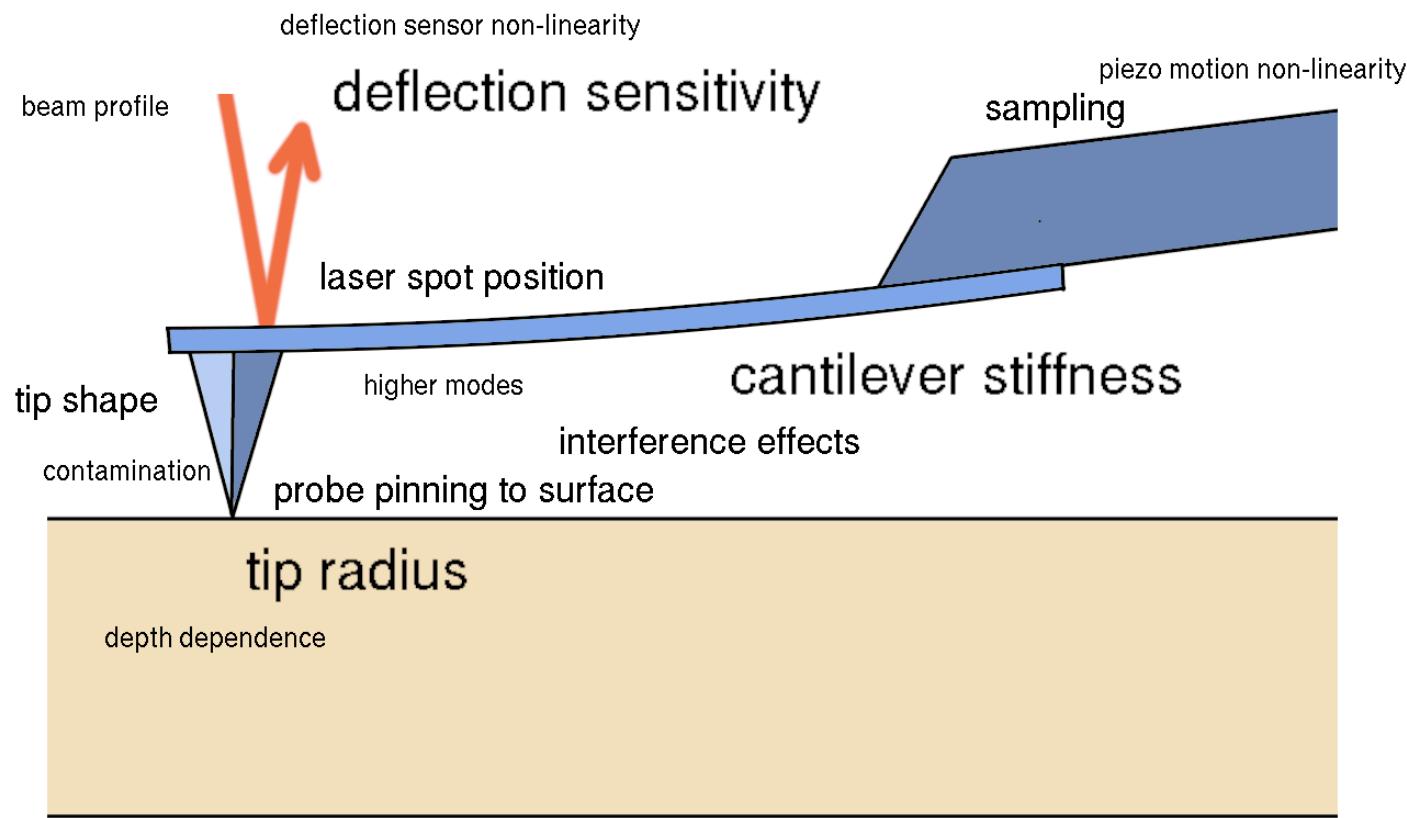
The key elements in SPM are the probe/cantilever assembly and the optical pickup.

Parameters most affecting the measurement:

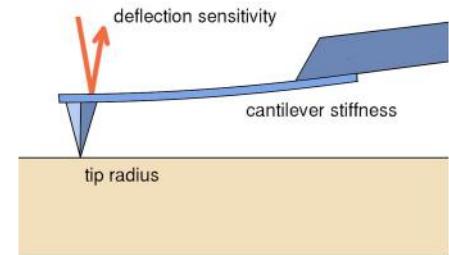


The key elements in SPM are the probe/cantilever assembly and the optical pickup.

Reality is even worse:



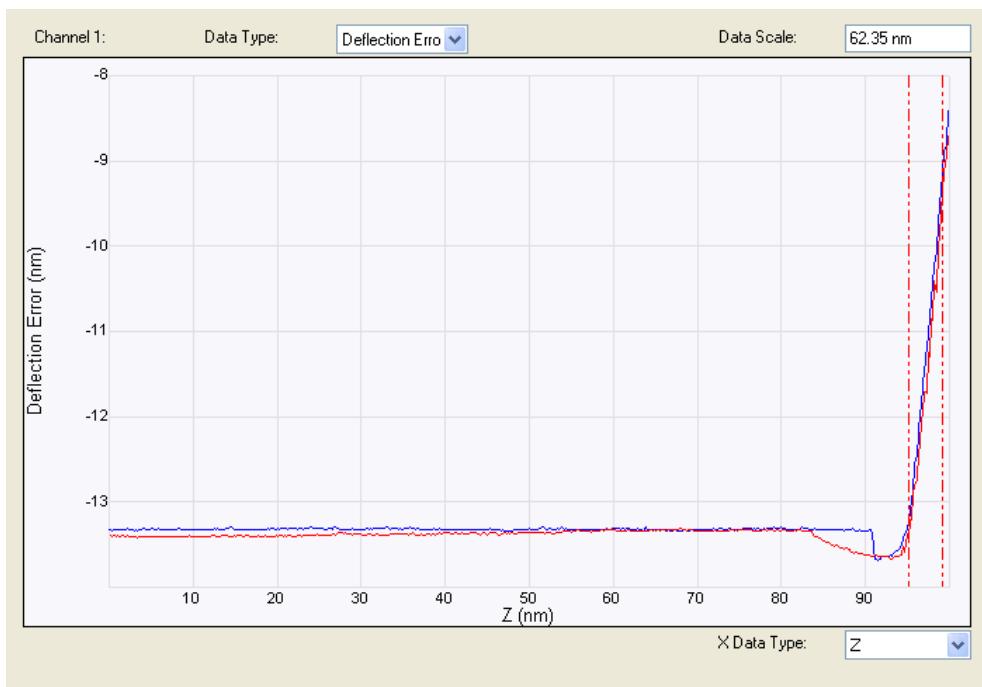
This includes calibration of the whole sensing element of the microscope, including the laser alignment, position sensitive detector settings and electronics readout.



It needs to be done for each probe, everytime it is mounted and it is done via pressing the cantilever towards hard surface (e.g. sapphire).

Unless we want to measure similarly hard surfaces, it works fine.

Variance of the results is in percents.

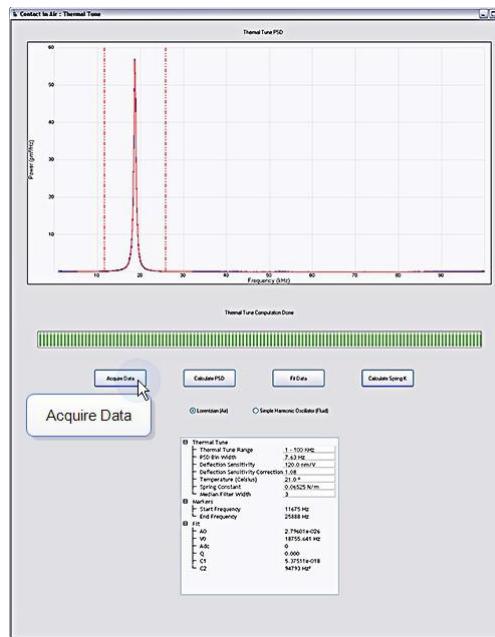
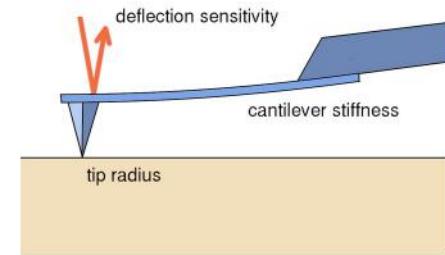


Cantilever stiffness

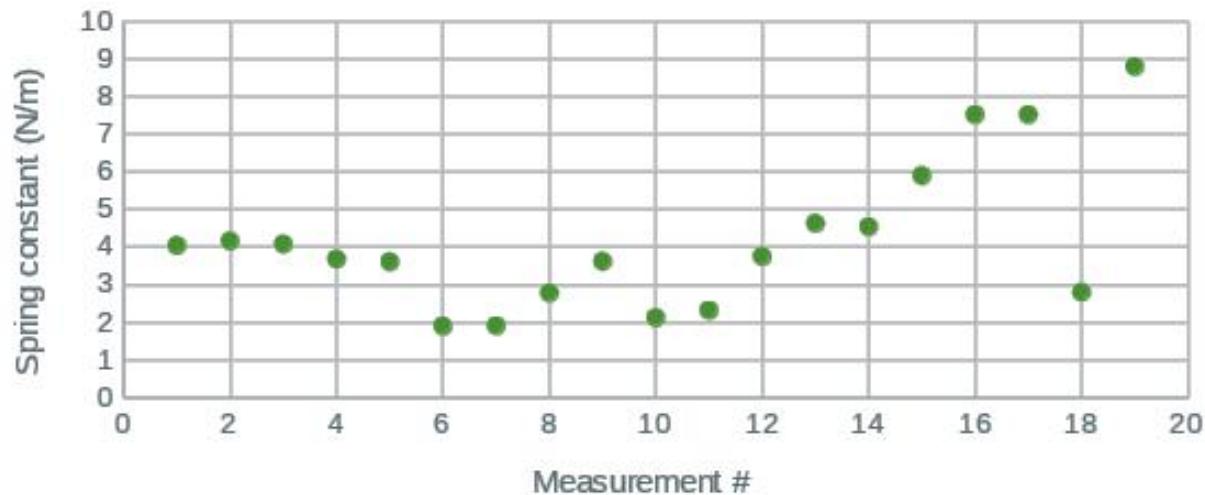
Our sensor measures deflection, not force.

Stiffness calibration needs to be done.

The most common and built-in methods are based on thermal fluctuations, which can be done up to about 10-15 N/m cantilever stiffness.



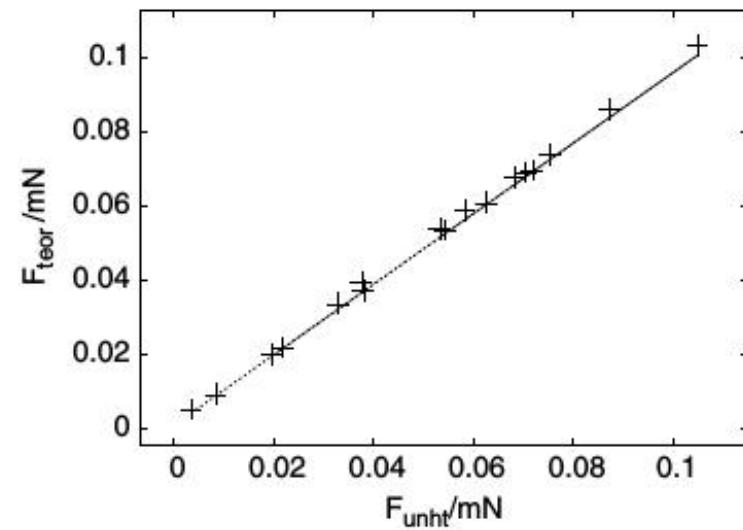
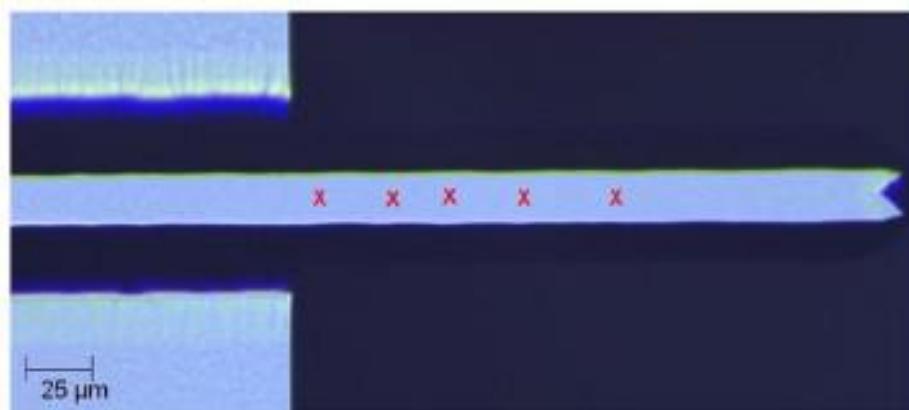
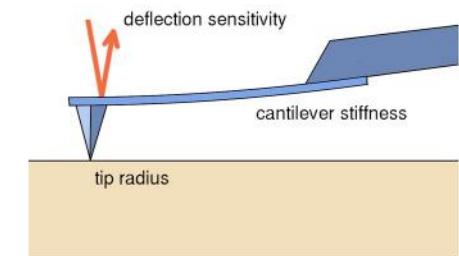
Thermal Tune PPP MFMR Spring Constant



Cantilever stiffness

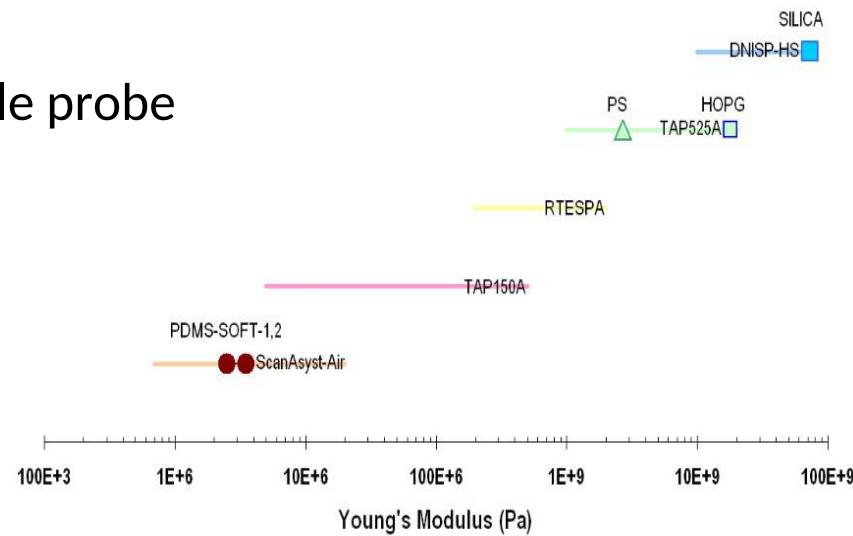
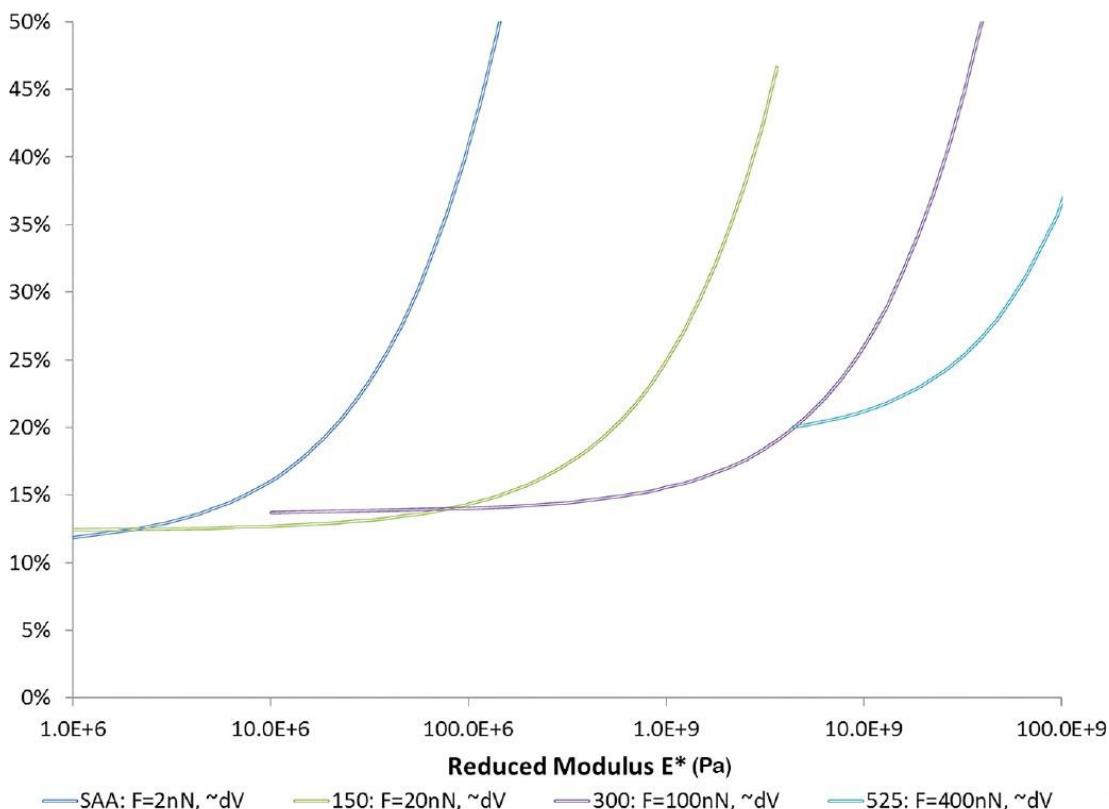
There are many more elaborated methods, some of them having uncertainties below 10 percent.

One of them is to use the instrumented indentation and measure the dependence of force and displacement on the cantilever. In principle even a single measurement should work.



A Campbellová *et al* Meas. Sci. Technol. **22** (2011) 094007

Not every probe is suitable for every measurement

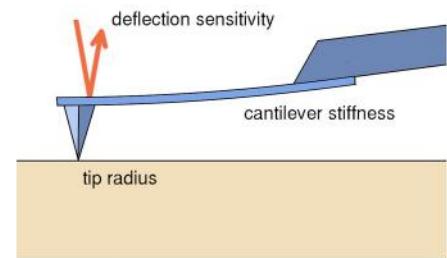
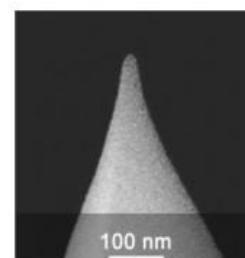
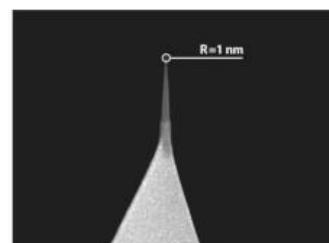
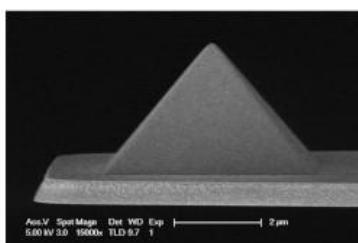
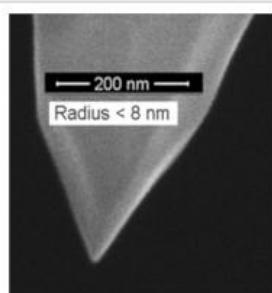
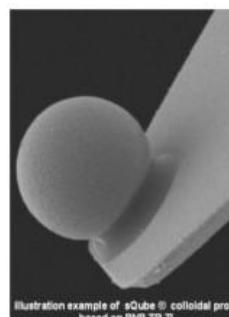
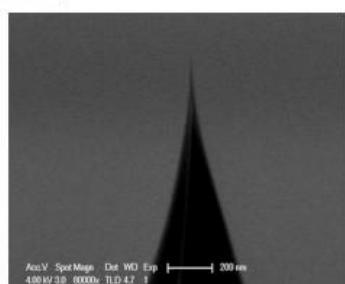
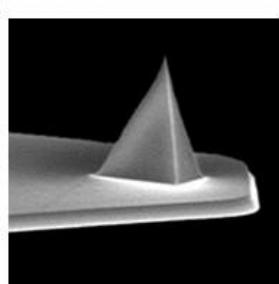
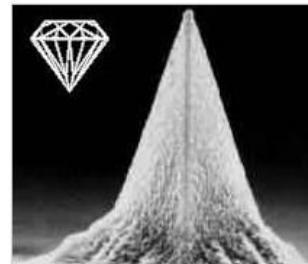
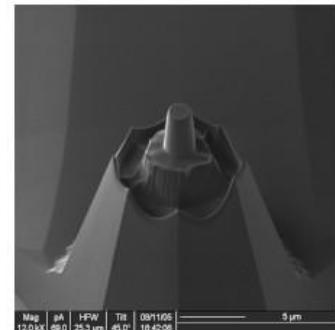
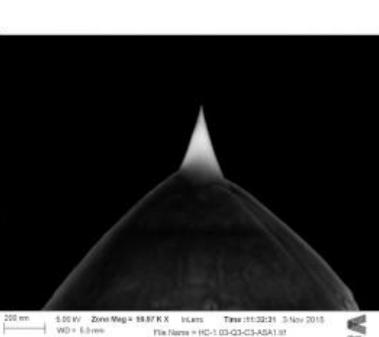
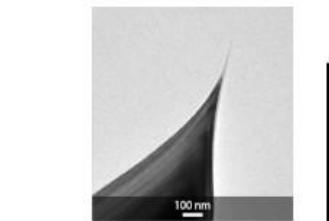


Probe	Radius (nm)	k_c (N/m)	Min. E (MPa)	Max. E (MPa)
SAA-HPI-30	33	0.25	0	15
RTESPA150-30	33	5	5	500
RTESPA300-30	33	40	200	8,000
RTESPA525-30	33	200	1,000	50,000
DNISP-HS	40	450	10,000	100,000

Bruker App note DOI: 10.13140/RG.2.2.15272.67844

Tip radius estimation

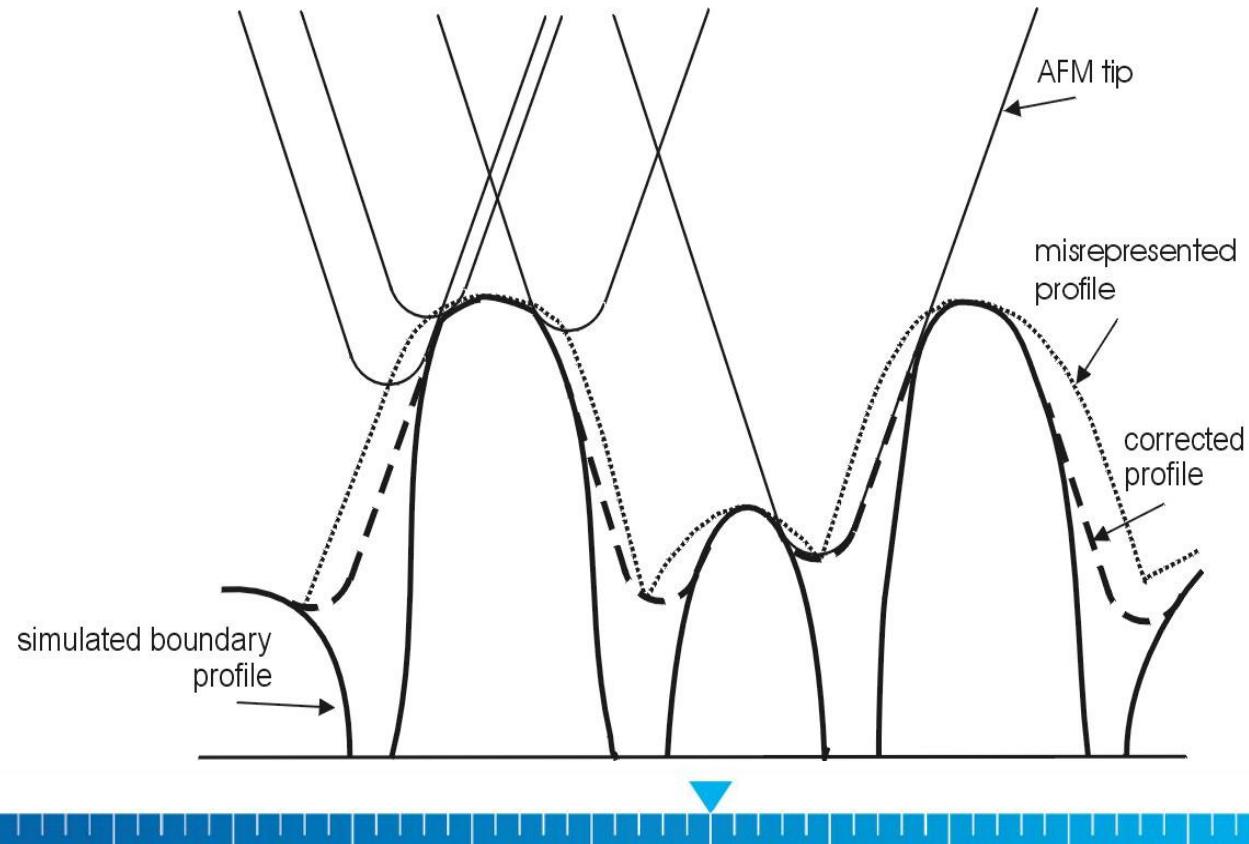
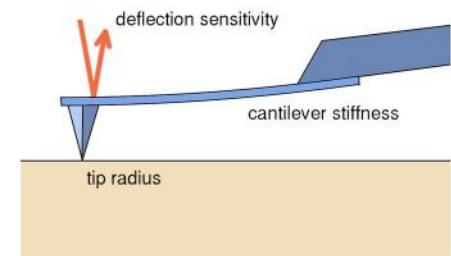
Tip radius needs to be determined and **constant**.



Tip radius estimation

Tip radius needs to be determined and **constant**.

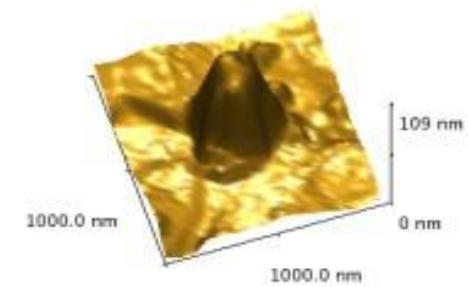
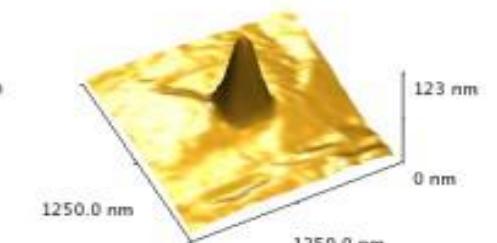
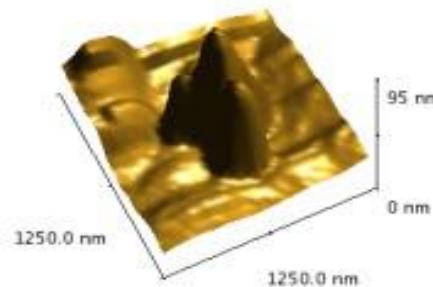
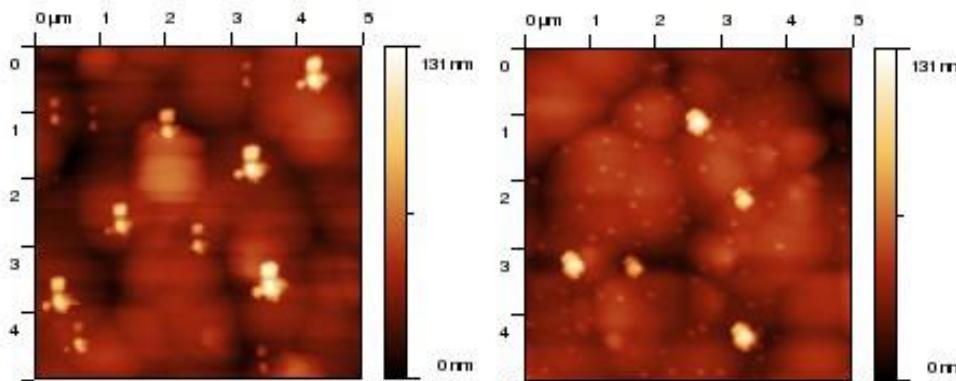
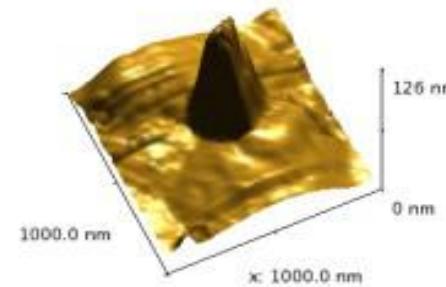
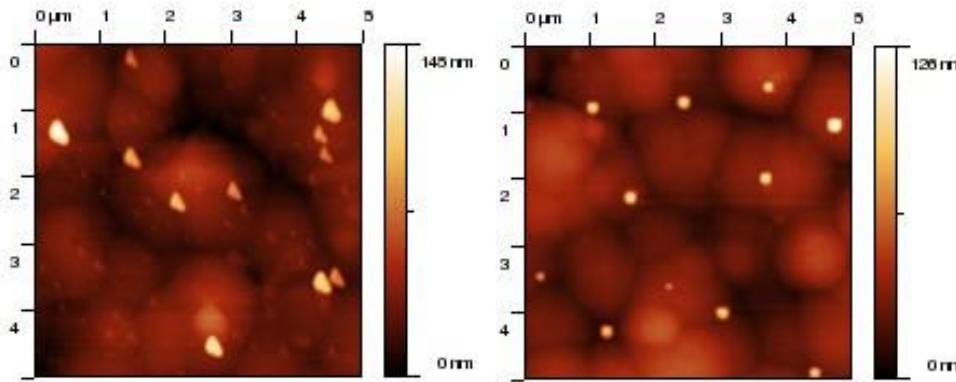
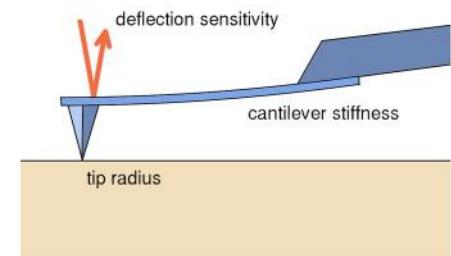
We use tip-sample convolution to determine it, scanning a known surface.



Tip radius estimation

Tip radius needs to be determined and **constant**.

We use tip-sample convolution to determine it, scanning a known surface.



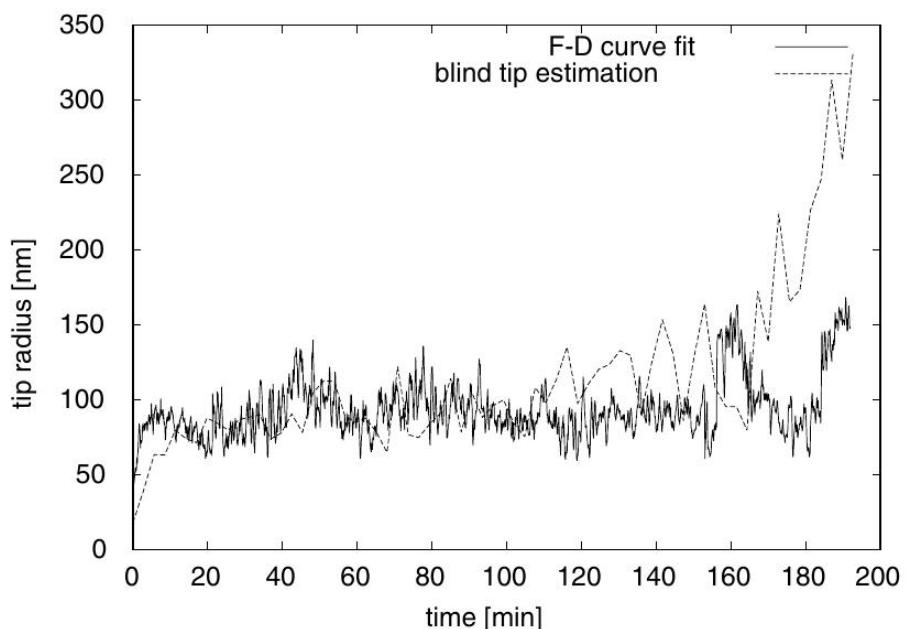
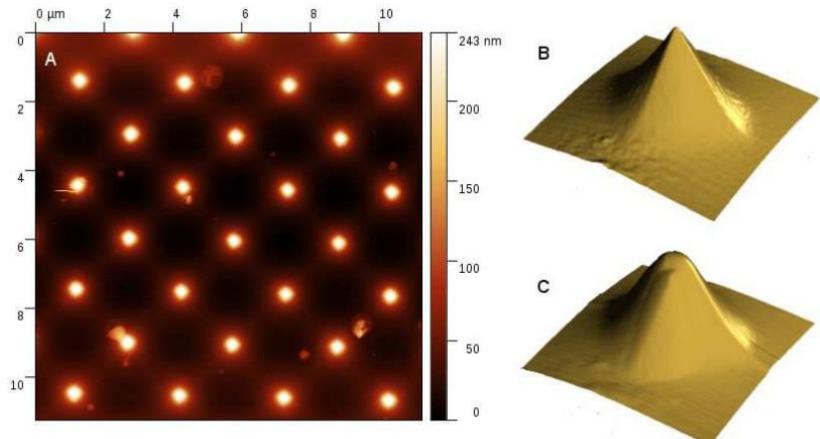
Reference samples for radius determination are usually part of the calibration set for nanomechanical mapping

However, radius can change (and often changes) while scanning.

Also while scanning the reference samples.

It is therefore very likely that our tip radius might be wrong by tens of percents.

P Klapetek and D Nečas
Meas. Sci. Technol. **25** (2014) 044009

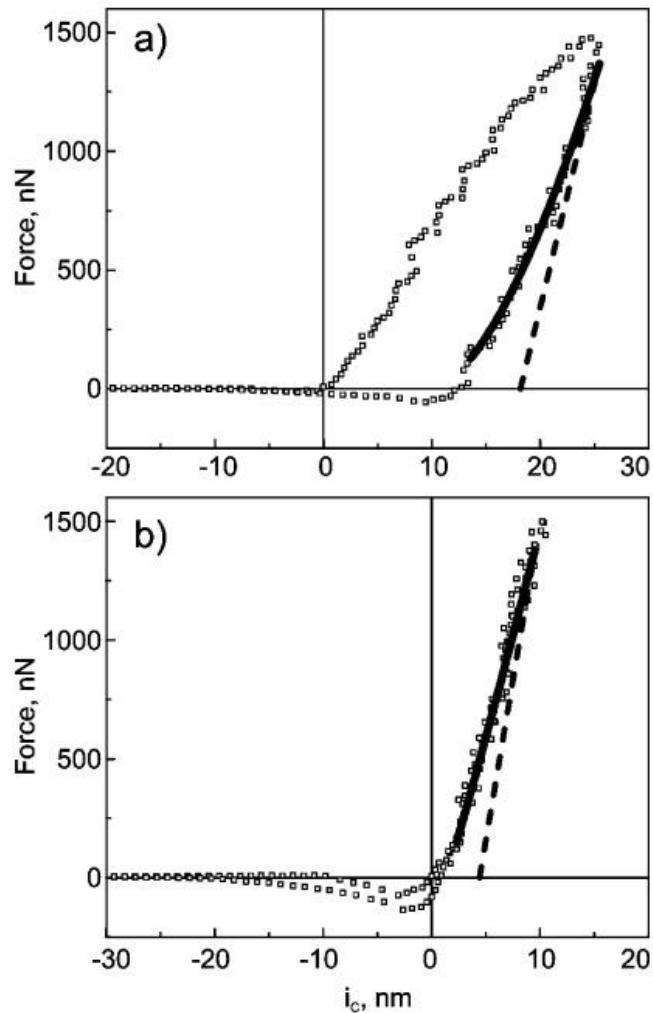


Sharp probe is however always **not ideal** tool for nanomechanical measurements.

It can lead to plastic deformation of the sample (or probe) and if high resolution is not needed, results obtained with somewhat blunt probe can be more reliable.

See e.g. images on left from: Dokukin, M.; Sokolov, I. *Macromolecules* 2012, 45, 4277–4288.

Some manufacturers even sell spherical probes with large radius (e.g. 200 nm), but usually the sphere material is not very hard.



Two potential approaches are used for getting the measurements traceable

Absolute method: probe radius is determined on a tip check sample

Benefits: good for understanding what happens

Drawbacks: limited applicability

Relative method: one or two reference samples are used and probe radius is matched to get the correct results

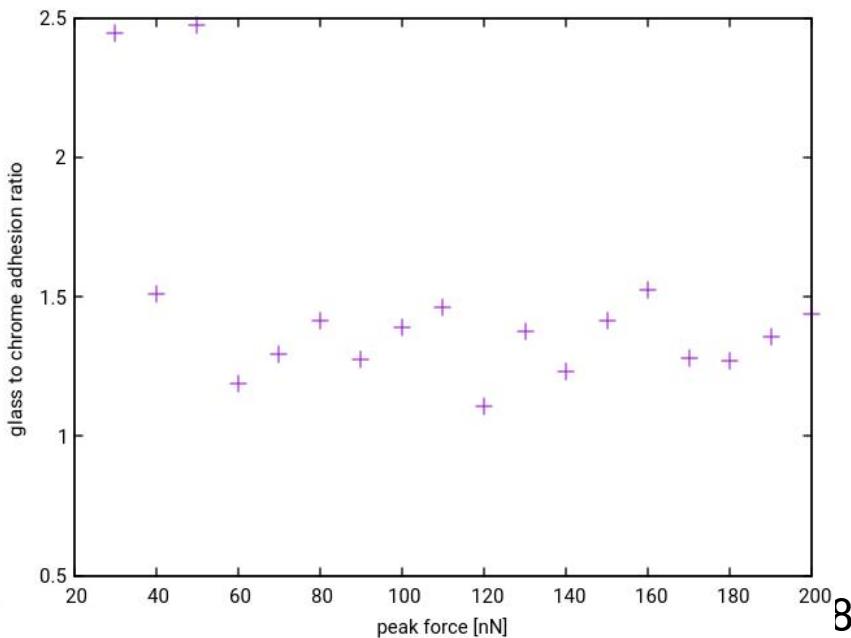
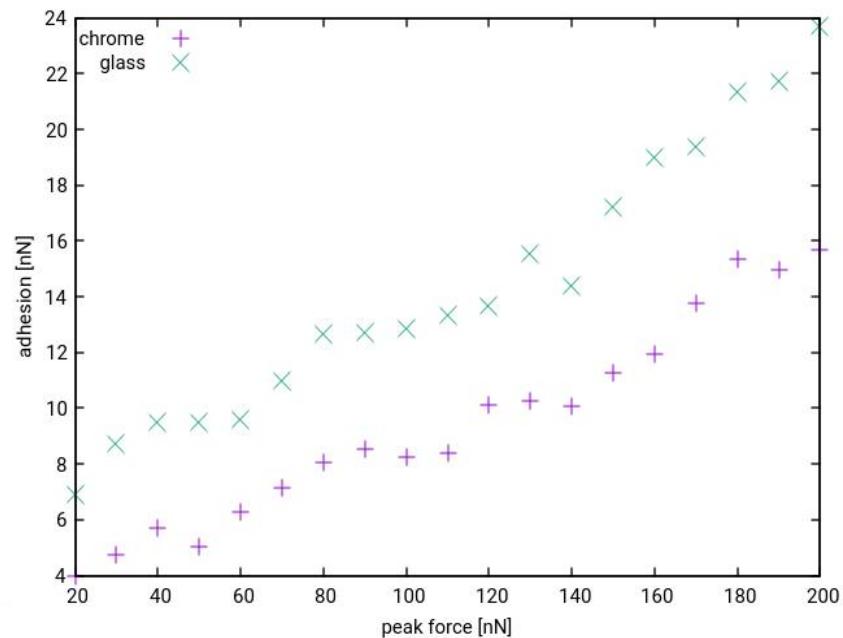
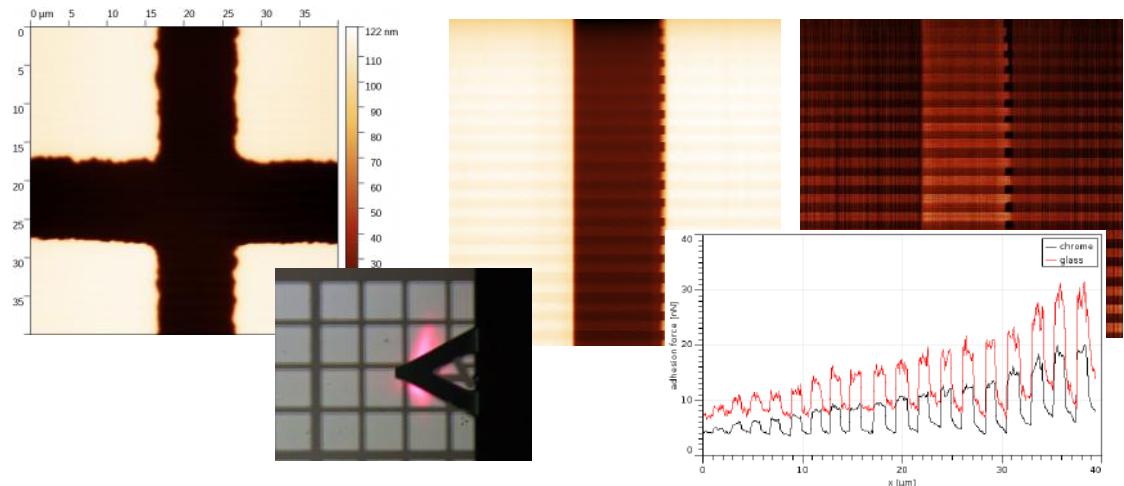
Benefits: many systematic errors can be hidden into it

Drawbacks: relies on reference samples, measurement on unknown sample should be similar.

Dependence on load

Chrome on glass sample

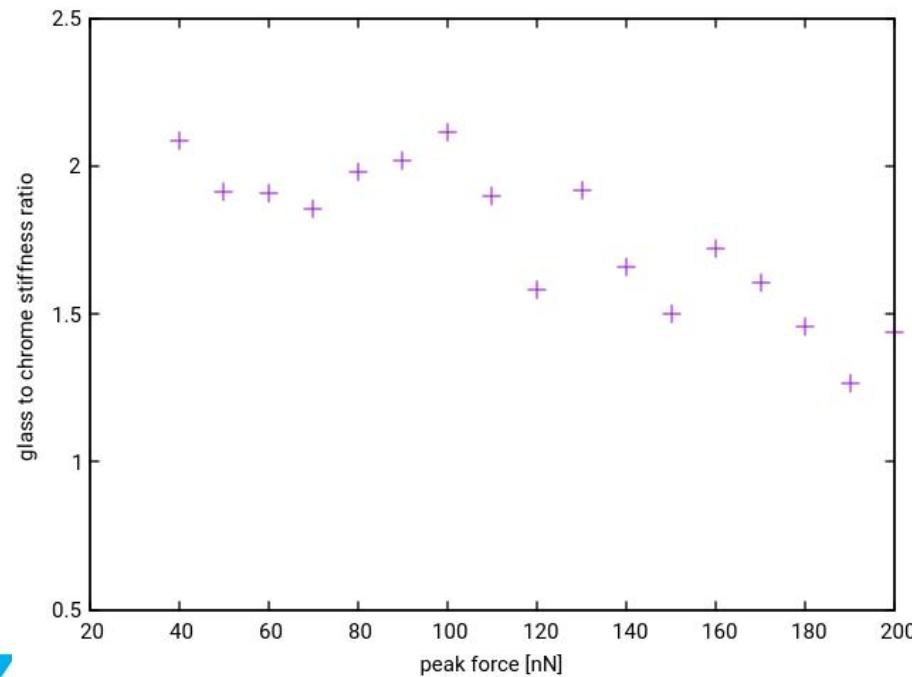
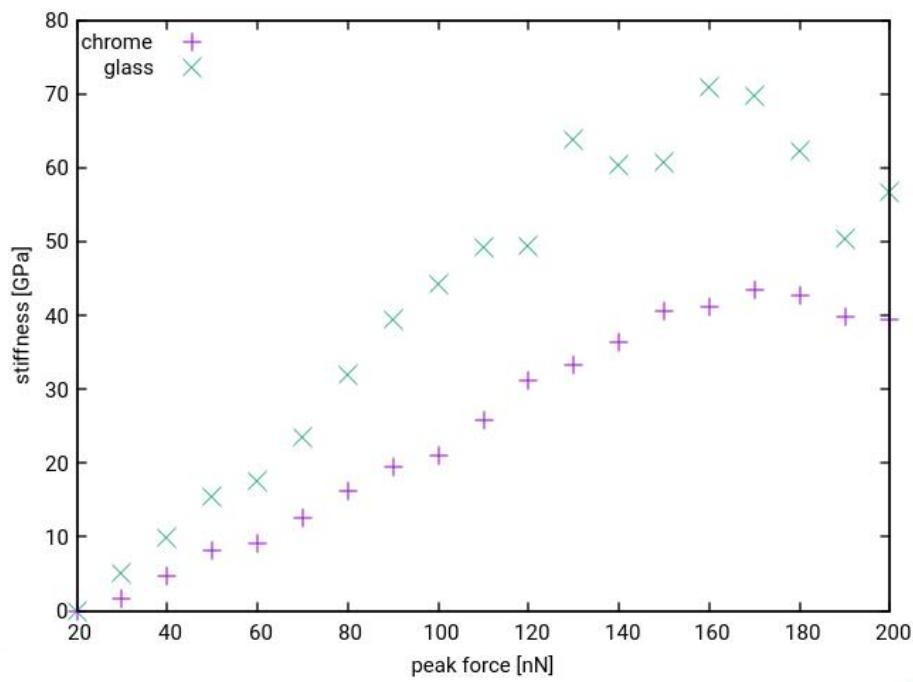
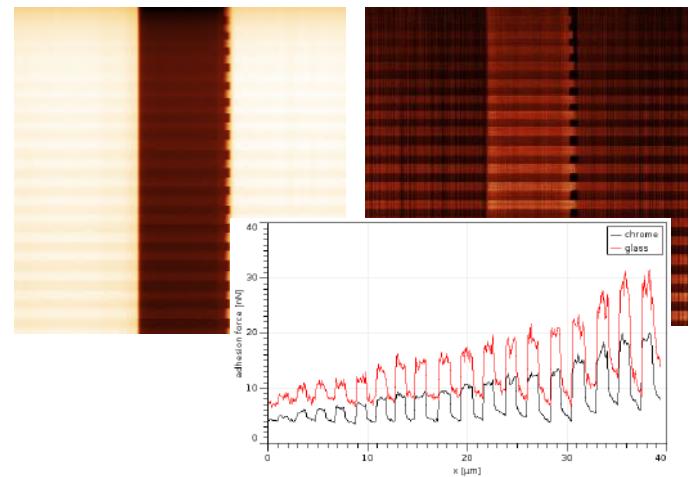
Adhesion channel evolution for different peak forces.



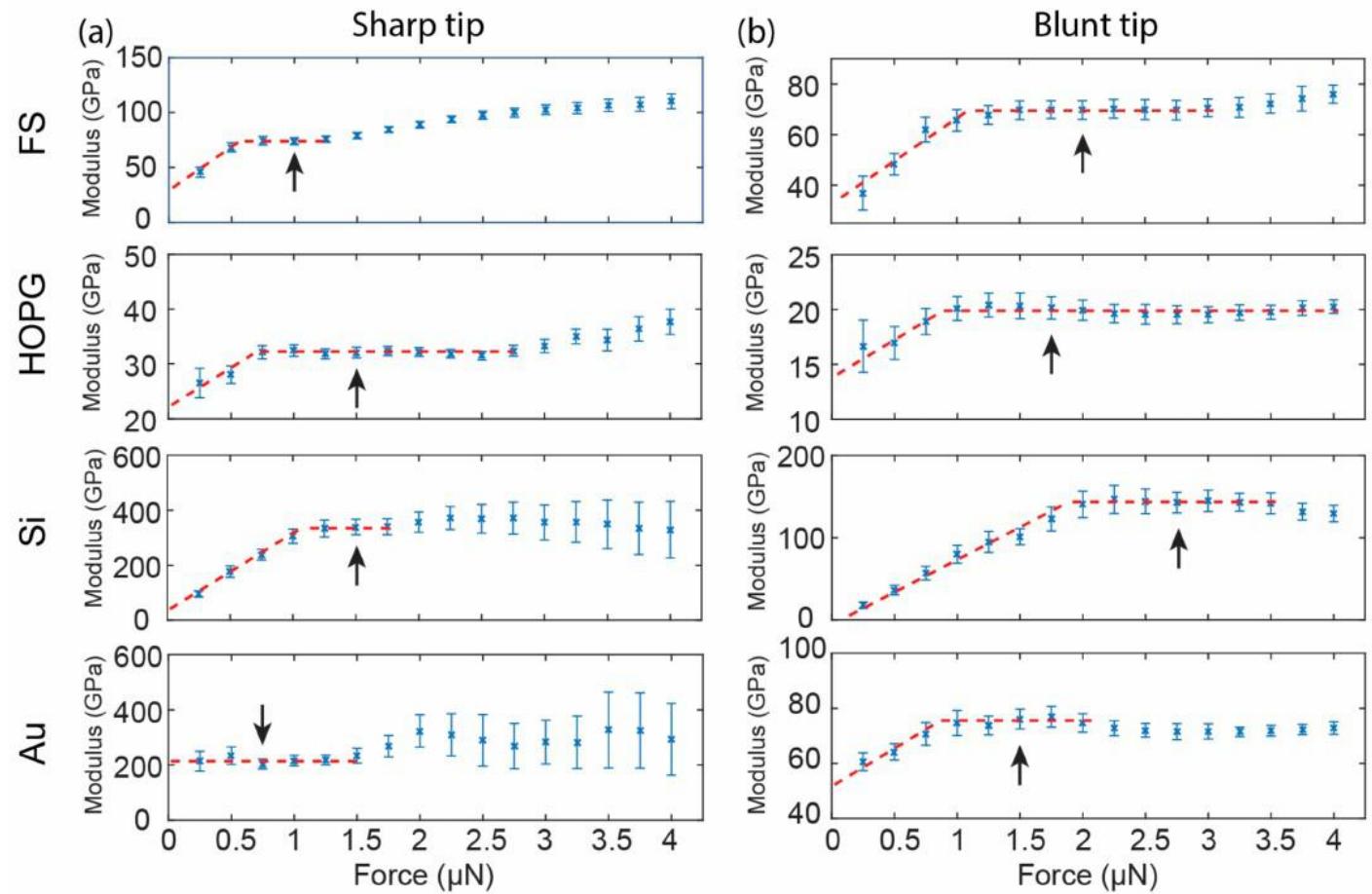
Dependence on load

Chrome on glass sample

DMT modulus channel evolution for different peak forces.

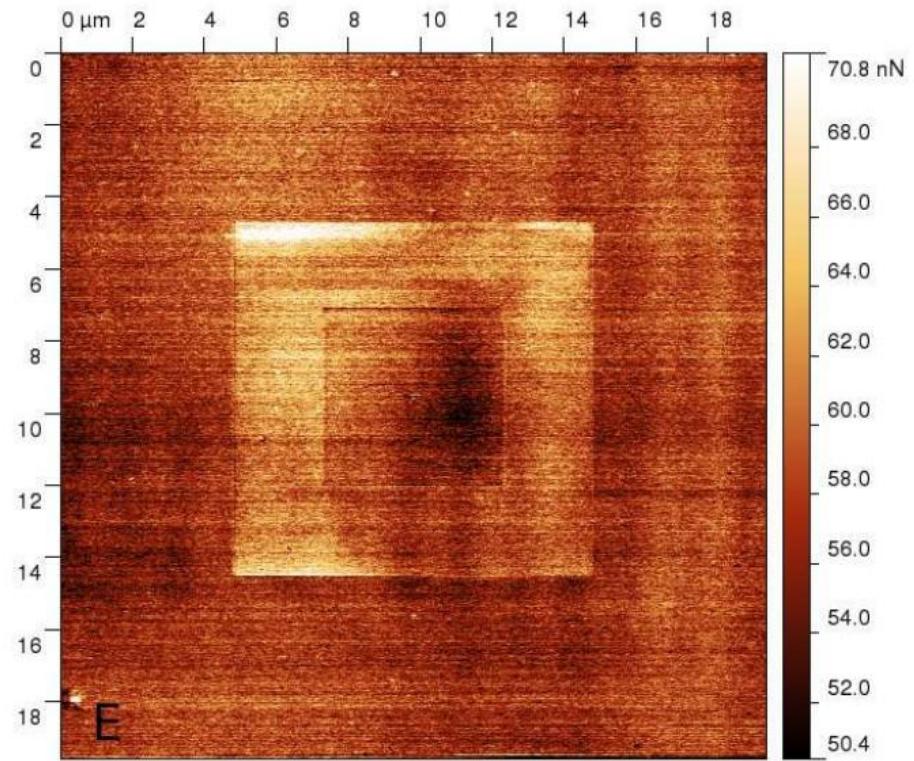
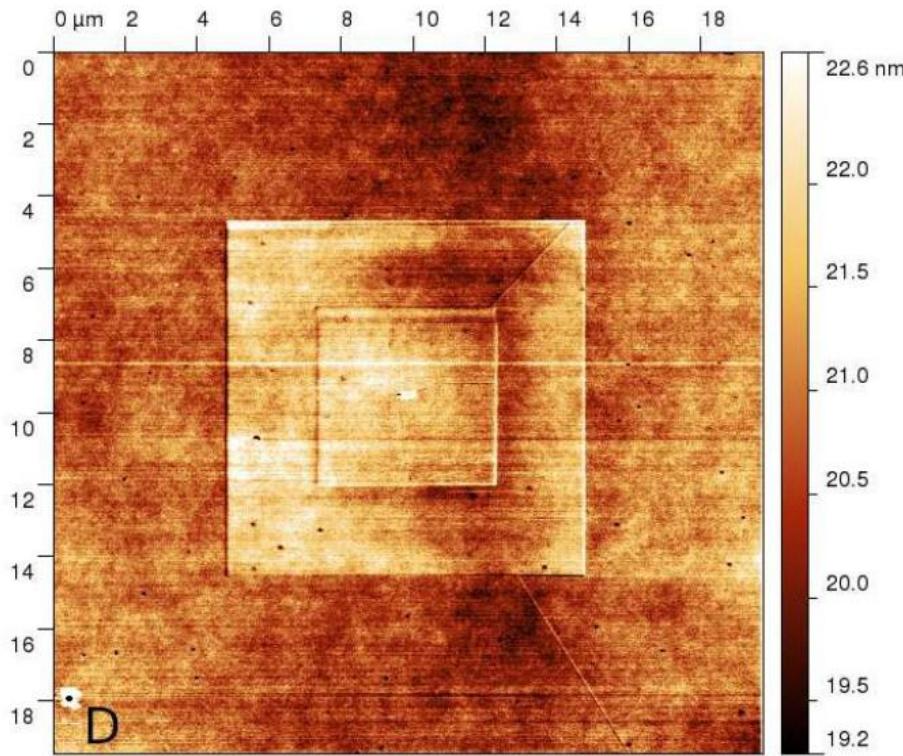


Dependence on load was observed also by other authors



Still non-destructive technique?

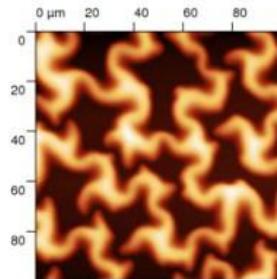
Residuals on silicon surface after repeated PeakForceQNM measurement (topography and adhesion channel)



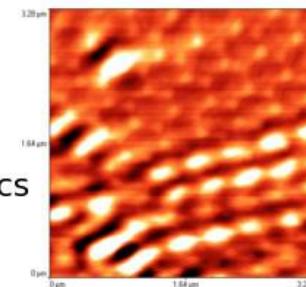
Mechanical measurements guidelines:

- calibrate your probe (deflection sensitivity and stiffness), do not believe default values
- determine your probe radius after measurement
- use some test sample to check that everything works
- store data for off-line processing

SPM – scanning probe microscopy

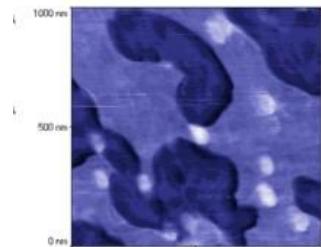


Morphology from microscale
to nanoscale

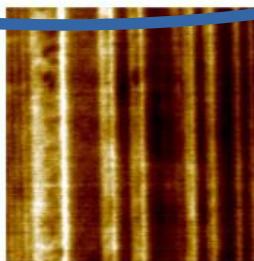


Optics and plasmonics

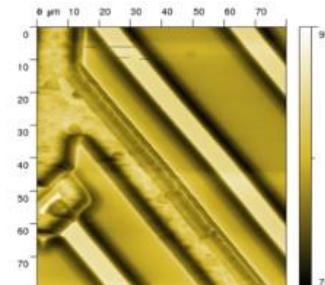
Local mechanical properties



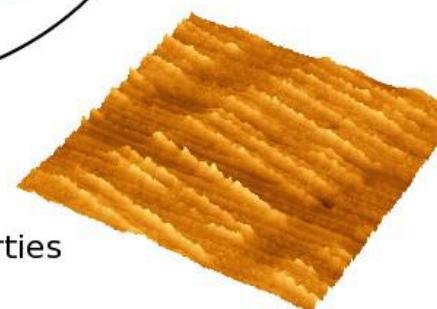
Electrical properties,
forces and capacitance



Temperature and
thermal conductivity



Magnetic properties



Conductive Atomic Force Microscopy

Conductive Atomic Force Microscopy

Use of electrically conducting probe connected to a transimpedance amplifier.

Applications:

Semiconductors, solar cells, 1D and 2D materials

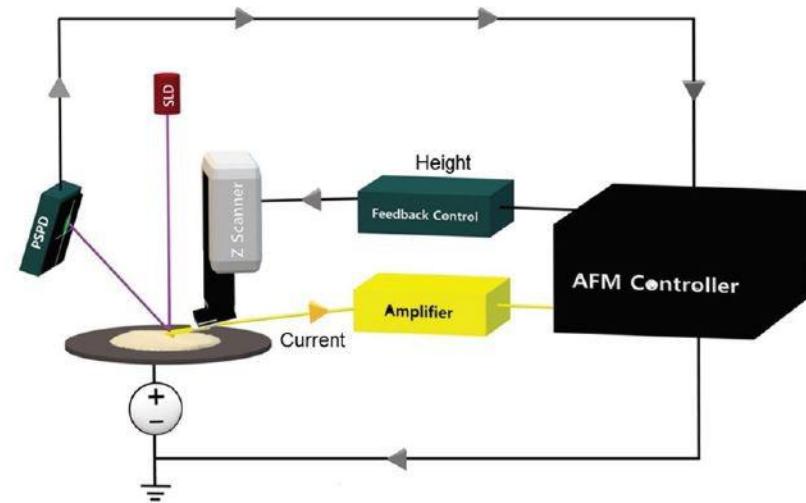
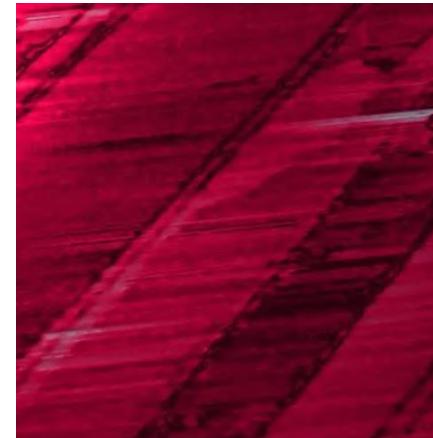
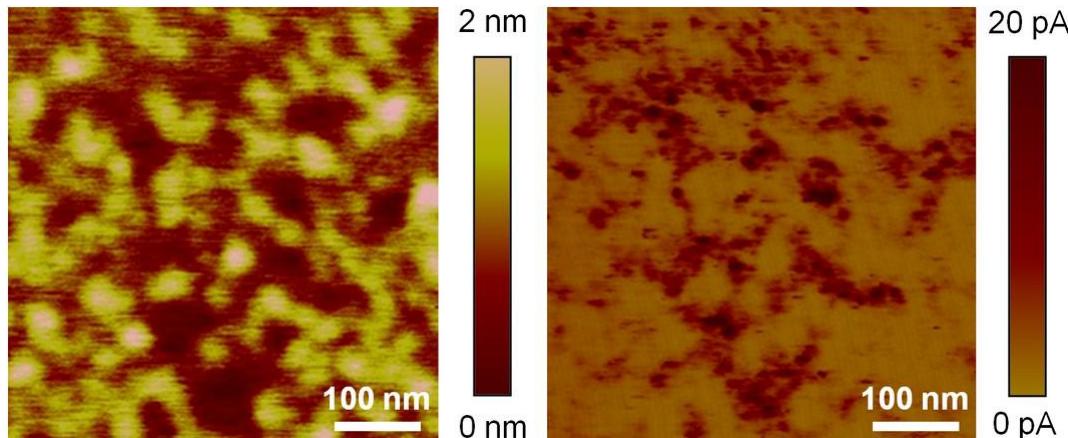


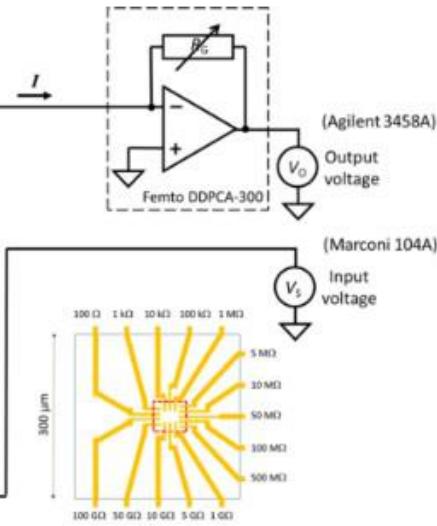
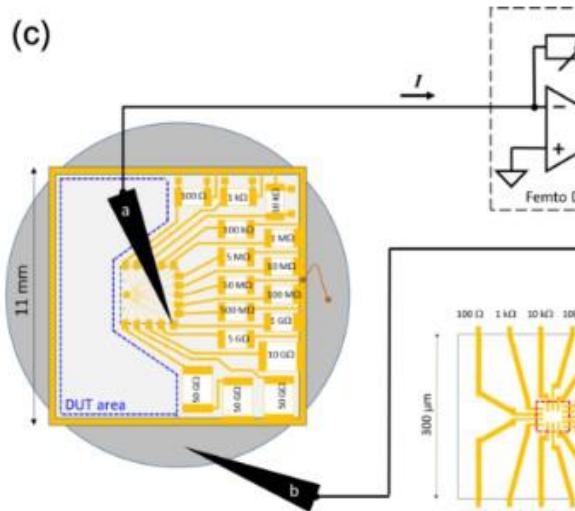
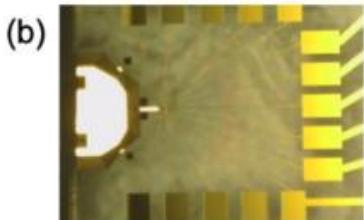
Image source: Park Systems, Wikipedia, Nanosurf



C-AFM reference samples?

“Multi-resistance standard” developed by French metrology institute LNE, within project EMPIR ELENA.

Set of SMD resistors with many decades of resistance, mounted on a glass block, with pads leading to the central part measurable using C-AFM.

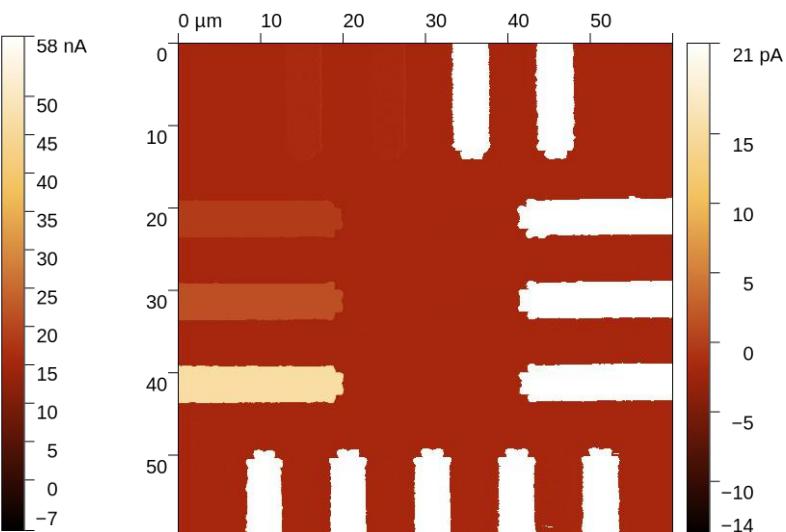
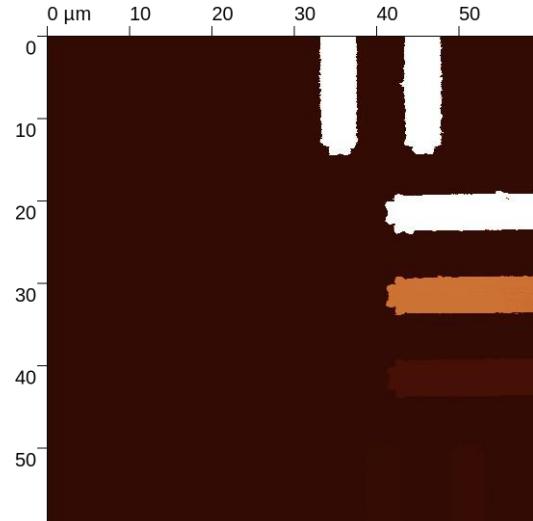
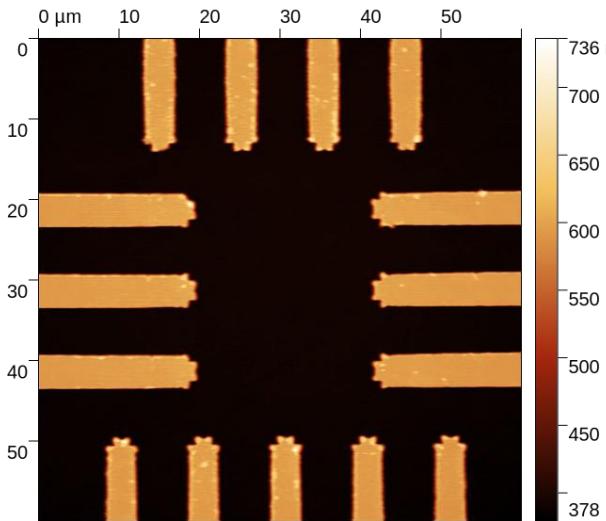
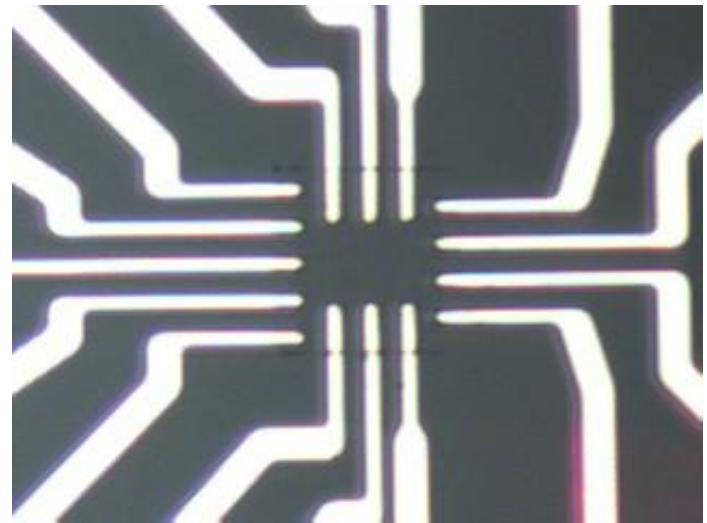


C-AFM reference samples

How to use the calibration sample?

Mapping the sample conductivity with some probe-sample bias.

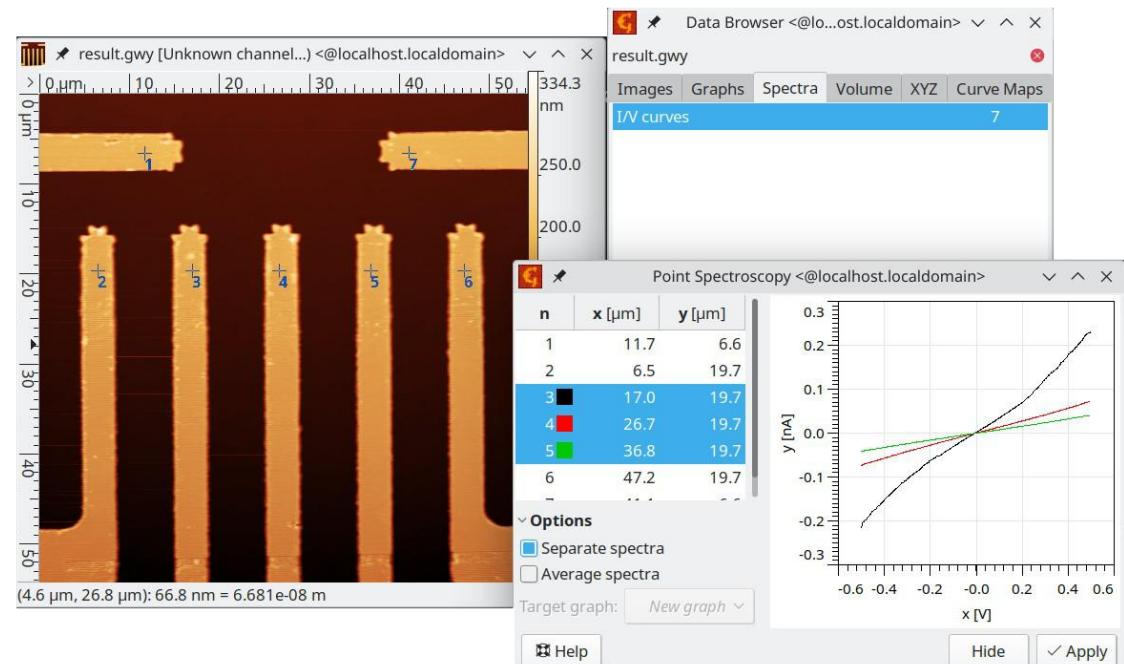
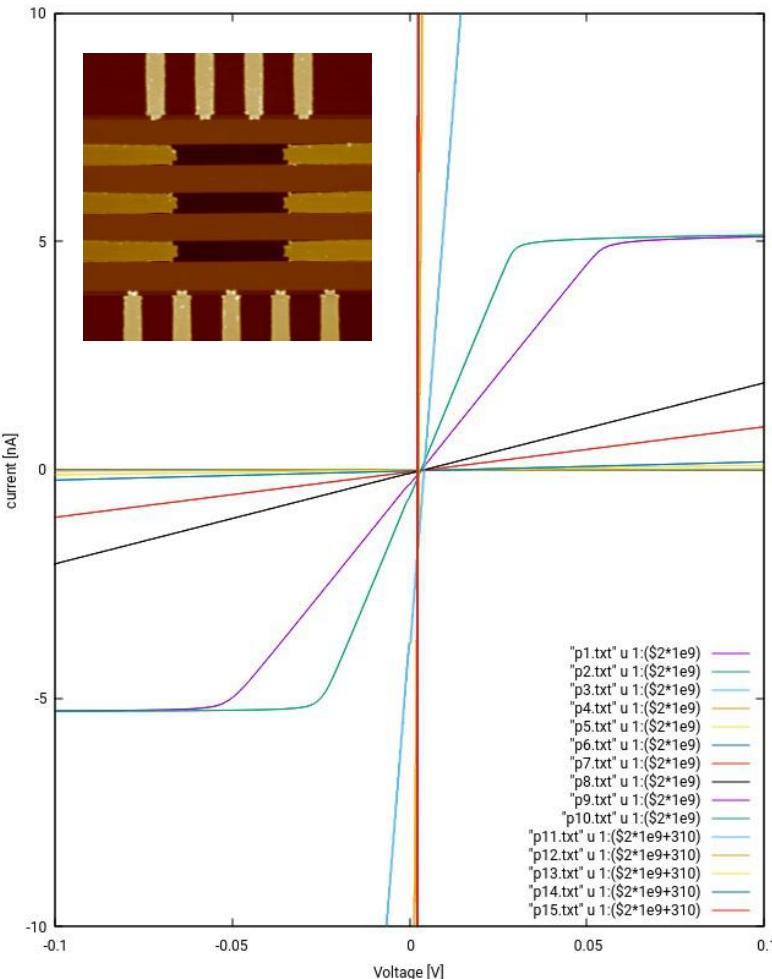
Limits of the transimpedance amplifier range – with single settings we can get reasonable signal on few pads only. Logarithmic amplifier, as used in SSRM would be better.



C-AFM reference samples

Measurement of I/V curves

Potential problems with parasitic capacitance when not connected properly.



Conductive AFM measurements guidelines:

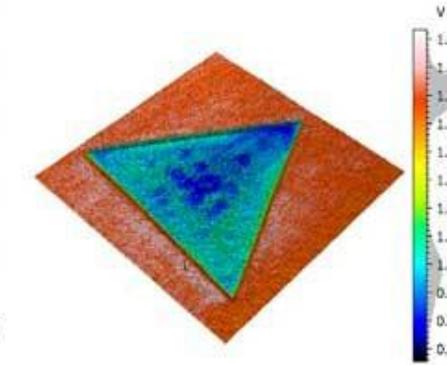
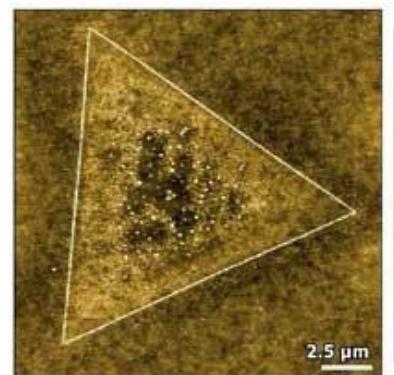
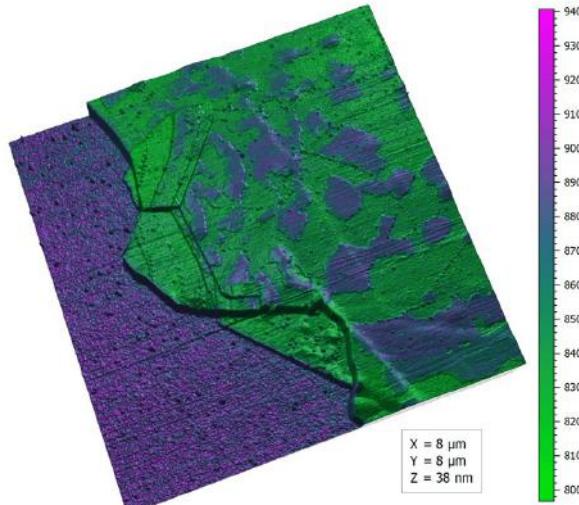
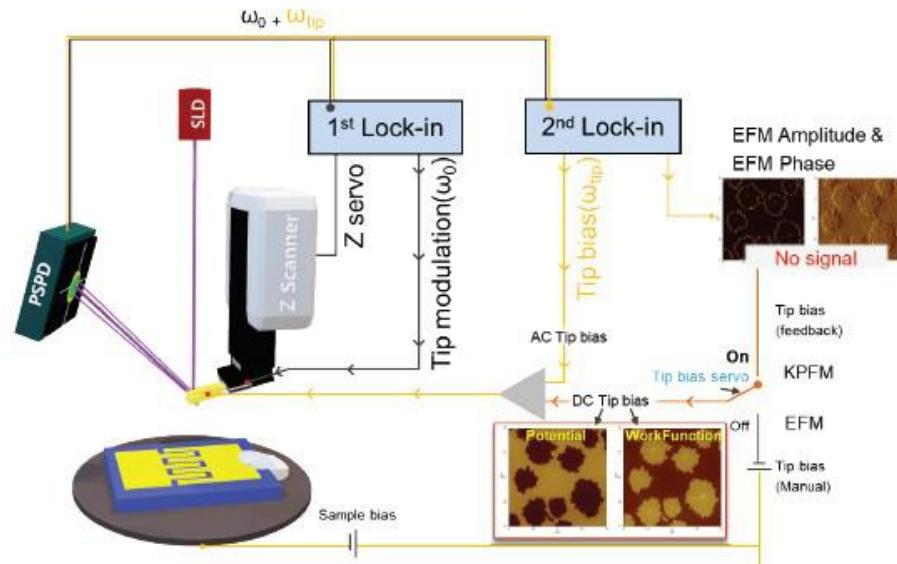
- calibrate your transimpedance amplifier (at least once)
- use solid body probes as coated ones can wear
- larger force is usually better
- do not believe in data obtained on rough samples

Kelvin Probe Force Microscopy

Monitoring electrostatic force between probe and sample and adjusting probe bias to minimize it ... measurement of contact potential difference.

Applications:

Semiconductors, 1D and 2D materials.

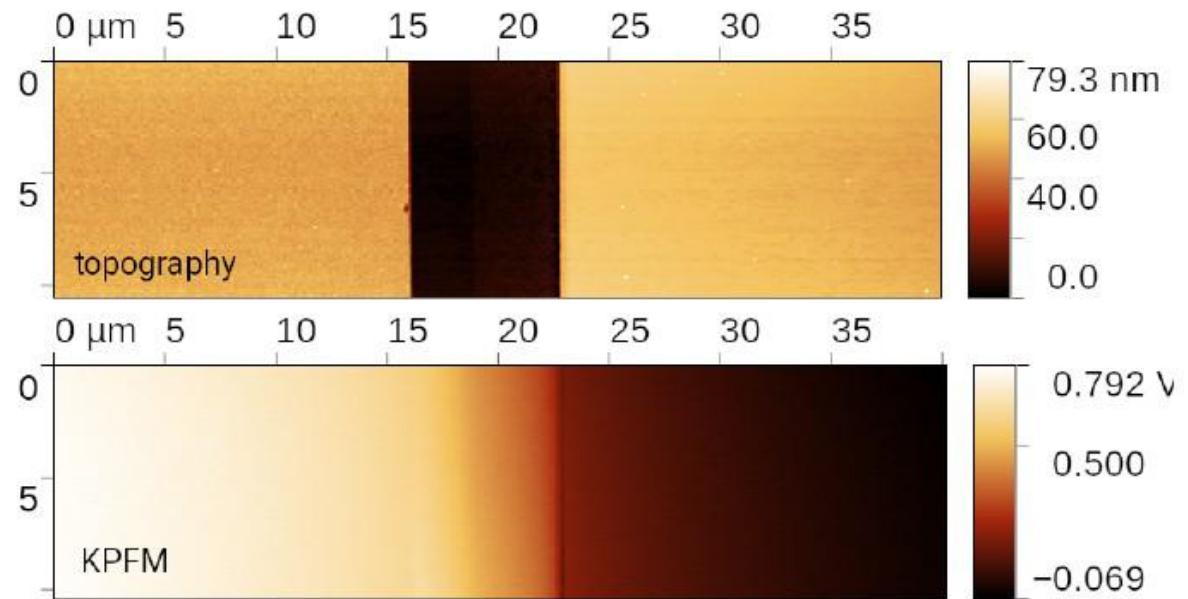
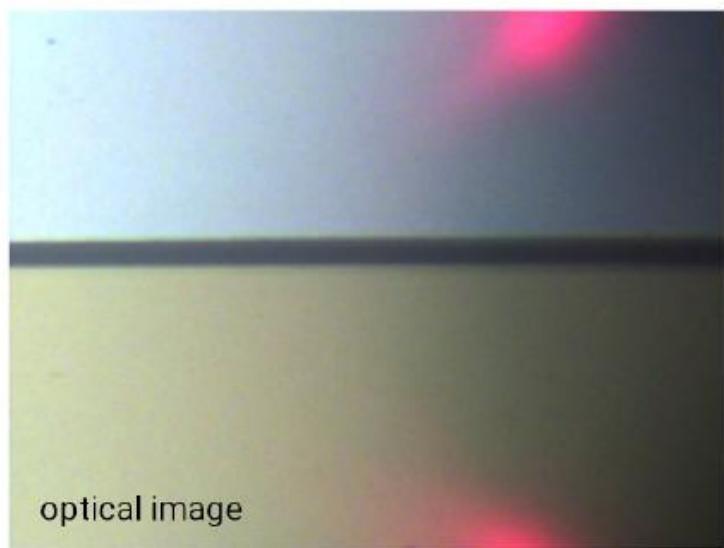
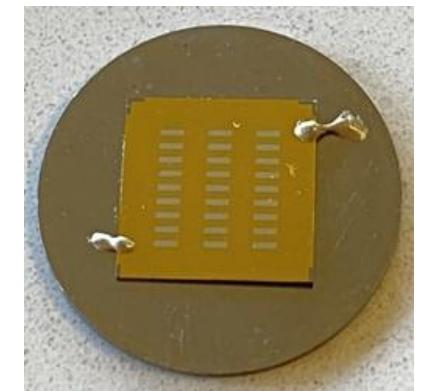


2D materials KPFM, Image sources: Park systems, Nanosurf

Bruker reference sample: aluminium and gold on silicon

Benefits: cheap, widely used.

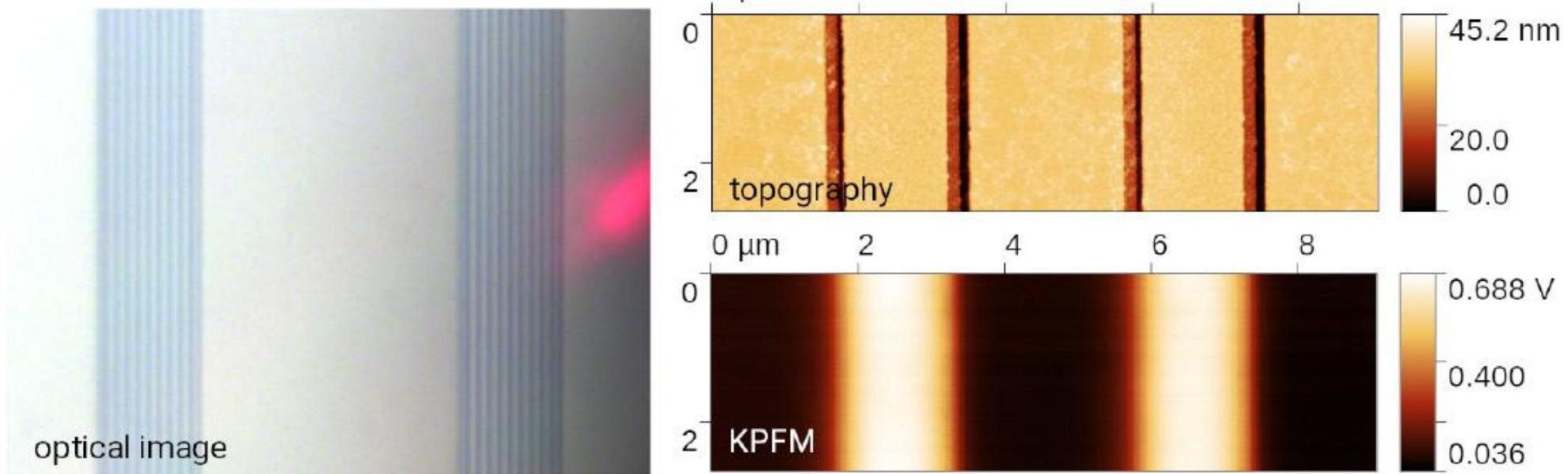
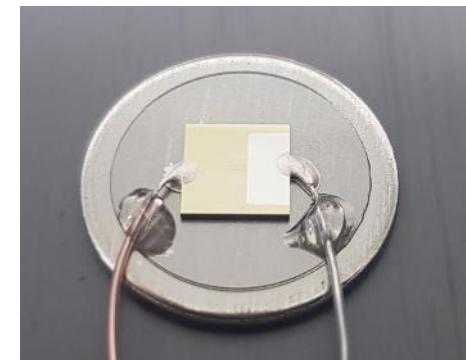
Drawbacks: on one transition can be measured in a single image, gap is large.



BudgetSensors: interleaved electrode arrays

Benefits: external voltage can be set on the electrodes, determining the KPFM scale and linearity.

Drawbacks: smallest electrodes are micrometer sized.

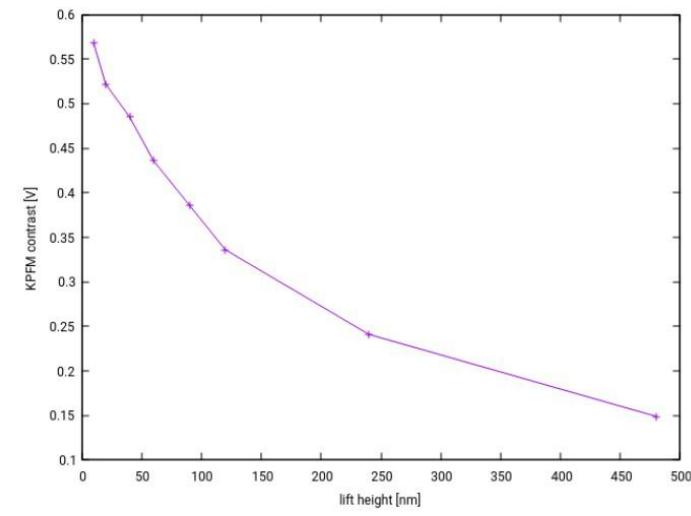
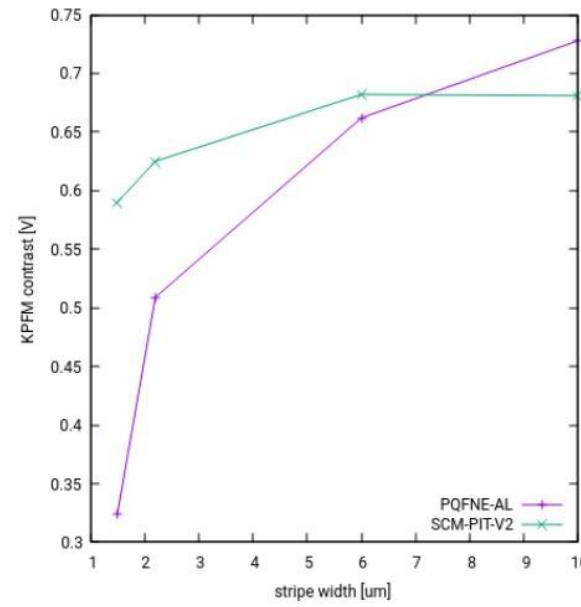
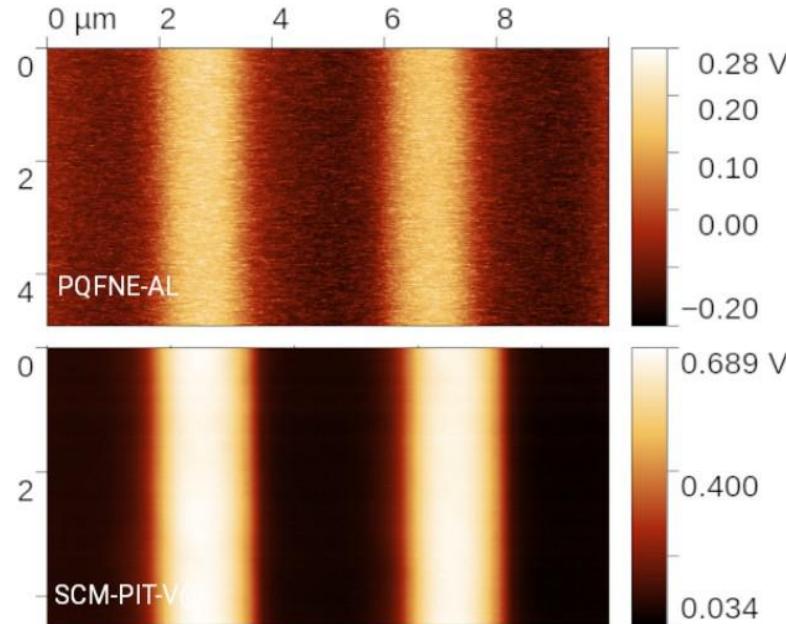


Spatial resolution vs. accuracy

How accurately we can get V_{CPD} depending on the feature size?

When using AM-KPFM, a reasonable result could be obtained only on quite large features, in micrometer scale.

It is important to measure in as low lift height as possible, when using two-pass techniques.

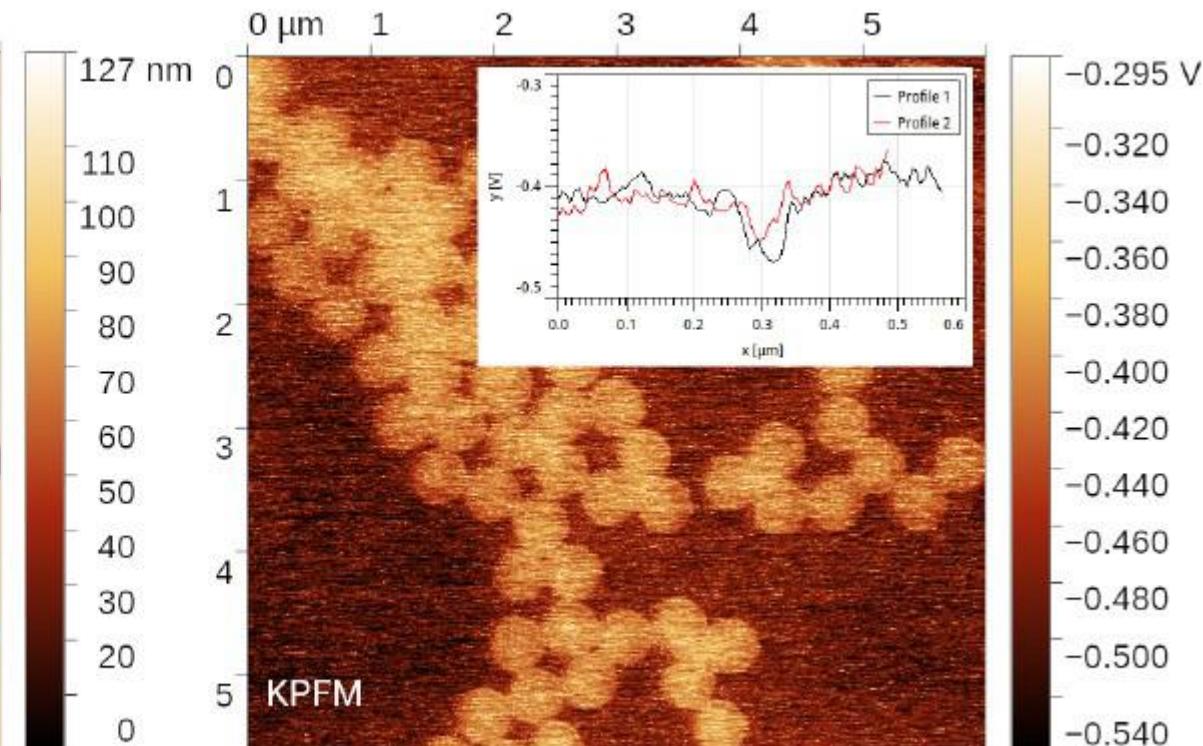
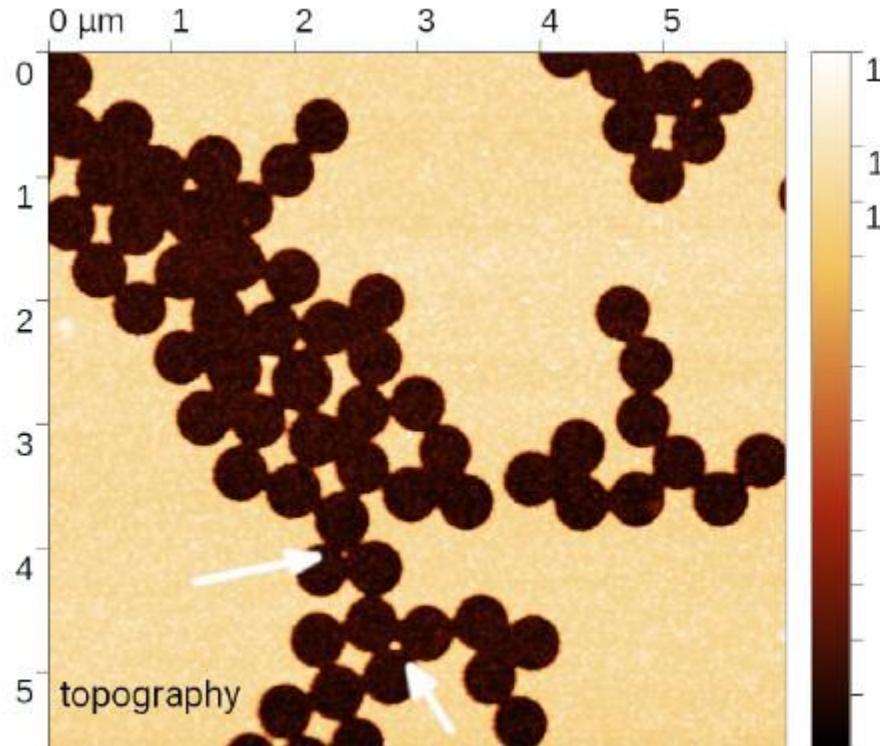


Spatial resolution vs. accuracy

Monolithic PQFNE-AL probe was best in term of resolution in our studies.

How to determine resolution?

One option is to search for smallest resolvable islands.

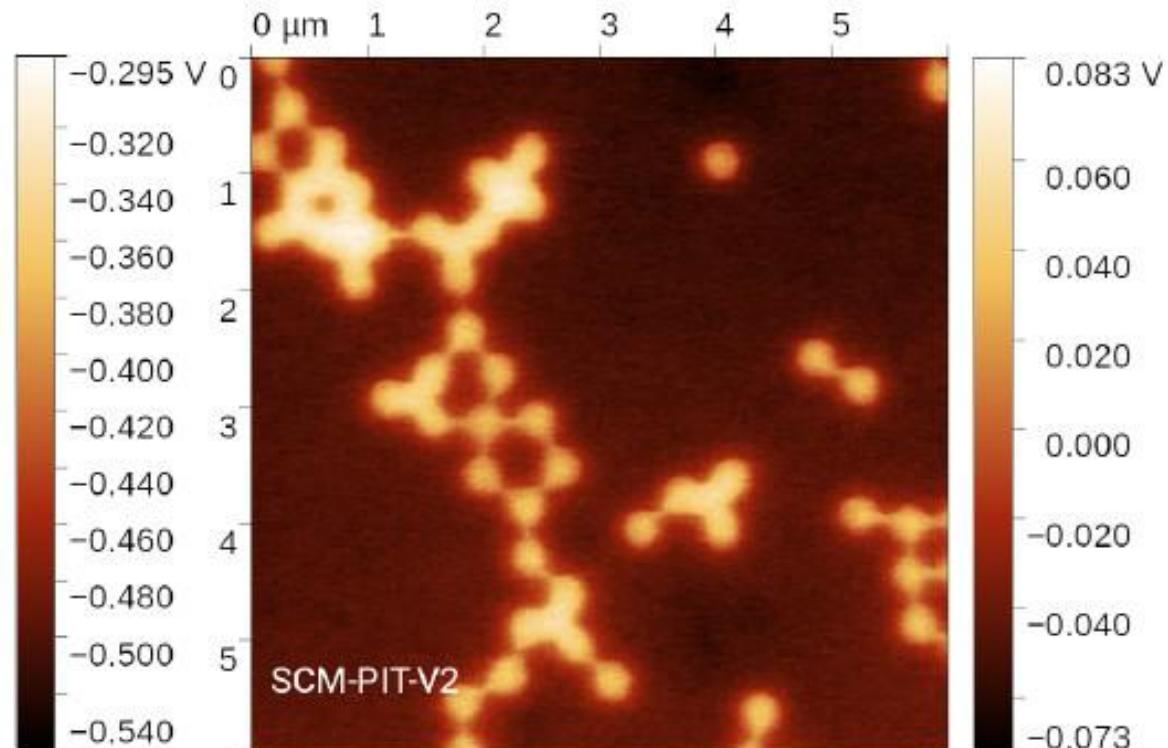
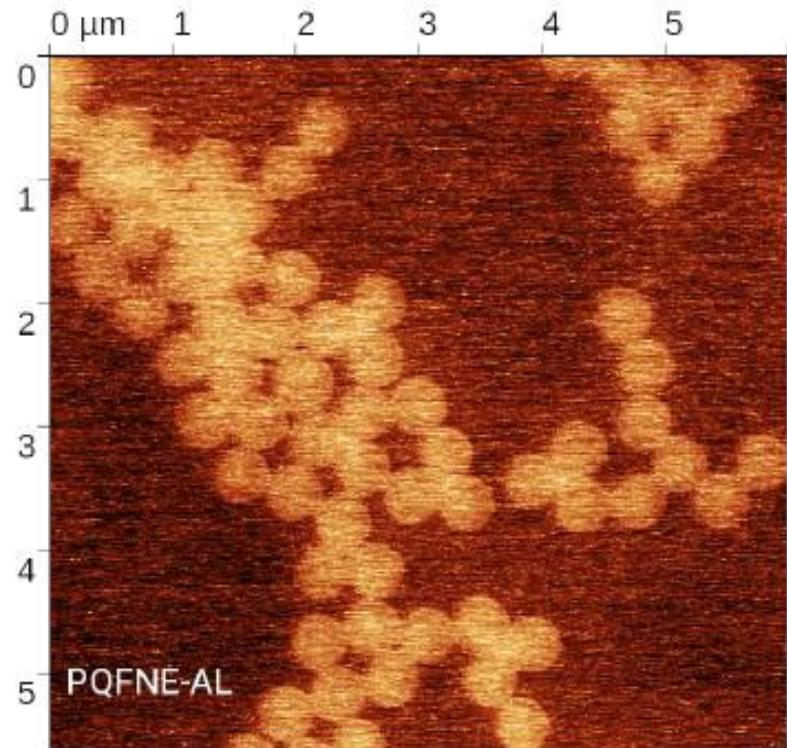


Spatial resolution vs. accuracy

How to determine resolution?

Second option is to search for shape of signal on an edge.

- resolution with PQFNE-AL probe: 15 nm,
- resolution with SCM-PIT-V2 probe: 100 nm.

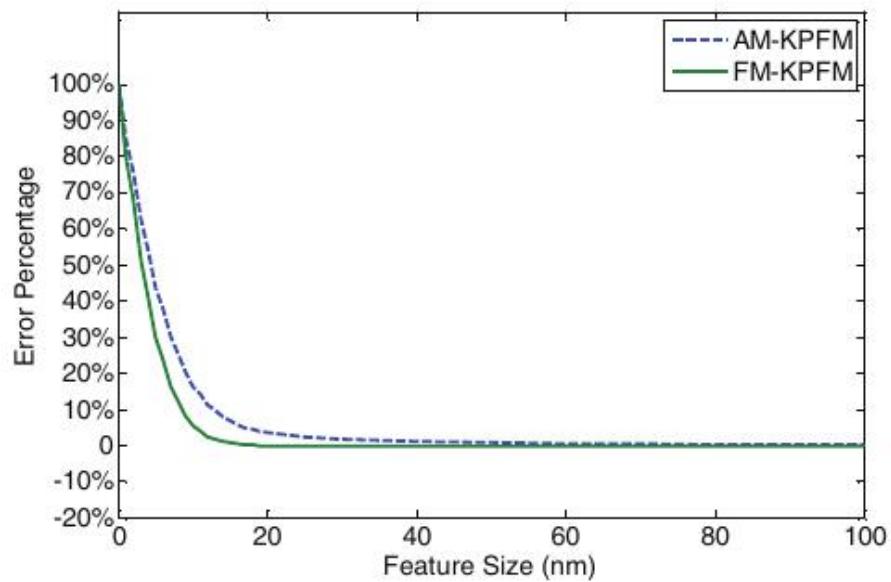


Spatial resolution vs. accuracy

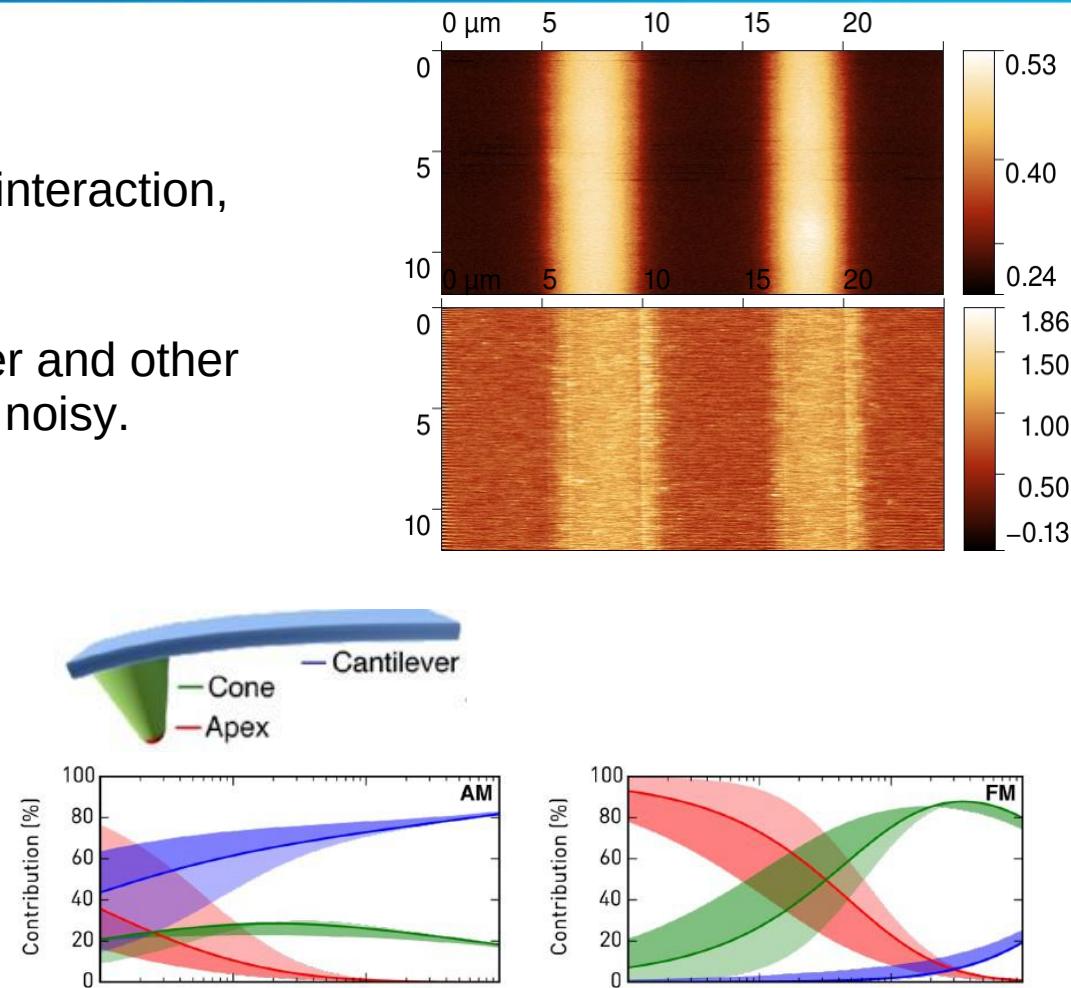
How to increase the resolution?

Use FM-KPFM which uses more localized interaction, force gradient instead of its value.

It is less sensitive to the impact of cantilever and other long range force sources, but can be more noisy.



Li et al. Rev. Sci. Instrum. **83**, 113701 (2012)



T. Wagner et al.

Beilstein J. Nanotechnol. **2015**, *6*, 2193–2206.

doi:10.3762/bjnano.6.225

Kelvin probe measurements guidelines:

- use FM mode if you want to get better resolution
- use specialized probes for KPFM if you have them
- use some test sample before measurements to check that everything works
- note that every probe produces different CPD, calibrate if, e.g. on HOPG

Scanning Microwave Microscopy

Conductive probe + Vector network analyzer

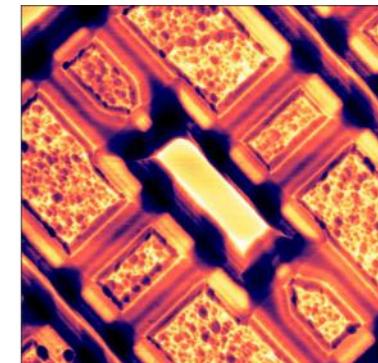
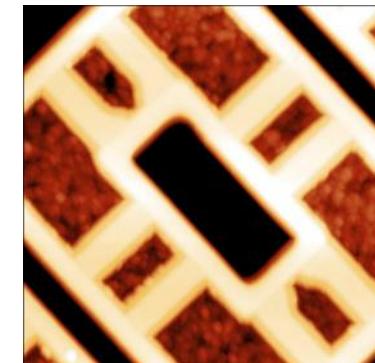
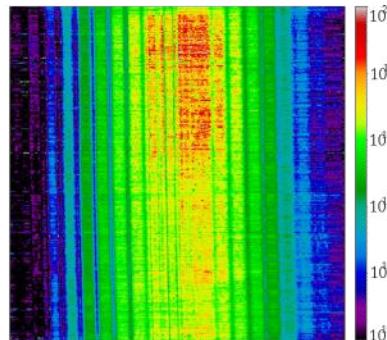
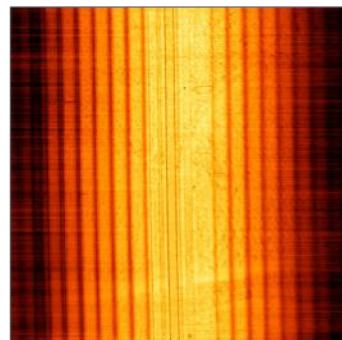
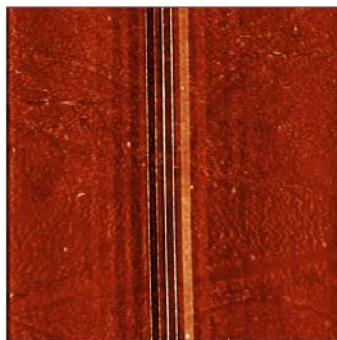
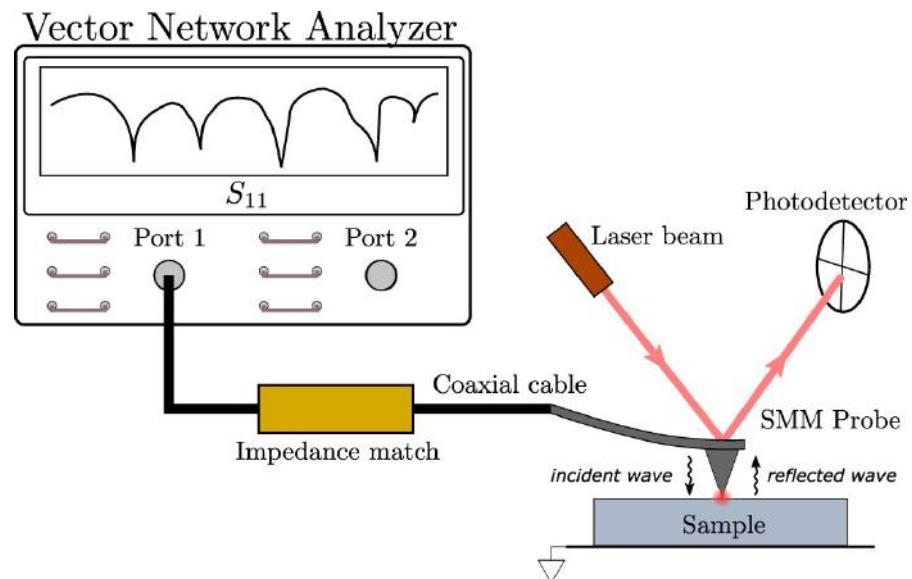
Frequency 1-20 GHz, rarely even up to 100 GHz

Impedance matching element can be complicated, frequency dependent and expensive.

As an output, VNA provides reflection coefficient, a complex number, called S_{11}

This can be used to address sample dielectric properties.

Sample results from Nanosurf (dopants, SRAM)



Scanning Microwave Microscopy

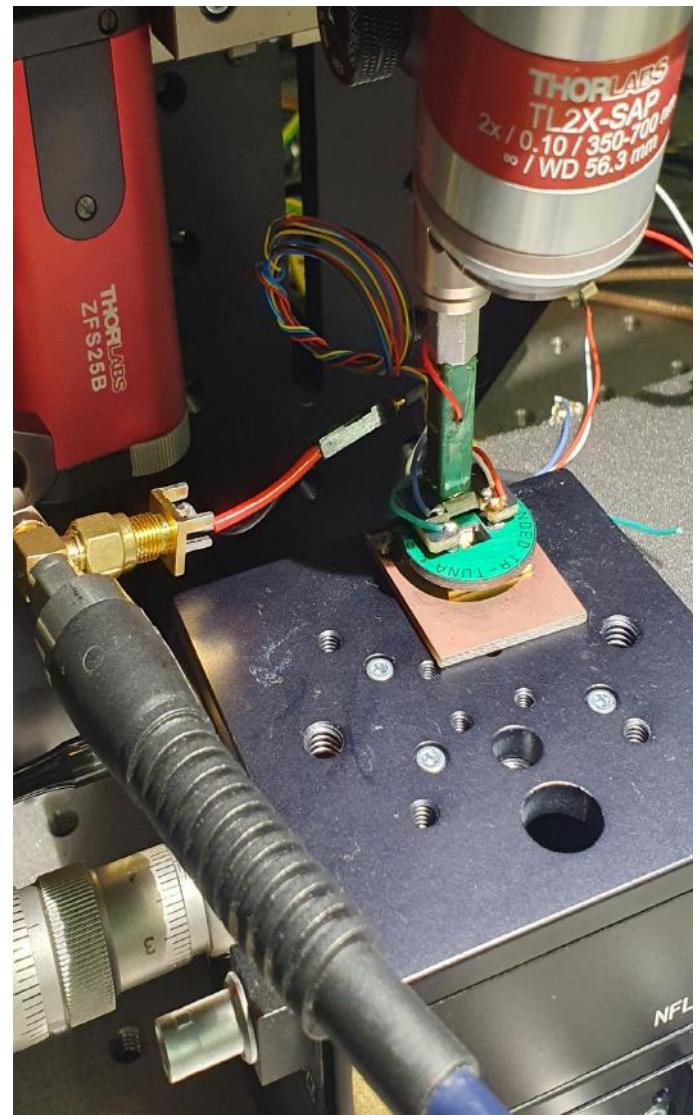
Only few options how to buy it.

Can it be done as custom built instrument?

Keysight PNA (> 30 kEuro), 128 dB range

PicoVNA (~ kEuro), 118 dB range

LibreVNA (~ 600 Euro), 100 dB range

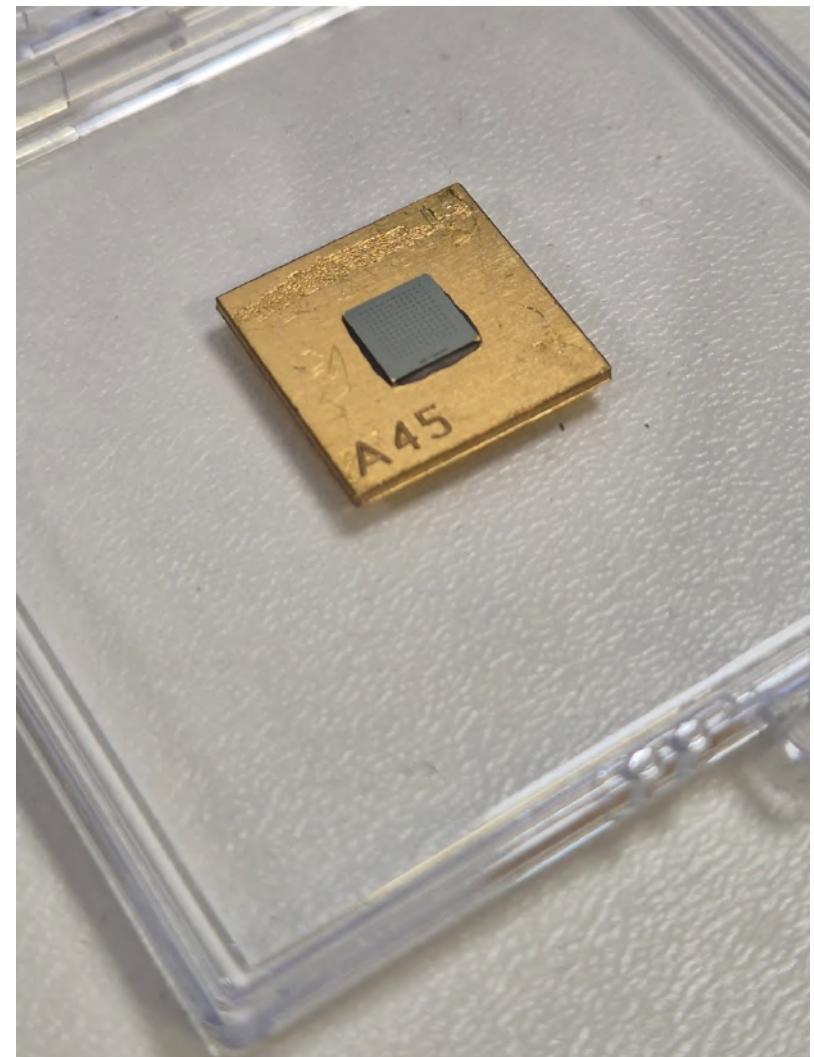
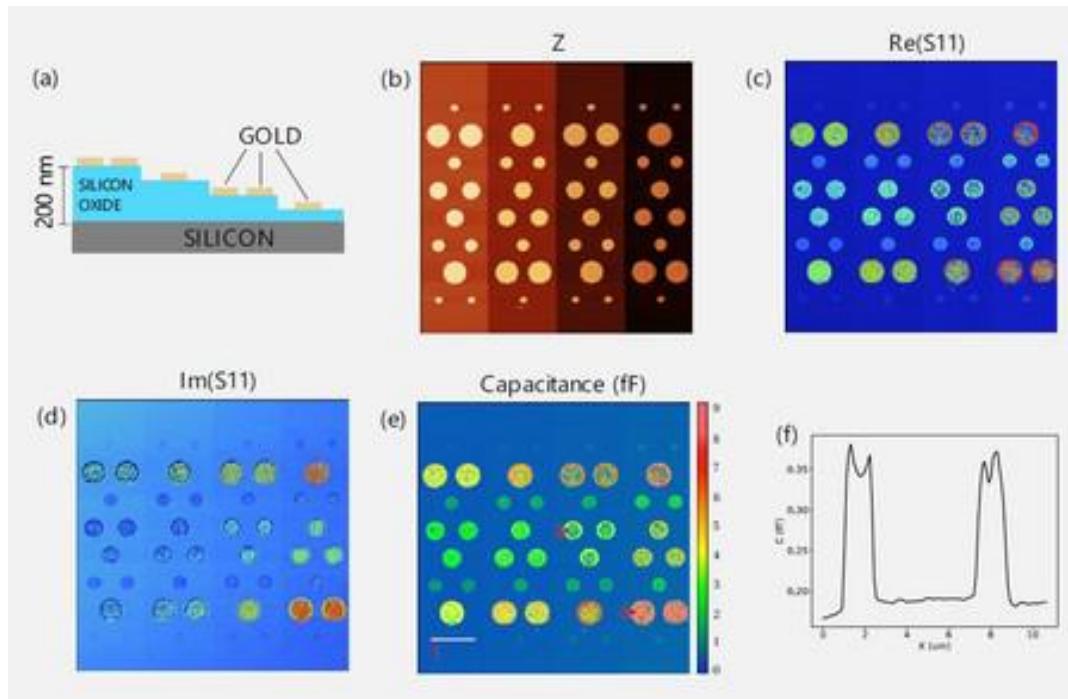


SMM reference samples

SMM reference samples

Small capacitors developed by MC2 company.

Gold pads on silicon dioxide with varying thickness and pad size. Very wide range of capacitances in fF range.

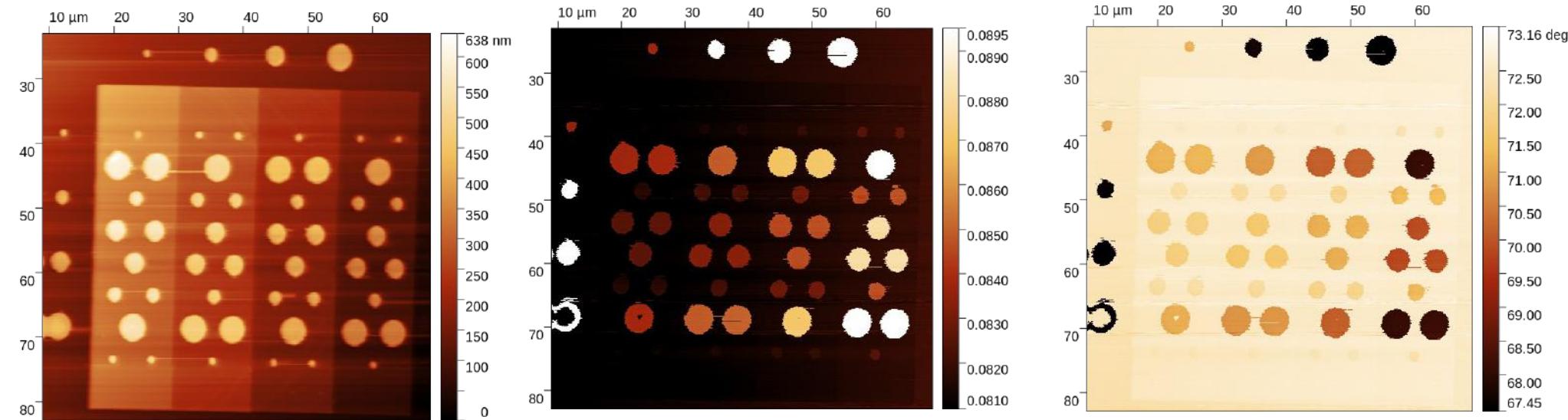


SMM reference samples

Testing a simple setup based on PicoVNA on MC2 calibration sample.

Probes are crucial – here we use full platinum Rocky Mountains probe

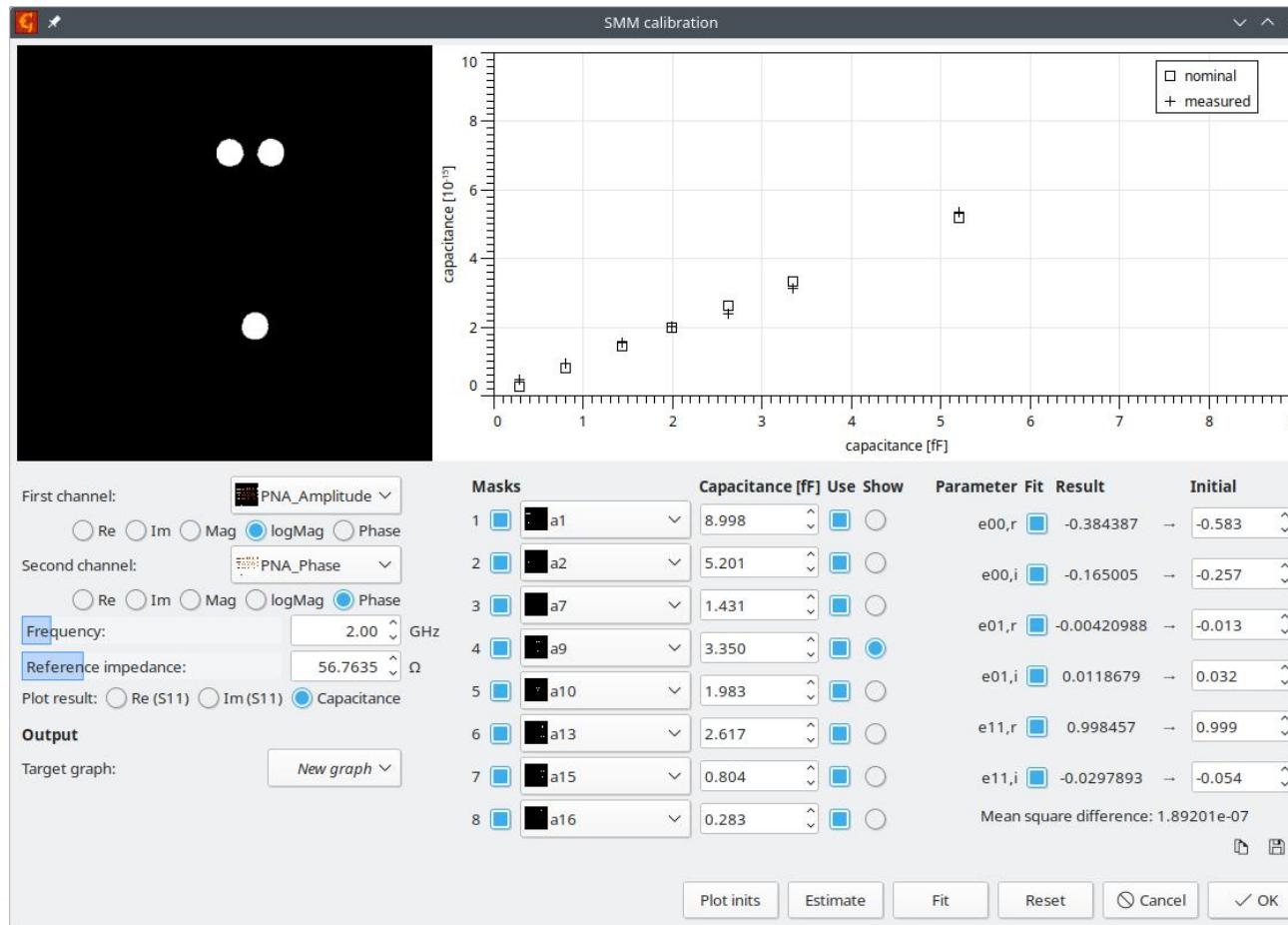
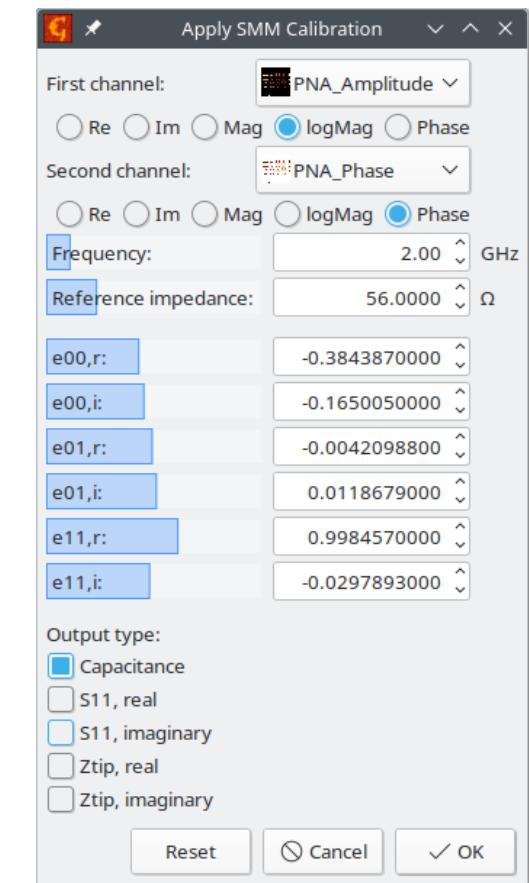
Using VNA we get $\log(\text{magnitude})$ and phase signal in every pixel of the image.



SMM calibration

We can calibrate our setup by using known capacitances and determining three complex parameters of the microwave circuit, using modified SOL calibration methodology.

See more in: Nanomaterials 2021, 11(3), 820; <https://doi.org/10.3390/nano11030820>

Apply SMM Calibration

First channel: PNA_Amplitude

Second channel: PNA_Phase

Frequency: 2.00 GHz

Reference impedance: 56.0000 Ω

e00,r:	-0.3843870000
e00,i:	-0.1650050000
e01,r:	-0.0042098800
e01,i:	0.0118679000
e11,r:	0.9984570000
e11,i:	-0.0297893000

Output type:

Capacitance

S11, real

S11, imaginary

Ztip, real

Ztip, imaginary

Reset Cancel OK

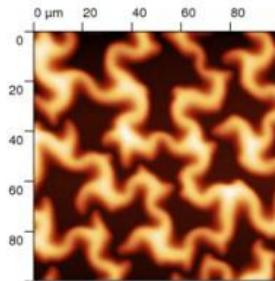


SMM wrap up

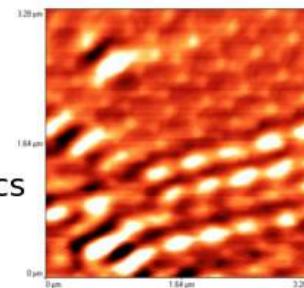
SMM measurements guidelines:

- know your setup, including impedance matching circuitry
- calibrate the response on known samples
- solid large probes work better

SPM – scanning probe microscopy

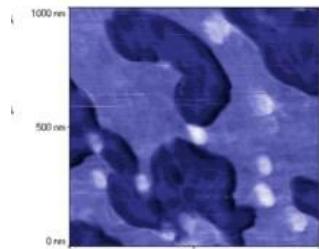


Morphology from microscale
to nanoscale

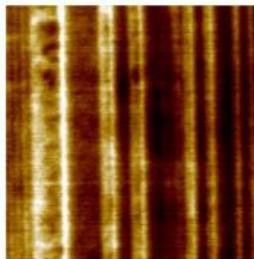


Optics and plasmonics

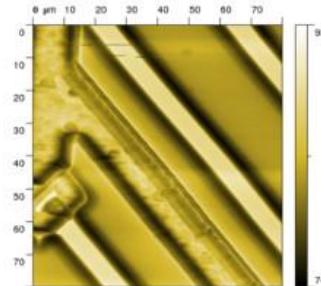
Local mechanical properties



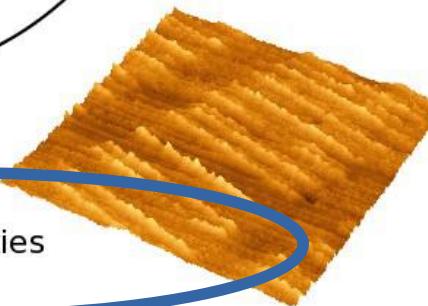
Electrical properties,
forces and capacitance



Temperature and
thermal conductivity



Magnetic properties



Magnetic force Microscopy

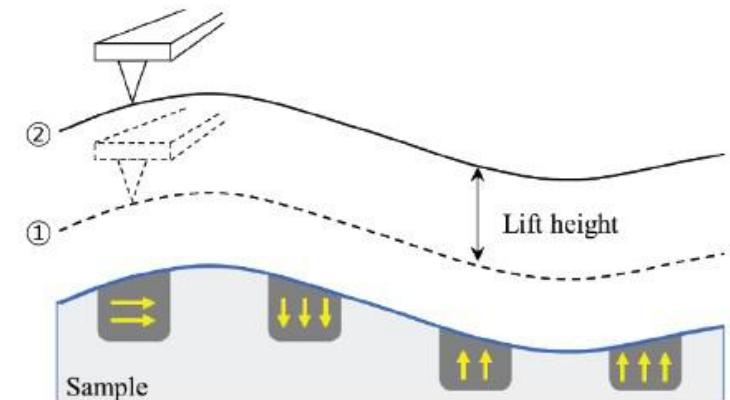
Use of a magnetically coated probe to address the stray field above the sample.

Two pass measurement or force-volume data acquisition.

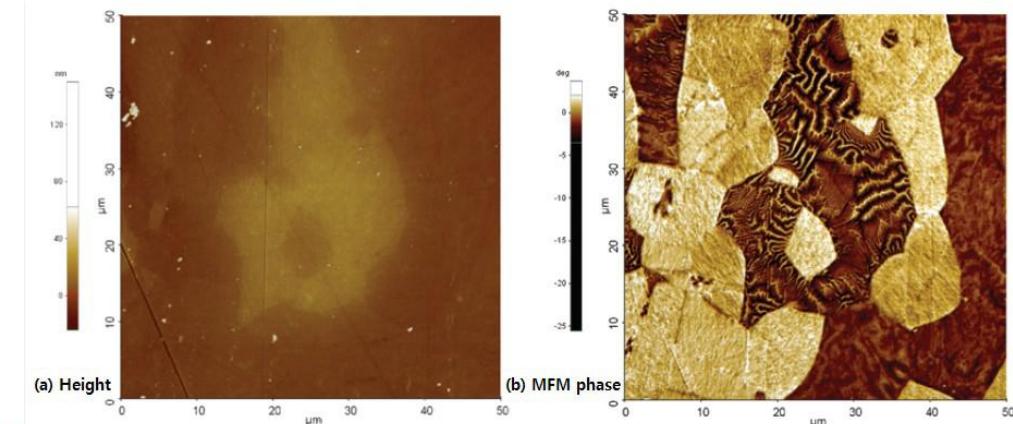
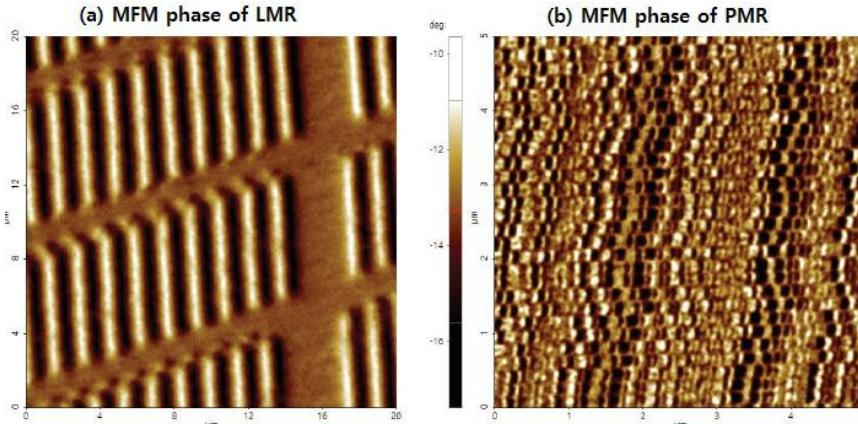
Applications:

Data storage, materials, nano-magnetism

Image source: Park Systems (HDD, steel)



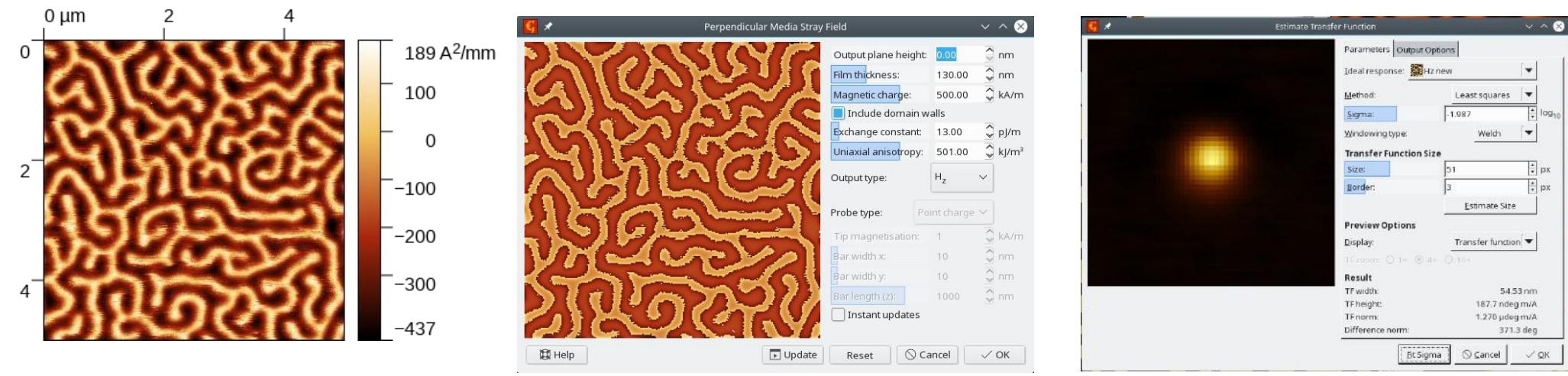
- ① First pass (van der Waals force)
- ② Second pass (Magnetic force)



Quantitative MFM:

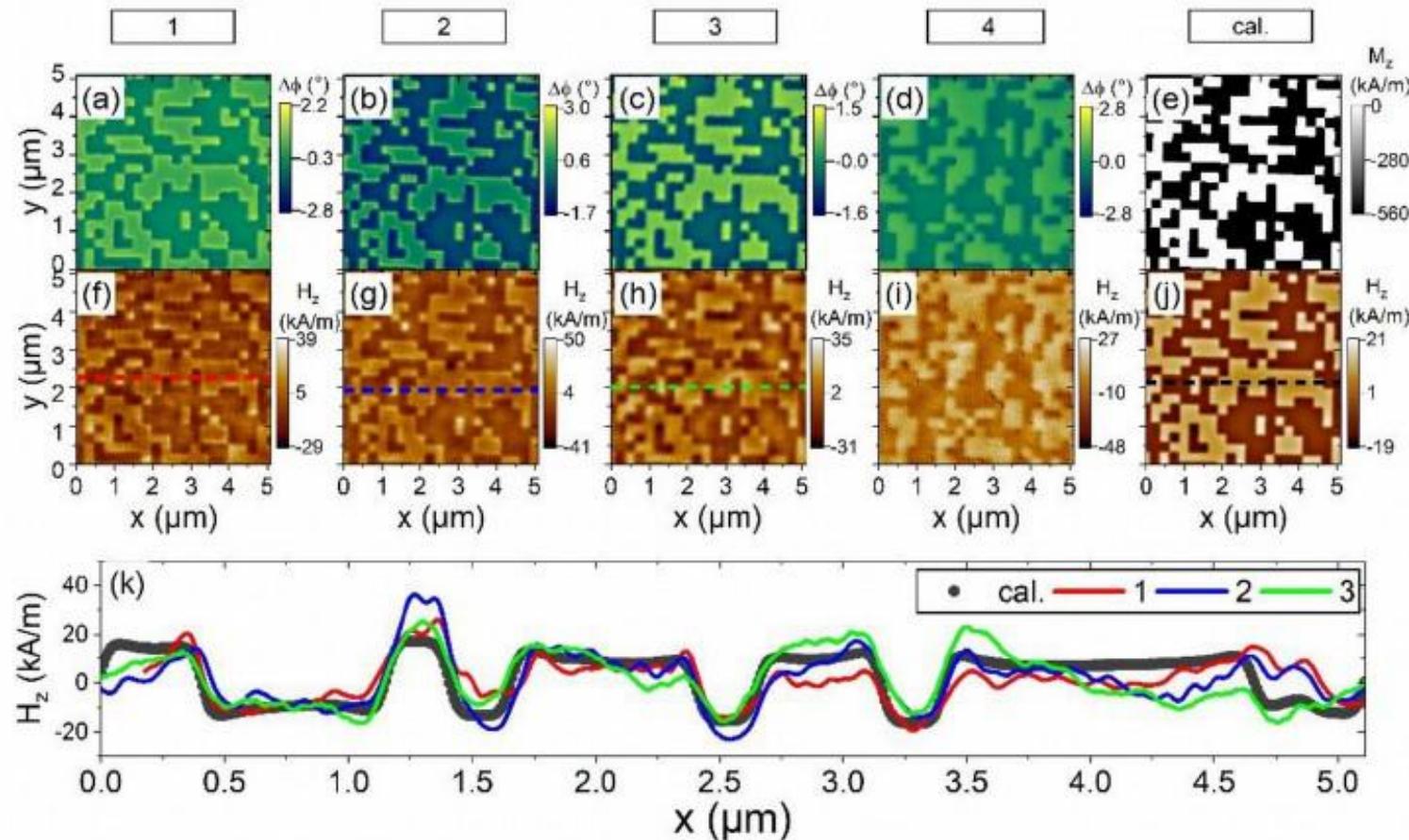
- Use a sample with calculable stray field (e.g. perpendicularly magnetised pattern in a multilayer).
- characterize the probe with it, obtaining a tip transfer function.
- deconvolve the TTF from measurements on the unknown sample.

See more in Nečas et al, <https://doi.org/10.1038/s41598-019-40477-x>



EMPIR Nanomag project comparison using the quantitative MFM methodology:

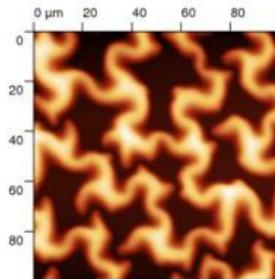
See more in: X. Hu et al, <https://doi.org/10.1016/j.jmmm.2020.166947>



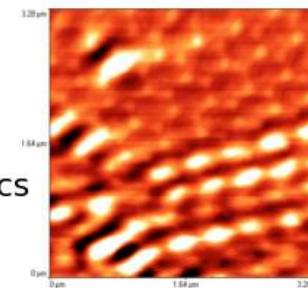
MFM measurements guidelines:

- get some reference samples
- calibrate your probe and use the whole quantitative MFM procedure
- scan in more lift heights to get rid of van der Waals forces
- be cautious if your probe has low magnetic moment and sample high

SPM – scanning probe microscopy

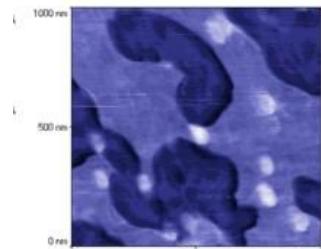


Morphology from microscale
to nanoscale

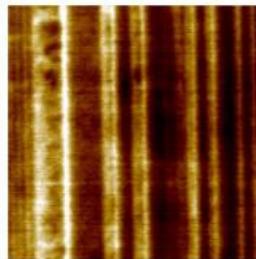


Optics and plasmonics

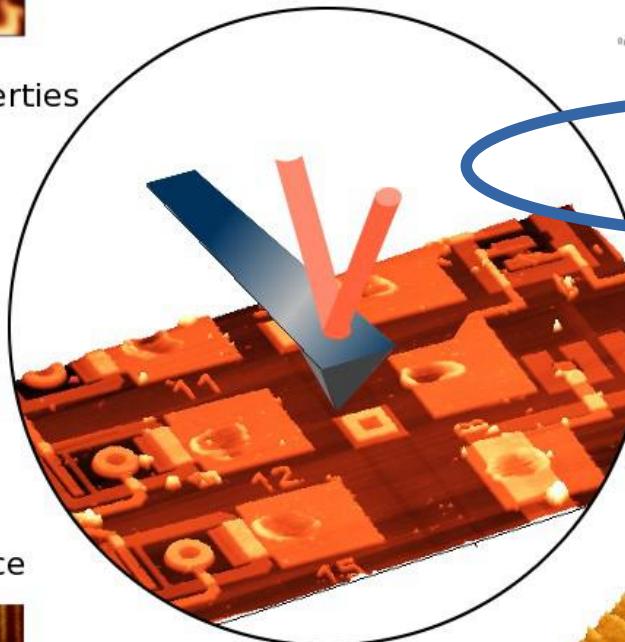
Local mechanical properties



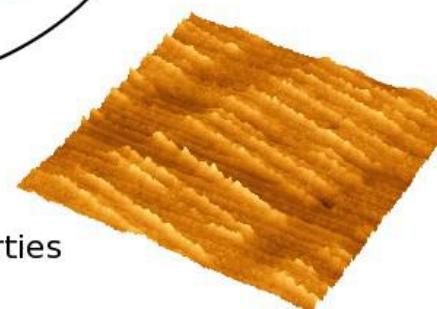
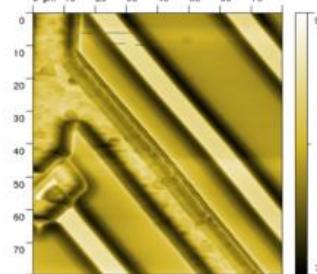
Electrical properties,
forces and capacitance



Magnetic properties

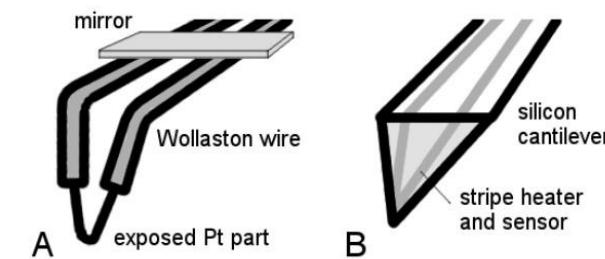
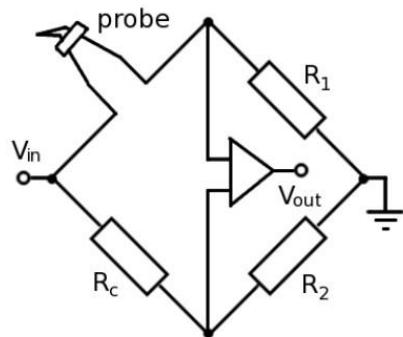
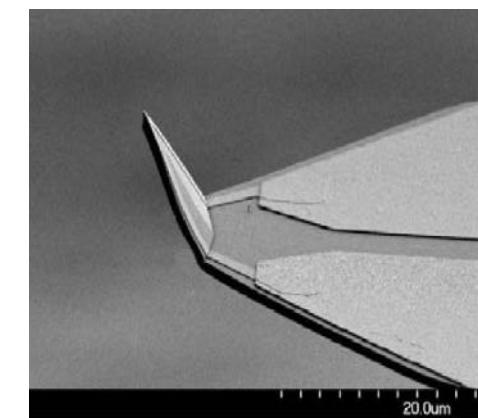
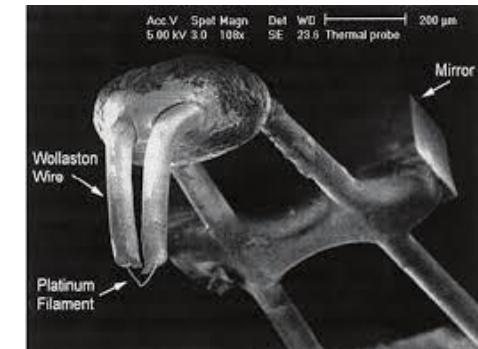


Temperature and
thermal conductivity



Scanning Thermal Microscopy (SThM)

- use of a special probe that can generate heat and sense temperature.
- **temperature** measurements: minimize probe self-heating, measure the probe resistance only with minimum current.
- **thermal conductivity** measurements: heat the sample using probe and monitor thermal losses.
- nanoscale thermal analysis: sample **transition temperature** by ramping the probe temperature and monitoring the mechanical response.



Temperature applications:

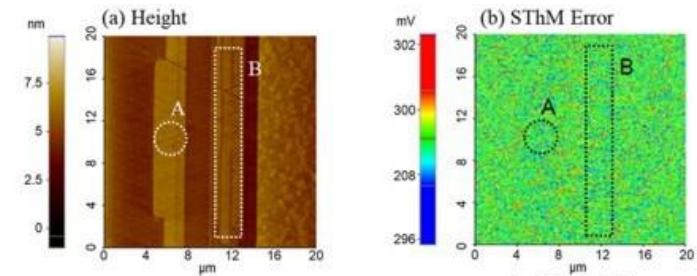
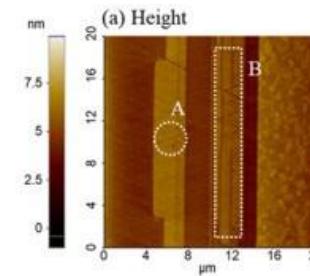
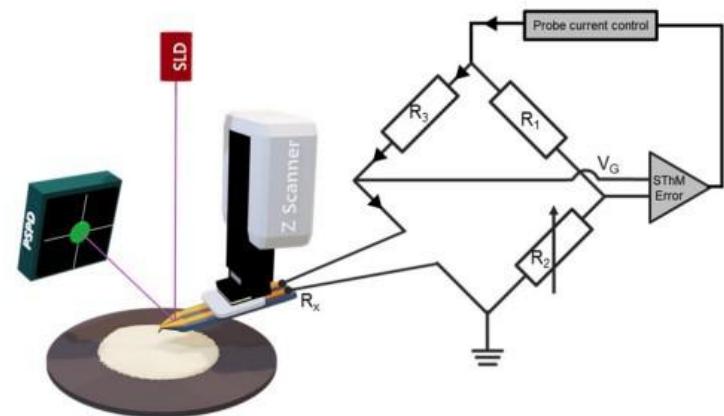
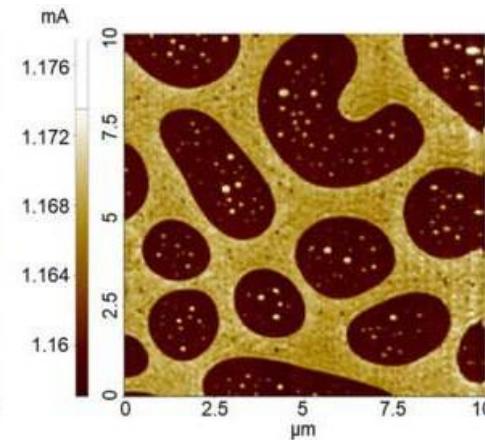
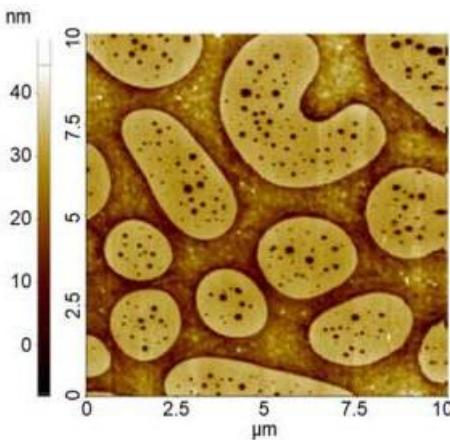
high power transistors, microelectronics, optoelectronic devices.

Thermal conductivity applications:

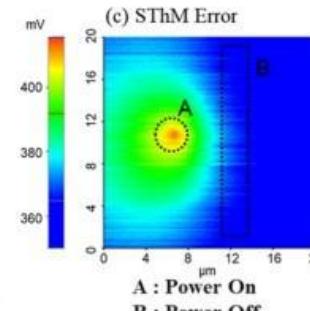
heat management materials, nanocomposites, 1D and 2D materials.

Nano thermal analysis applications:
polymers

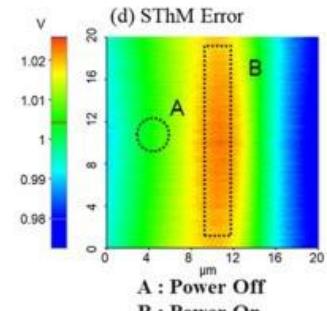
Image source: Park Systems (polymer blend, HDD)



A : Power Off
B : Power Off



A : Power On
B : Power Off



A : Power Off
B : Power On

Local thermal conductivity

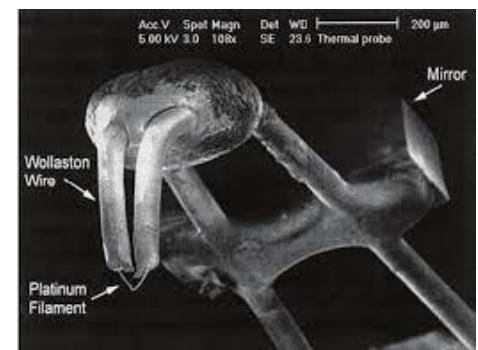
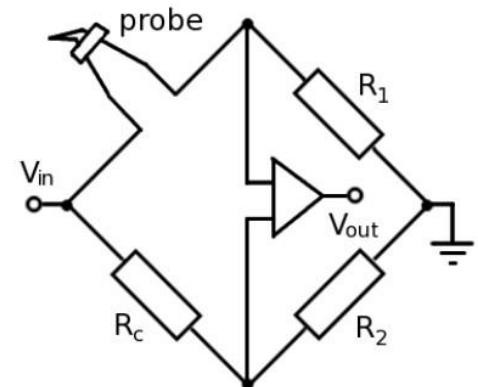
Our goal is to heat the sample with the probe (by passing current through it) and to use it as a sensor of the local temperature at the same time.

Measurement methodology

- in contrast to temperature measurements, do not minimize self heating
- use value far from the sample as a reference
- use set of calibration samples for traceability

Potential calibration strategies:

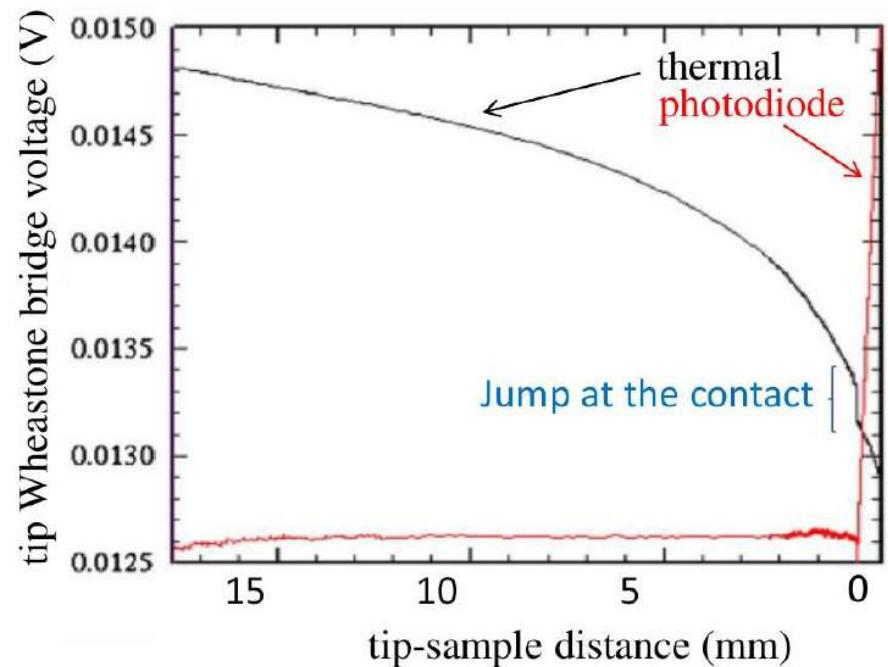
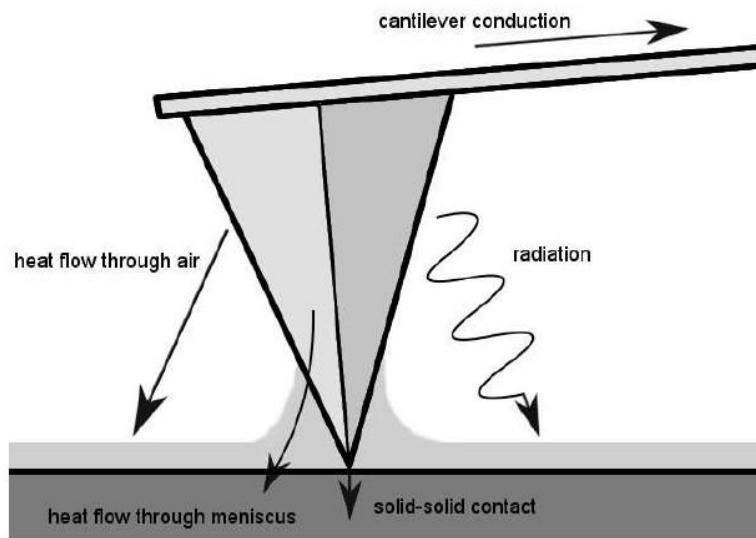
- measurement of the energy flow in the system
- calibration on known reference samples



A) Calibration of thermal conductivity based on energy balance in the system

- problems with too many unknown heat transfer paths
- in most cases the solid-solid heat flow is only very small contribution

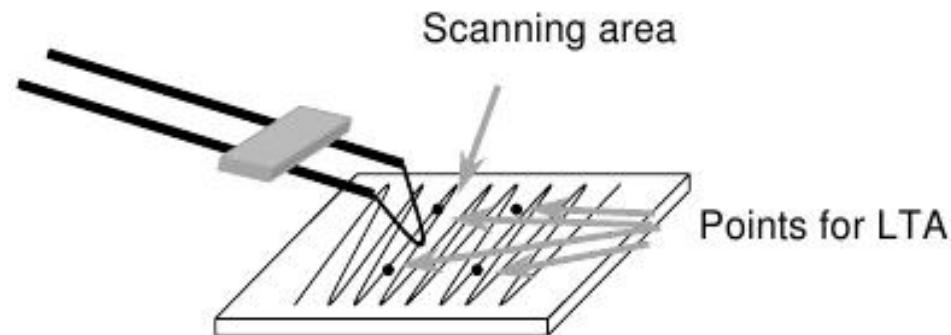
... really not an option in the present state of knowledge



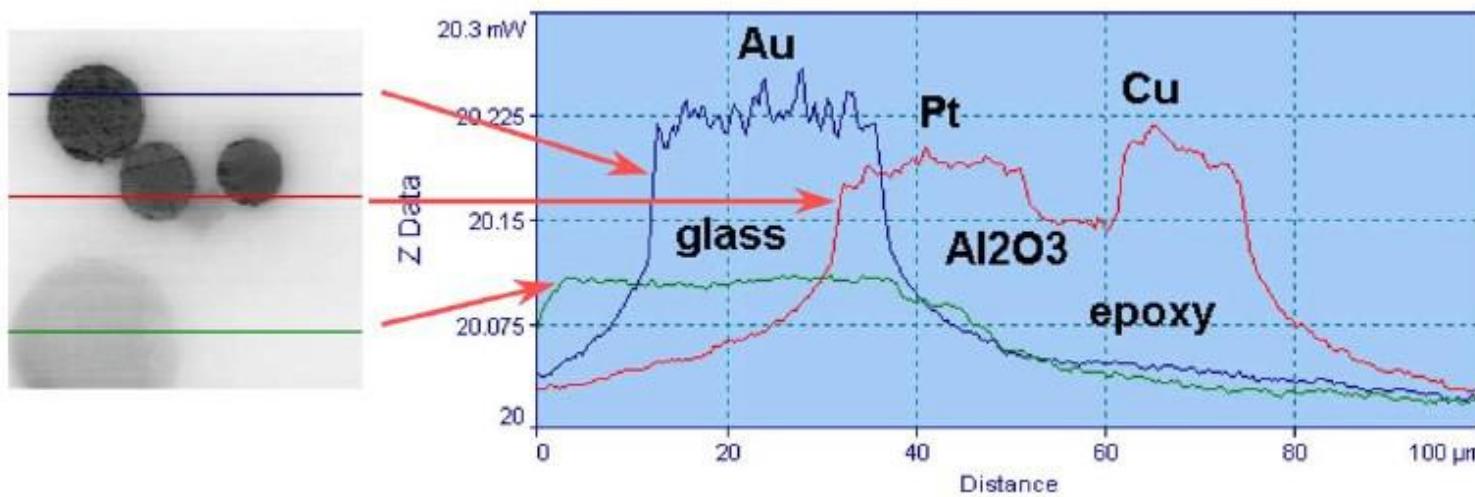
B) Calibration based on samples

Method proposed by Fischer, at present mostly used approach.

Ideally, we want to use sample with multiple known materials within single scan range (e.g. 100x100 micrometers).



H. Fischer / Thermochimica Acta 425 (2005) 69–74



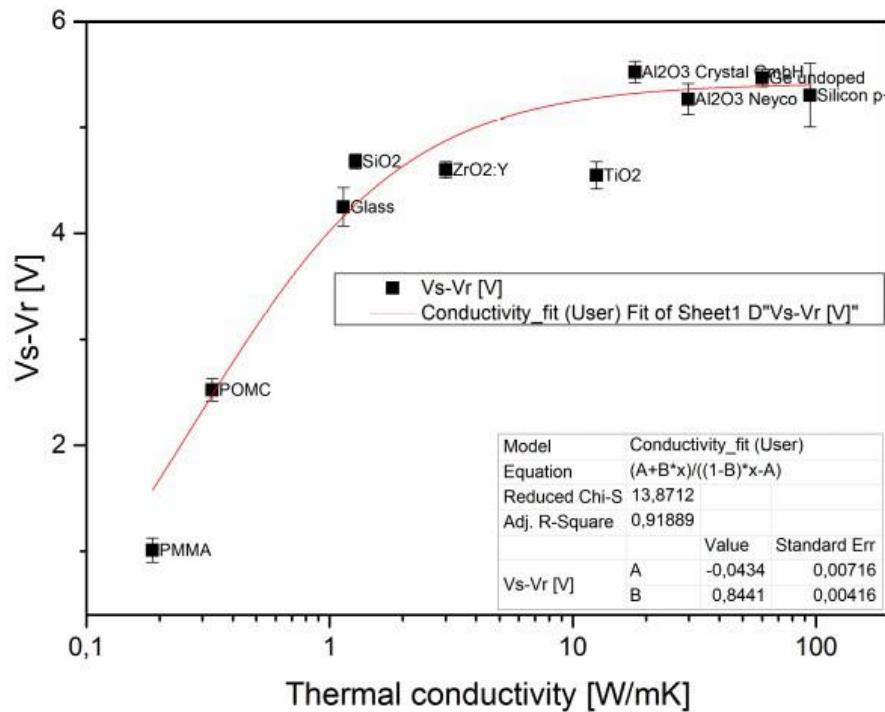
Bulk based calibration samples

Set of bulk samples prepared during Quantiheat project, measured by laser flash method.

Benefits: bulk samples, known thermal conductivity

Drawbacks: impact of roughness, different types of conductors

Sample	Th. C. [W/mK]	Vs-Vr[V]	Err.
PMMA	0.187	1.01	0.06
POMC	0.329	2.52	0.05
Glass	1.14	4.25	0.09
TiO ₂	12.52	4.55	0.06
ZrO ₂ :Y	3	4.60	0.04
SiO ₂	1.28	4.68	0.03
Al ₂ O ₃ Neyco	29.8	5.27	0.07
Silicon p++	94.3	5.30	0.15
Ge undoped	60	5.46	0.04
Al ₂ O ₃ Crystal GmbH	18	5.52	0.05



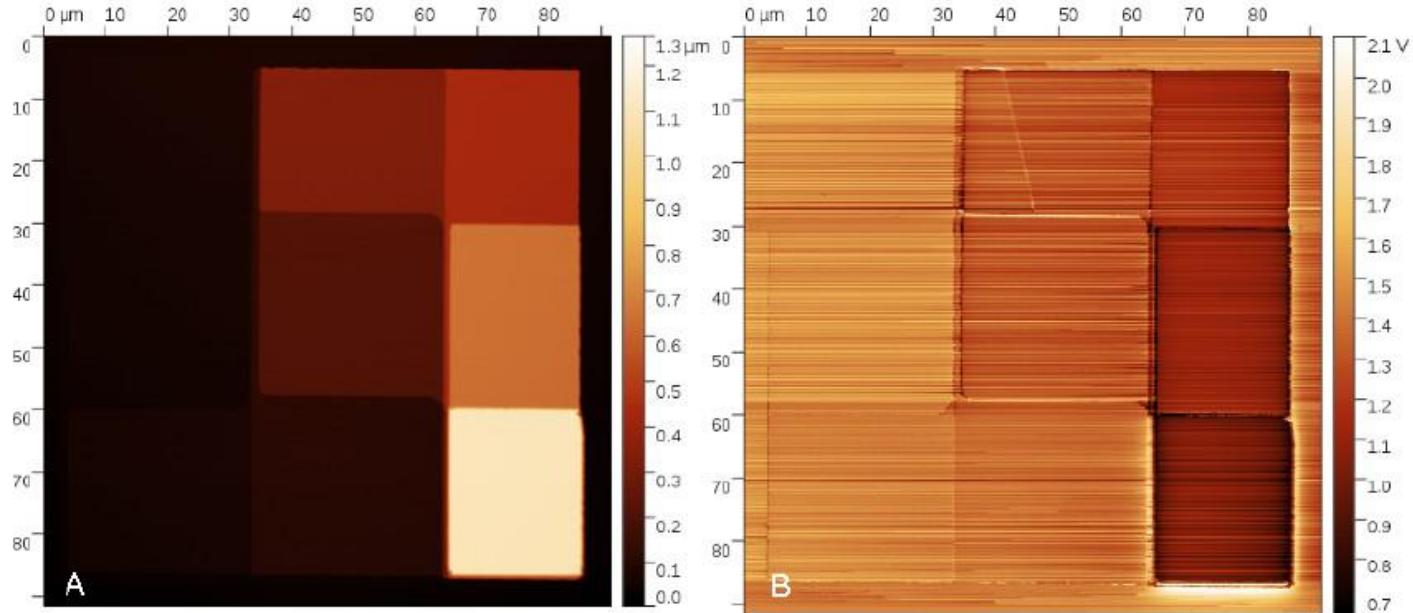
Thin film based calibration samples

Alternative sample from Glasgow university: silicon dioxide films with different thickness.

Benefits: smooth surface, similar on all parts of the sample.

Drawbacks: limited conductivity range, missing reference value.

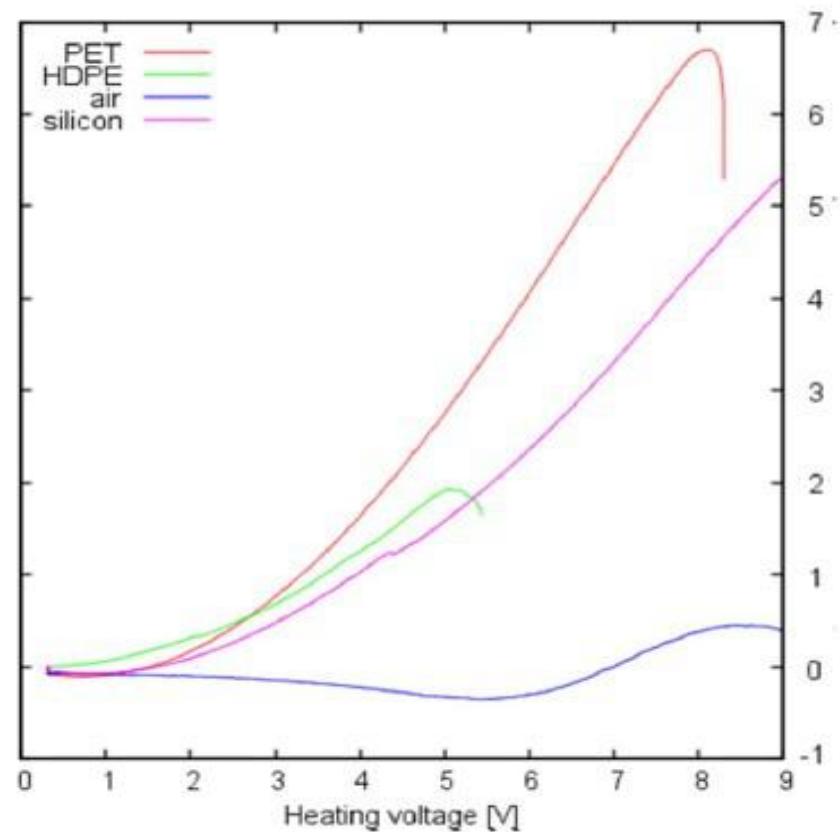
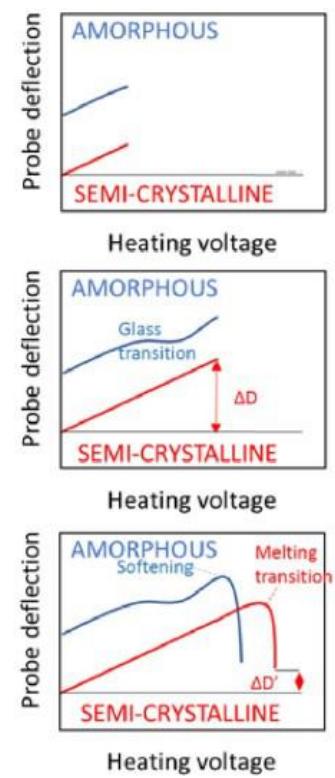
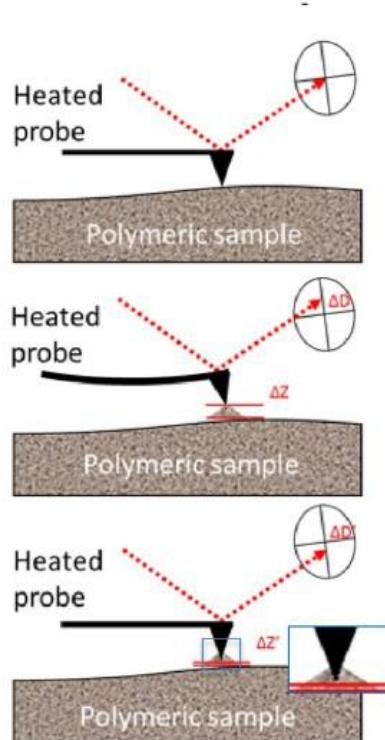
topography and thermal signal on the Glasgow Quantiheat sample



SThM thermal conductivity measurements guidelines:

- calibrate your setup on known bulk samples
- test your bridge time stability
- do whole experiment at once, without stopping
- do not believe in data obtained on rough samples

To measure thermomechanical properties, we ramp the temperature of the probe, while staying in contact to the surface. When probe reaches glass transition temperature or melting point, it penetrates the sample, which can be monitored in the probe-sample force signal.

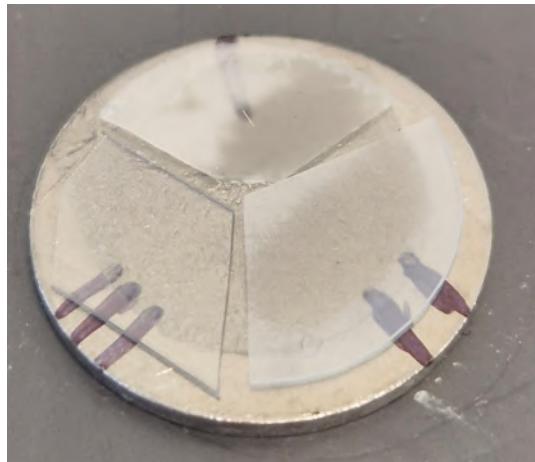


Metrological traceability

Differential Scanning Calorimetry: monitoring heat capacity changes with temperature.

Set of polymer samples with known transition temperatures developed in the Quantiheat FP7 project.

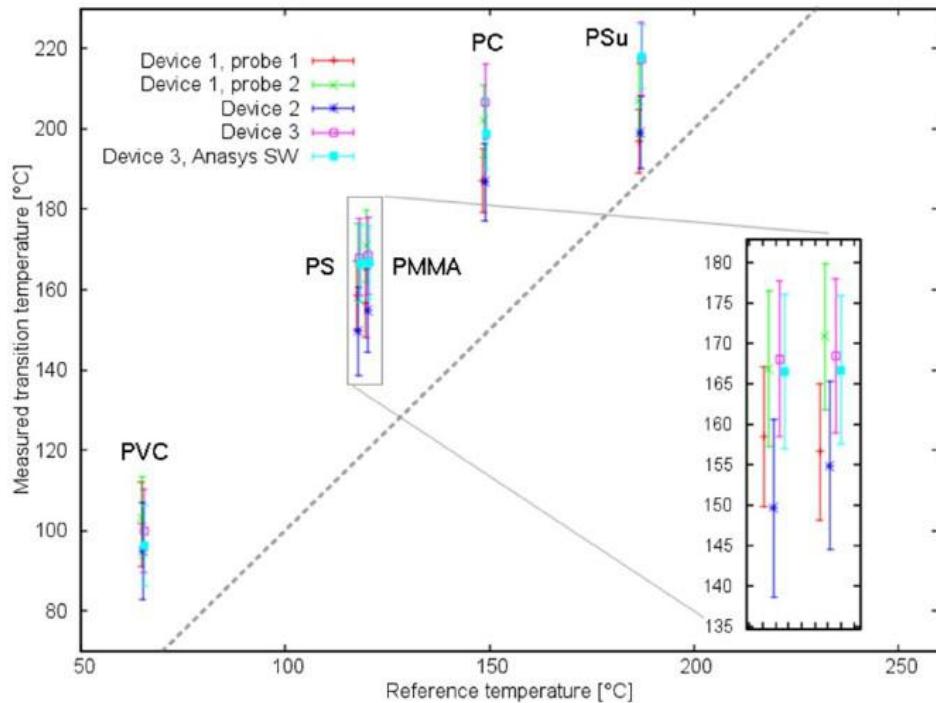
Bruker nano-thermal analysis test sample:
PCL, HDPE, PET, 55-235 °C.



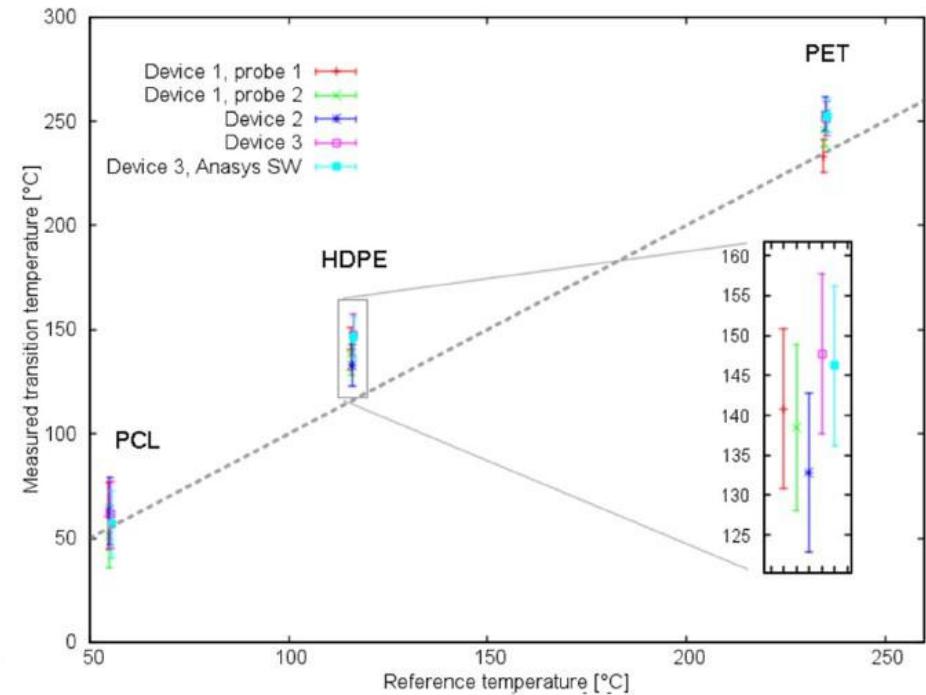
An interlaboratory comparison was run by ČMI, NPL and INSA (CNRS), using different probes, electronics and microscopes.

The results match within the measurement uncertainty (~ 10 K), however are shifted systematically when compared to DSC data. This can be related to different probing volume when comparing bulk and local measurements.

Quantiheat “unknown” samples



Anasys test samples



Thermomechanical SThM measurements guidelines:

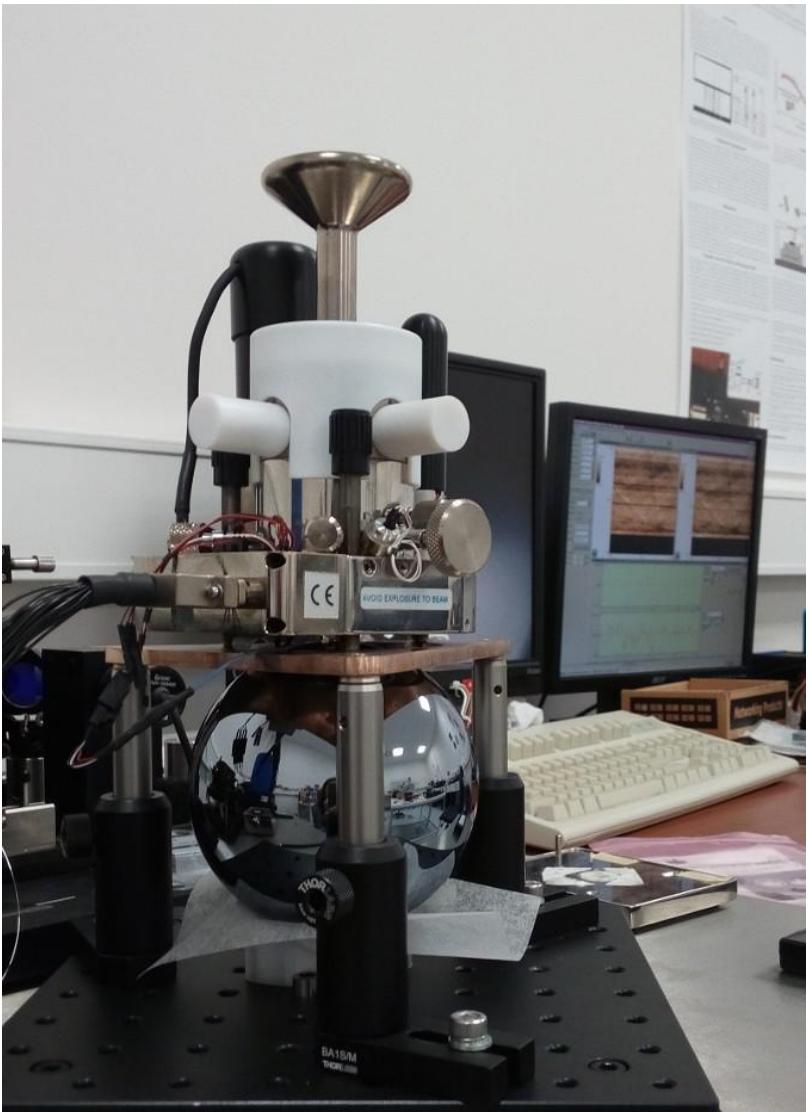
- get some reference samples
- calibrate your probe
- test the probe response in air and on solid sample (e.g. silicon)
- use same ramp rate when doing the calibration and measurement
- avoid sinking into the samples and probe contamination

General recommendations to keep your measurement quantitative:

- don't believe every promise
- get some known samples – ideally traceable ones
- know your uncertainty sources
- process your data only minimally
- try to use different probes, voltages, amplitudes, etc. to verify that everything works correctly

For dimensional measurements 1% uncertainty should be reachable.

For other properties, be happy for 10%.



More details about the data processing for different SPM measurement methods: book published by Elsevier

Gwyddion - Publications - Mozilla Firefox

gwyddion.net/publications/#Klapetek20

Books and book chapters

Quantitative Data Processing in Scanning Probe Microscopy, 2nd edition

Petr Klapetek et al.

Elsevier 2018, ISBN: 978-0-12-813347-7

Publisher's store link: Quantitative Data Processing in Scanning Probe Microscopy, 2nd edition

Table of contents:

1. Motivation
2. Instrumentation Principles
3. Data Models
4. Basic Data Processing
5. Dimensional Measurements
6. Force and Mechanical Properties
7. Friction and Lateral Forces
8. Electrostatic Fields
9. Magnetic Fields
10. Local Current Measurements
11. Thermal Measurements
12. Optical Measurements
13. Sample Data Files
14. Numerical Modeling Techniques

The book is accompanied with [freely available sample data](#).

Quantitative Data Processing in Scanning Probe Microscopy

Petr Klapetek et al.

William Andrew 2012, ISBN: 978-1-4557-3058-2

Publisher's store link: Quantitative Data Processing in Scanning Probe Microscopy

Table of contents:

Large set of sample data related to the book:

<http://gwyddion.net/qspm/>

Quantitative data processing in Scanning Probe Microscopy: associated data sets - Mozilla Firefox

Quantitative data processing in Scanning Probe Microscopy: associated data sets

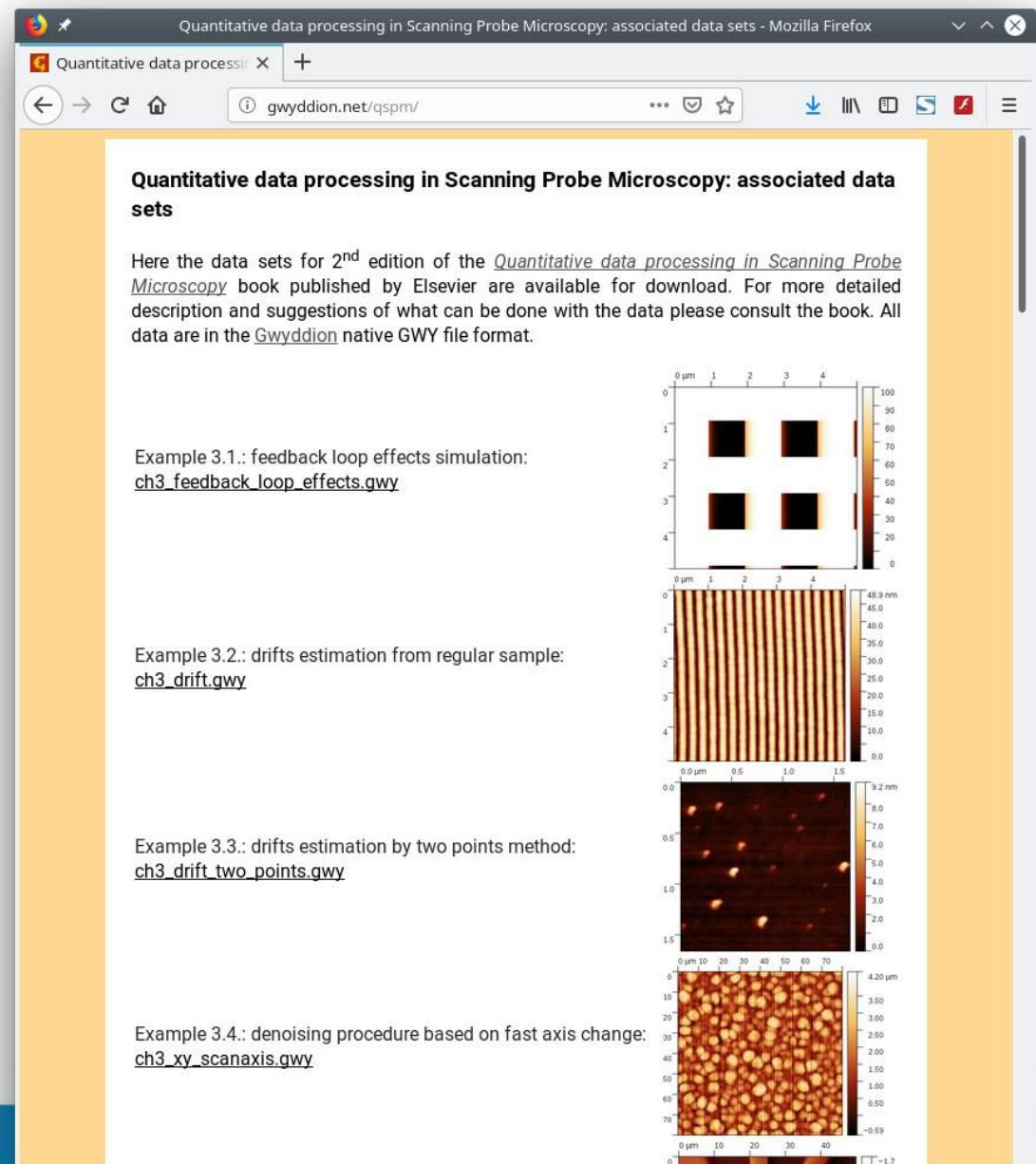
Here the data sets for 2nd edition of the *Quantitative data processing in Scanning Probe Microscopy* book published by Elsevier are available for download. For more detailed description and suggestions of what can be done with the data please consult the book. All data are in the [Gwyddion](#) native GWY file format.

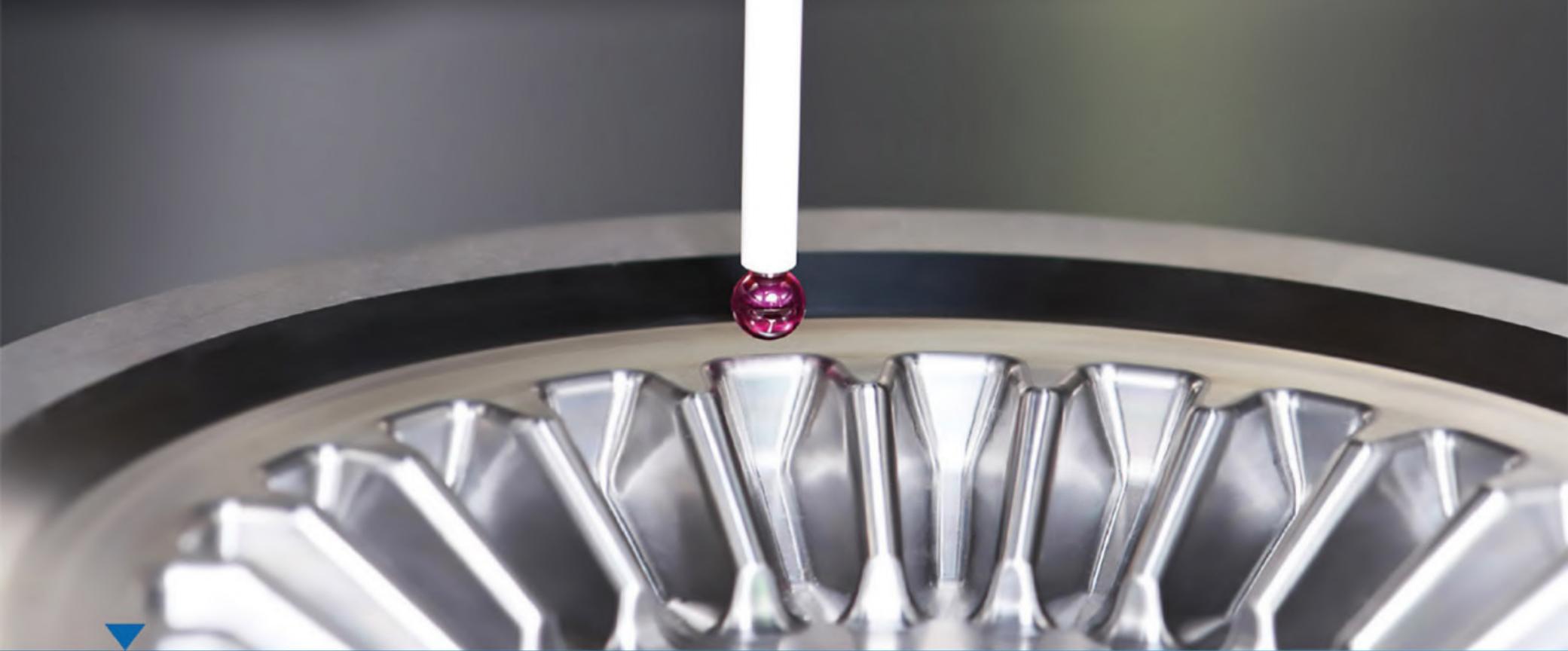
Example 3.1.: feedback loop effects simulation:
[ch3_feedback_loop_effects.gwy](#)

Example 3.2.: drifts estimation from regular sample:
[ch3_drift.gwy](#)

Example 3.3.: drifts estimation by two points method:
[ch3_drift_two_points.gwy](#)

Example 3.4.: denoising procedure based on fast axis change:
[ch3_xy_scanaxis.gwy](#)





A close-up photograph of a precision measurement device, specifically a coordinate measuring machine (CMM). A white probe arm with a red spherical probe is positioned above a series of metallic, ribbed cylindrical components. The background is dark, making the metallic surfaces stand out.

Thank you for your attention

